Recently I joined the Product Engineering group and have had an interesting time becoming acquainted with my new associates and their activities. I believe you also will find this of interest. In charge of this staff activity is Mr. D. F. Schmit. Mr. Schmit has been with RCA for over forty years. During this time he has made many friends and has become well acquainted with the various businesses within our Corporation. Through his staff and by personal involvement, he has provided many kinds of assistance to RCA's operating divisions, and done much to promote the professional status of RCA engineers.

One of the activities within Product Engineering is managed by Mr. W. O. Hadlock. All of you know something of Bill and his staff because they publish this magazine. What you may not know is that they are responsible for many other things that help you. Do you not like the ease with which you can get the pertinent facts about an RCA technical report from just the title page? Have you used the RCA Technical Reports Index? These are just two things that have come from the Publications group.

Mr. J. P. Yeatch, with offices in Washington, D.C., heads up the RCA Frequency Bureau for Mr. Schmit. Jim and his associates staff the Frequency Bureau offices in Washington, D.C., Camden, N.J., and New York, N.Y. Many facets of our business are concerned with the radio frequency spectrum and our Frequency Bureau is constantly working to protect RCA's interest in this area. They also help represent the United States in international frequency allocations and utilization conferences. In addition, they can help you interpret the FCC rules, obtain a station license, or get type approval on a new transmitter.

Another member of Mr. Schmit's staff is Mr. H. E. Schock. Harvey specializes in the area of product assurance. He is well informed on quality assurance techniques used by industry, as well as the many groups within RCA. He spends much of his time keeping our Quality Assurance groups informed of new developments and works with them to solve problems in this area.

Another activity within Product Engineering is managed by Mr. J. W. Wentworth. John and his staff are taking some impressive steps in the area of continued education for engineers. You will be reading more about the pioneering efforts of this team and their CCSE Program in the future.

Corporate Standardizing, under Mr. S. H. Watson, is a portion of the activity with which you should be well acquainted. Sam and his associates guard the integrity of the RCA drawing system and work closely with divisional groups to provide up-to-date standards with a minimum of duplication. You will find that excellent service will be provided when you request a drawing showing any standard item. In addition this group can be helpful when trying to locate old drawings.

Another member of our staff is Mr. G. A. Kiessling. George and his associates are concerned with a wide variety of activities that include education of engineers, professionalism, and communications. George provides liaison between our Company and several outside information sources. He plans and develops a number of very effective information exchange programs for our engineering supervision. He also is responsible for that popular publication Trend.

This is the Product Engineering organization together with a sampling of the services offered. It is a staff activity and, therefore, available to aid you. We invite you to take full advantage of our service.
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The engineer's formal means of professional communication consists largely of technical reports, published papers, and oral presentations. Logically, a written report should always come first, since this can be the most comprehensive of the group. From this base, both the professional paper and the oral presentation can easily be derived. An understanding of the techniques and procedures of the professional writer, and of the basic differences between reports, papers, and talks, can be of great help to the engineering author.

One does not become an accomplished writer or speaker after reading one paper about these subjects. However, it could help. This paper concentrates on practical advice and counseling for potential authors who are anxious to improve their capabilities.

The Engineer and the Corporation

THE ENGINEER AND HIS PROFESSIONAL COMMUNICATION

I. M. SEIDEMAN, Mgr.
Astro-Electronics Division
Reports and Proposals
Princeton, N. J.

YOUR TECHNICAL REPORT

The present nature of engineering at RCA dictates a rapid pace for everything we do. Professional writers can turn out quite satisfactory reports in very little time. If you, the engineering author, learn the basic techniques and procedures for professional writing, you can make your own lot easier, and avoid the cost or schedule overruns often resulting from a wrong start.

The approach to writing a report is basically the same as that for solving an engineering problem. It is necessary to move in an orderly manner: to analyze, classify, and synthesize. Even when a piece of electronic equipment must be designed in a hurry, you still do not lay out the chassis before you select the circuits. If you can find standard, state-of-the-art circuits for your design, you use those rather than unproven, exotic configurations—even though the latter may seem intriguing and impressive. And if you knew an engineer with experience in the equipment you were designing, you probably would discuss your plans with him, to get the benefit of his advice. Very much the same thing applies to report writing. No matter how great the rush, you should:

1) Plan your report in advance.
2) Use specific and straightforward language.
3) Get advice or help from your Publications Support group.
4) Read, remember, and use the techniques and procedures adopted by professional writers.

When Write is Wrong

The last thing to do first is to write. When you suddenly realize that work on the report can no longer be put off, sit quietly for a few seconds to settle your nerves and then ask yourself these questions:

1) Who am I writing for?
2) What will I say?
3) How much do I have time to say?
4) In what order will I say it?
5) How will I say it?
6) What don't I want to say?
7) What help can I get—and how soon?

You already know the answers to some of these questions; the information in this paper will help you answer the others. When you have settled on satisfactory answers, you will not only be able to write with speed and certainty; you will also have greatly reduced the chances that an editor or a reviewer will ask for a rewrite or prolonged explanatory sessions.

To help you arrive at the right answers, let's examine the import of these questions.

Who Am I Writing For?

If you are writing only for the information of your supervisor, you can assume that he knows the project background, its special language, and how isolated events fit into the general context of the project’s progress; in this case, write as though you were talking to him. But if your report is to go to management or the customer (via your publications group), then you must avoid laboratory jargon, and include the necessary background and explanations to make what you say comprehensible to the technical layman (i.e., any engineer who doesn’t know as much as you do). Abbreviations, coined or borrowed words, and general terms (such as “tested satisfactorily”) should be explained. The relation of smaller portions of the project, or equipment, to the over-all project should be noted. This is the time, too, to discover if a writing or publication specification has been invoked. If this is the case, get an explanation of its effect from your publications group.

But doesn’t all this take more time instead of less? Not in the long run. Time spent to plan and to establish a firm base of understanding permits faster progress in the later stages of writing. And less time is taken if you freely accept this approach instead of mentally protesting at every step.

One other point. You are also writing for a typist. She is in short supply and overworked. Pity the poor girl, and speed up the processing of your work by anticipating her problems. Double-space your handwritten manuscript. Dot your i’s and cross your t’s—these are important clues in her isolating little groups of graphite ripples into m’s, n’s, u’s and w’s. Distinguish beta’s from capital U—s a note in the margin that you have started on the Greek alphabet helps. Print new and unusual words the first time they appear. And remember that the typist types what she sees; don’t print in capital letters if the typed draft is to be lowercase.

IRVING M. SEIDEMAN received his BS degree in Physics from Carnegie Institute of Technology in 1941. He then joined the RCA-Victor Division in Camden, N. J. as a member of the Publications Section of the Special Apparatus Group. In 1946, he became an advertising copy writer for the International Division of RCA. He left RCA in 1947 for work in industrial advertising and electronic equipment sales, but returned to the Missile and Surface Radar Division in Moorestown in 1956 as a Publications Engineer on the TALOS and BMWWS programs. When the Astro-Electronics Division was formed in 1958, he transferred to this activity and handled publications for the TIROS, RELAY, NIMBUS, and other spacecraft projects. He was promoted to Leader, Publications Engineers in 1962, and became Manager, Reports and Proposals, in January 1964. He also has been an Editorial Representative for the RCA Engineer since 1963.
What Will I Say?

The specifics of what to say depends on the project and the type of report. However, it always helps to first list the most important topics, then the next most important, etc. Then develop a continuity for each topic, for example, discussing in turn: 1) the design concept, 2) the established design, 3) the equipment construction, 4) its test, and 5) its acceptance—or 1) the delivery of a vendor item, 2) its test, rejection and return to the vendor, and 3) its redelivery, test, and acceptance. Whatever the sequence, follow through to a disposition that doesn’t leave the reader hanging.

A published report of a similar type might be helpful as a reference in organizing your report; ask your publications group to look for a suitable one that might be borrowed.

How Much Do I Have Time to Say?

Words must be equated to time and money. The size and scope of the report should be established (if it has not been previously), based on customer requirements and the project budget. If the report is to consist of several sections, consider the relative importance of each and—before you start writing—ration your word-count accordingly. You may not want to repeat what is in previous or subordinate reports; a summary statement and a reference may do. The extent of detail to be presented must be considered: mathematical derivations often can be shortened, and typical or summary data tabulations can be given in place of comprehensive tabulations. But do not try to telescope three thoughts into one (thus risking ambiguity) or omit articles, adjectives and conjunctions (the reader may think you have just learned English).

How Will I Say It?

Use simple, direct language to report your information. It takes will power and deliberate effort to think through each sentence as you write it, instead of relying on technical clichés and prefabricated phrases, used like a set of patch cords for any and every purpose. Don’t hesitate to cross out an unfinished sentence and start over. More than any other fault, sentences which are started before the ending is thought out
tend to slow down both the writer and the reader. Use of abstract words in a sentence often make it difficult to convey an exact thought. "Implementation of the work was effected" is an obscure substitute for "Work was done." Trying to include afterthoughts in a started sentence most often ends in a confusing statement. Again, rewrite when you rethink.

**What Don't I Want To Say?**

Although the reader of a report will want to know what went wrong as well as what went right, he is not interested in emotional detail. In short, do not complain and do not blame. Also, do not philosophize. There is a difference between coming to conclusions based on the results of study and research, and giving opinions based on intuition or your personal inclinations.

Don't report implicitly. For instance, the statement: "the video display chassis was transferred from the model shop to the assembly and wiring area" probably means that "fabrication of the chassis was completed and assembly of parts on the chassis was started." The latter statement is specific, and it should be used if that is what is meant. Of course, if a subsystem is shipped to another contractor for integration, this is in itself a milestone, and should be reported.

Don't abbreviate the names of companies or other RCA divisions without spelling them out at frequent intervals. Don't refer to locations only, such as RCA-Lancaster, RCA-Camden; state the division name. There may be more than one division of RCA at a particular location, and vice versa.

**What Help Can I Get—And How Soon?**

One of the unfortunate facts of life is that a large proportion of an engineering report must be written by the author. This is in contrast to an operating or maintenance handbook, a test plan, and several other types of documents which can, in large part, be ghost written by a technical writer. Among the reasons for this are the fact that a great deal of the report information has never before been communicated; and even if it has been recorded, it is in the form of skeleton notes which can be reconstructed only by the author. Also, the author knows best the degree of success of his work, and he is usually the person best qualified to draw conclusions and make recommendations.

But there is more to a report than the author's first manuscript. If funding is provided for publications support, call them in early. They can help with your outline, interpret any specifications involved, start the drawings necessary, and take or prepare photographs for the illustrations. They will check your work for coherence and continuity, edit it, type it in "repro" form (that is, the "clean" copy required preparatory to printing), proofread it, make up the Table of Contents, List of Illustrations and Covers, add page numbers, make up an assembly list showing how text and illustrations fit together, print it, collate it, bind it with covers, verify the accuracy of the work, and see that it is distributed to the customer and within RCA. They will then file the text and illustration material and have it available for revisions or a reprint.
Practice is Necessary
This writing plan may seem complicated to the harried author whose deadline looms just over the weekend. He should remember that the instructions for assembling a tricycle also seem complicated if one has never done it before. But after going through the procedures once or twice, they suddenly become simple.

When There is Time...
The author who has more time to prepare a report may indulge in the luxury of over-writing and then cutting back his material. He may want to review his first manuscript as many as three times: once to delete redundant or extraneous material, once to rephrase what is left, and—if he is an experienced author—once more to refine and polish his sentences, to add sparkle and interest to his manner of expression.

He may want to include more illustrations or discuss his illustrations in more detail instead of leaving their relation to the text implicit. He may want to add references to related work. He may want to add appendixes with detailed supporting information. And he may want to schedule more time for publications editing and production.

YOUR TECHNICAL TALK
An invitation to deliver a talk at a technical meeting implies that the papers committee thinks you have information of current interest and significance to your professional colleagues which would be enhanced by oral delivery. The same information could have been—and might subsequently be—published in a professional journal. Obviously, then, something different than the mere reading of a report or a paper is expected of you when you stand before your audience and speak to them.

Differences Between Talks and Papers
Whether or not you anticipate publication of your paper, you should consider two versions—one suitable for printing, the other suitable for oral presentation. Why should there be a difference?

Recent research relating to machine recognition of human language reveals some deep and interesting differences between the hearing and reading processes of the human being. We hear sound in a serial fashion, but we read (or, at least comprehend) a group of words in parallel. Further, the listener depends on much more than hearing a sequence of words to understand the speaker’s meaning.

The reader can proceed at his own pace; the listener must keep up with the speaker’s. The reader can scan, can reread, can refer from text to illustrations and back, and can stop to consult a basic text or a dictionary; the listener depends on the speaker to make everything clear in logical sequence. The sentences of a talk should be short and straightforward, the audience is unlikely to grasp the complex relationships in long sentences with many explanatory and restrictive modifiers. A paper for publication may be of almost any length (the journal editor can run it in two parts, or may negotiate on its final size); a talk must be carefully planned not to exceed the pre-established time allocated for its presentation. There should not be a one-to-one correspondence in detailed content between a talk and a paper; the author often may assume his audience will read his detailed paper in published proceedings of the meeting.

Organization Of Your Talk
A talk should be developed from your completed report or paper, or from a detailed outline of the information to be presented. It should have an introduction and a conclusion, and maintain continuity in between. Although the meeting program may carry an abstract of your talk, assume that the listener has not read it or will not be able to recall it as you begin speaking.

To put your audience at ease (and, perhaps, yourself too), use the first 200 words, more or less, to tell the audience what you are going to talk about. You may occasionally wish to withhold a salient point in your work for a later dramatic impact, but remember that suspense in a technical paper generally is in poor taste.

You will then have your listener anticipating, and receptive to, the main body of your talk. Develop your theme, but assume that the listener believes what you say to be true. Do not try to present detailed analyses or verifications of your work in your talk. Keep mathematical supporting data to a minimum.

An audience needs an occasional amount of relaxation. This may be accomplished by a quip, repetition of a phrase, statement of a familiar fact, or a second or two of silence.

Do not use abbreviations or acronyms in your talk. There are a few notable exceptions: those which are universally known and, perhaps, more easily recognizable in the short form, such as AC, FM, NASA, Tins, and PERT. With proper emphasis (such as display on a slide) you may get the audience to remember one or two abbreviations or acronyms for long or involved expressions. Indiscriminate usage, however, may have the same effect on your audience as the use of Russian nouns and Arabic verbs; the barrier to understanding is not worth risking.

The use of symbols (other than those well known within the
context of the subject matter) without continual identification can “lose” large portions of your audience. In addition to the phonetic similarity of many symbols (e.g., b and v, or c and z), the parameter definitions themselves often are unfamiliar and will bear repeating.

Your talk should have a formal conclusion. You may wish to emphasize the usefulness or the value of the results, the plans or need for additional work, or (if your talk was descriptive) to recapitulate your subtopics. Don’t introduce new topics in your conclusion.

The length of your talk will be governed by the time allotted; plan to stay within this time limit. A good figure to use in calculating average talking speed is 140 words per minute. Thus, a 20-minute talk with no planned breaks would consist of about 2,500 words. However, you must reduce this number somewhat if you plan to show slides.

Several elements contribute to the time allotment for slides. The considerate speaker waits for a few seconds after a slide is displayed before he discusses it. The audience will examine it anyway, to the exclusion of the speaker’s concurrent remarks, and may then not be able to follow the remaining discussion. There are other delays involved, such as the switching of room lights, occasional aligning of individual slides, and your own search for a particular part of the slide to point to. (A flashlight-type pointer permits you to stand further away from the screen and minimizes this last delay.) It is wise to deduct 15 seconds from your talking time for each slide; 12 slides, for example, would then cut your narrative by three minutes, or approximately 400 words.

Illustrating Your Talk
If you use slides, or other projected-image illustrations, plan to show a few at a time, and have the auditorium lights turned up in between. A prolonged period of darkness provides a choice environment for slumber or departure.

Avoid showing multiple curves, complex tabulations, etc. unless you want merely to impress the audience with their general complexity. Identify each curve by name; do not use letters or numbers and a separate keyed descriptive list. Hold block diagrams to seven blocks or less.

Transparencies
Art work for transparencies must be arranged to ensure legibility of the projected image. Lettering size should be at least one-twentieth the height of the projected area; if the slide is predominantly text, ten lines of printing is the maximum that is comfortable to view. Color adds to contrast, and tends to reduce glare. However, black-and-white is visible at a greater distance from the screen (for the same light intensity at the projector). The illustration of legible, well-designed slides compared to illegible and crowded slides should make the importance of proper layout obvious.

Large-area transparencies (such as Vu-Graphs) offer advantages in cost and preparation time. In many cases they can be prepared by the author. (Instructions for preparing these are given in the Appendix at the end of this paper.)

Some professional societies specify slide size and orientation; your RCA Editorial Representative or publications group can advise you on most requirements. Slide projectors (and even motion-picture projectors) usually are available to accommodate standard or specified characteristics.

Art work prepared for slides usually is suitable for illustrating your printed paper; the reverse, however, is seldom true.

Preliminary Arrangements At The Meeting
Plan to arrive early at the auditorium or meeting room. Contact the session chairman or person in charge of arrangements, let him know you are ready, and confirm the availability of facilities you will need.

1) Is there a public address system? Is there a neck or lavaliere microphone available, or do you use a (fixed) podium microphone?
2) Is there a slide projector? Will it take your size slides?
3) Is there a pointer available for you to use when slides are projected? (You may wish to bring your own flashlight-type, if one is available to you.)
4) If possible, arrange to have someone at the back of the hall signal to you during your talk if your voice is too loud or inaudible.

Facing the Audience
When you first come to the podium and face your audience, are you nervous? Most speakers are. The idea is not to let your nervousness show. Don’t duck your head, rearrange your clothing, or take a tight grip on the podium. And don’t rush into the first sentence of your talk. Stand quietly for a moment, move your feet a few inches apart, loosen your knee muscles (bend your knees just a bit), and drop your hands loosely to your sides. RELAX! Look two or three people in the audience right in the eye (move your head slowly to do this), and then begin with your first sentence.

Try to remain aware of your talking speed. Over-emphasize the explosive consonants (d, t, p, etc.) and hold on to the hummings (m and n). That will help the audience to understand you and will keep you from building up speed.

Move around (unless you are dependent on a non-mobile microphone). Do not stride or walk continuously, but change your location from time to time. Your audience will then see you instead of inventorying the chandeliers to relieve their neck muscles. You may continue to speak while you’re moving. However, return to the podium for your conclusion; it will be easier for the session chairman to find you there.

If there is a question and answer session, repeat each question before you answer it. It will verify that you have heard the question correctly, and it will ensure that your entire audience hears both question and answer.

ACKNOWLEDGEMENT
Much of the material on graphic aids was made available by the kind cooperation of S. Skarlatos, Manager of Graphic Arts Production for the Astro-Electronics Division.

APPENDIX: VISUAL AIDS
Several types of visual aids for a speaker are in general use. Each type has advantages and disadvantages, depending upon such things as the audience size, the type of meeting hall, and the facilities available. Those which can be readily prepared in-house are:

Flip Charts
These consist of pads of paper, 28 x 34 inches in size, often containing a faint background grid. Lettering, charts, and simple illustrations are drawn on the sheets, using felt-tip markers, tapes,
or other means of drawing black or colored lines. The pad is supported on an easel, and each sheet is "flipped" to the rear as the next becomes of current interest. Either the author or a professional artist can prepare flip charts. They may be considered equivalent to free-hand sketches.

Presentation Boards
These can be procured in any size that is convenient to handle (a practical limit is 30 x 40 inches). Generally, lettering and art work are prepared by a professional artist who uses mechanical aids to produce a high quality of illustration. They may be stacked on an easel, and removed one-by-one as the talk proceeds. They also are more suitable for small audiences.

Projection Transparencies
This category is subdivided by sizes: the smallest and most popular is the 35-millimeter slide; a larger size, known by various trade names (e.g., Vu-Graph, Tekni-fax), has an image area of 17½ x 9¾ inches.

35-Millimeter Slides
These slides afford the opportunity for a high-quality display of line drawings, photographs, and text on screens large enough for virtually any size audience. They can be prepared in both black-and-white or color; color "trim" may be used to enhance black-and-white illustrations. Line sharpness and contrast on these slides are good, and subtle variations in shade and color come through well. However, the cost of preparation is relatively high, and more time is required for their preparation than for other types of visual aids. A newer variation of this size is the Superslide, which has a somewhat larger image area with square corners. However, some 35-millimeter projectors will cut off the edges of these slides.

Larger Transparencies
These are large enough to accommodate full-size illustrations as they appear on an 8½ x 11 inch document page. They may be prepared in a great variety of ways. The simplest, perhaps, is through use of a clear acetate medium on which the subject matter is drawn with a grease pencil, broad-stroke pen, or adhesive tape. More commonly, however, art work is transferred to them by simple techniques similar to those used in making prints from engineering drawings. Elaborate preparation, using color, is possible. Because of the larger size and projection technique, portions of the image area may be masked during the initial projection, and then sequentially unmasked to "build up" a picture for the viewers.

A pre-printed form has been prepared by the Astro-Electronics Division Graphic Arts Group to facilitate the preparation of text or artistic elements (i.e., technical) written, because it conforms to the aspect ratio of most screens. The large area at the top (see Fig. 12) is provided for the caption; a monogram or other identifying symbol may be inserted at the left. For minimum acceptable quality, free-hand lettering with a soft lead pencil or a black ballpoint pen can be used. For sharp lines and a neater appearance, a sketch should be submitted for redrawing by a professional artist. Material may be typed on this form if the impression is a heavy black.

For reproduction of graphs and charts, the curves or bars should be drawn on the reverse of the graph paper, and only the significant grid lines redrawn.

This size transparency can be the most economical and the fastest to prepare, and consideration should be given to these virtues when a presentation is being planned.

BIBLIOGRAPHY
   (An early Faux analysis, with some practical results of interest to engineering authors.)
   The author presents clearly the difference between "imaginative" and "functional" (i.e., technical) writing; how to convey meaning, rather than merely express it; and how to avoid saying what you don't mean. The material is taken from a postgraduate course given at University College, London. It is short; it is readable; it has current application.
   A recent text combining instruction in technical and scientific writing with a handbook of usage and style. The authors seem quite familiar with the conduct of electronic and aerospace projects, and much of the material is directly applicable to current programs at RCA.
   Small, easy-to-read, text book with specific instructions and examples of the most important elements of style in any type of writing. Wholly applicable to technical reports.
   An editor of the New York Times compiles from his paper examples of good and bad writing, especially with respect to word usage. Contains many examples of bow to say it precisely with a minimum number of words. An eleventh printing, in 1966, confirms its present worth.
7. Robert L. Webb, Grammar for People Who Wouldn't Have to Worry About It If They Didn't Have Children, Crowell-Collier Press, 1953.
   In spite of the facetious title and light writing style, this book is an excellent refresher course on parts of speech—for adults.

Fig. 11—Three booklets in use at the Astro-Electronics Division to assist engineers.

Fig. 12—Standard Vu-graph format at Astro-Electronics Division.
LASERS AND RCA

The laser, now seven years old, has stimulated an extraordinary amount of technical and popular interest. Where does this new development fit into the interests and needs of RCA? What part is RCA playing in the research area? Where is it likely to make use of lasers as a part of a system or in process control, and what will it manufacture? This paper attempts to answer these and other questions concerning lasers in a general manner, while other papers in this issue present details on laser work at: RCA Labs, Princeton; RCA Victor Research Labs, Montreal; Electronic Components and Devices, Somerville; Aerospace Systems Division, Burlington; Astro-Electronics Division, Princeton; and Applied Research, Camden.

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In the seven years since the laser (or optical maser) was first developed, there have been enormous advances in both its technology and its application. The laser is having a pronounced impact on the science of optics, where it has put new life into a somewhat moribund field. It has sparked a great deal of work in the materials area, and the suggested range of applications is ever widening. However, its use in industry is still small, and it remains more a promise than a reality.

ROD-TYPE LASERS

The laser principle was first demonstrated with a rod of ruby crystal. Ruby still remains the most commonly used material for the rod type of laser, which is distinguished by its ability to emit pulses of very high peak powers with modest average power. Where does RCA fit into this area?

Much excellent work has been done at RCA Laboratories on new materials for rod lasers. This work includes extensive investigation of calcium fluoride host crystals doped with rare earths, doped calcium tungstate, and yttrium-aluminum-garnet (YAG) host crystals doped with neodymium. YAG is a practical cw crystal laser which is of particular interest in the field of communication. When a YAG laser is properly modulated (e.g., with a gallium arsenide electro-optic crystal), a communications link with a bandwidth wide enough for TV can be designed. However, the rod type of laser must compete with the much more easily modulated and more efficient injection laser.

None of the new materials developed for rod-type lasers compete with ruby for high peak power output. Where, then, will RCA make use of this work? There are no plans for RCA to develop and sell laser crystals, nor to make equipment using rod lasers for commercial sale. In the defense area, RCA will have an interest in the new materials for possible use in development of a communications system that can be part of a very large contract. However, this application may be better accomplished with an injection laser. RCA defense engineering activities are also using ruby rod-type lasers for various military applications, including distance-measuring equipments for the army, missile-tracking systems, and special radar transmitters. For such applications, the peak power of the ruby laser permits ranges of several miles. Both the gas laser and the injection laser may be serious contenders in this area, however, particularly for shorter distances.

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problems appear to be solvable, they point up the fact that such equipment has until now been used for experimenting, rather than for actual production.

GAS LASERS

Originally, gas lasers were considered as a source of highly coherent light with a narrow line width but rather low power. This type of laser has been chosen for work in optical fields such as interferometry, and is an excellent research tool. Gas lasers have for some time been able to put out continuous, though low, power. This power output is now being increased very rapidly into the range of several hundred watts. The most powerful gas laser, the CO₂ laser, has a wavelength of 10 micrometers. Although this region is of great interest, suitable detectors must be developed for it.

What about gas lasers and RCA? The gas laser is being used in many scientific investigations. Perhaps the most interesting to RCA is the new area of holography. This method of producing pictures, or some outgrowth of it, is of intense interest to a "picture device" company such as RCA. Because the gas laser can readily be made to emit in the visible region, it is also of great interest for producing TV pictures by new methods. One possibility is to use an electro-optical crystal for horizontal scanning and some mechanical means for vertical scanning. Modulation might possibly be accomplished with an electro-optical crystal such as gallium phosphate.

The best known of the gas lasers is the He-Ne laser, which has an output in the red region. Although argon is a very attractive gas because it lases in the blue region, to date such lasers have had a very short life. RCA Laboratories has recently developed an argon laser with a very long life, and there are plans for EC&D to make this laser on a development basis. In spite of its high power, the gas laser will probably be primarily a research tool for some time to come because of its bulkiness and fragility.

INJECTION LASERS

The semiconductor injection laser is the newest of the lasers, with a history of only four years. The first injection lasers used a p-n junction in gallium arsenide, with the cavity formed by shaping of the junction. The first lasers would operate only at low temperatures (77°K) with high-current pulses. Gradually the efficiency has been improved and the threshold current for laser action has been reduced. RCA Laboratories has made a major contribution to this field in the development of solution epitaxy to form the p-n junction. Today junction lasers can be made to operate under pulsed conditions at room temperature and can operate continuously at 77°K. The best individual lasers can deliver peak powers of 10 watts at room temperature with a current pulse of 40 amperes. The average power can be as high as 0.1 watt. Because injection lasers are extremely small (typically 2 mils by 5 mils by 10 to 20 mils long), a great many can be packed into a small area to create a very bright light source.

The injection laser and its companion, the non-lasing optical diode, are natural devices for RCA to manufacture. They are semiconductor devices, an area in which RCA is already in the marketplace, and they use gallium arsenide, an area in which RCA has made a large investment in technology. Both devices have been in development for four years by a small group in EC&D and for even a longer time by a larger group at RCA Laboratories. This work has been so successful that a new product group has been set up to exploit these devices in the Industrial Tube and Semiconductor Division of EC&D.

The compatibility of this semiconductor approach with EC&D's other work is undeniable. However, what is the market for these devices? The optical or non-lasing diode can be used for applications in which a continuous emission is needed at room temperature. If lasing diodes can be made to operate continuously at room temperature and low current levels, they would be preferable for such applications because of their higher efficiency. However, such operation appears to be a long way off. The optical diode can also find a large market in data-processing systems as the light source for card readers. Gallium arsenide is a suitable material for such diodes because it emits in the infrared region, where a silicon diode is an efficient detector. As compared to other light sources, the optical diode has the advantages of very small size, indefinite life (if processed correctly), and capability of being modulated at very high rates.

An optical diode that can emit in the visible region opens up new applications. Such a diode (of rather low efficiency) can now be made to emit in the red region by use of alloy materials of gallium arsenide and phosphide. A great deal of work is in process to improve the efficiency of such diodes by use of RCA's new vapor epitaxial growth process. These diodes can be used as very-long-life indicator lights. Another possible application which is being investigated is alpha-numeric arrays. It appears possible for optical diodes to compete directly with the present "nixie" tubes in this area. Diode arrays not only have the potential of low cost, but also, because of their low-voltage operation, can be driven easily by transistors or integrated circuits.

Where does the semiconductor injection laser fit? To date, there have been two major applications. The first is as a light source for a short-range optical communications system. For this purpose, one or a group of lasers can be operated at room temperature using some sort of pulsed code communication. The equipment can be made very small and rugged, and requires only a small power supply. The second application is as a very bright light source that can be pulsed. Because it is possible to put as many as hundreds of lasers in a very small area, a very bright, powerful light source can be obtained. The efficiency of such a source can be greatly improved by cooling. (An article by M. F. Lamorte gives a more complete review of optical diodes and injection lasers.)

Neither of these applications of the injection laser needs the coherent light of the laser. The narrow angle of emission of the lasing diode, which greatly enhances the brightness (usually given in watts/cm²/steradian), is the important item. The semiconductor laser is not a particularly good laser because there is always a good deal of non-coherent light emitted, the angle of emission is rather large for a laser and there are usually many modes. However, the tremendous advantages of small size, high efficiency, and low voltage make it a very practical tool. It will not be useful in very-high-peak-power applications where the ruby laser fits, and will not supplant the gas laser as a scientific tool. In the future, however, it will find much use in applications requiring large numbers of lasers. With more development its lasing properties will improve, it may be possible to achieve continuous operation at room temperature, and its cost will rapidly fall.

CONCLUSION

Any attempt to prophesy the future in such a new and rapidly changing field is full of pitfalls. Although this paper has pointed out a few of the growing number of applications for lasers, it is more than possible that new uses which fit into RCA's pattern of business may soon outweigh any or all of the functions described.

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P-N JUNCTIONS AS OPTICAL SOURCES

Although RCA traditionally has been in the business of producing and selling light sources, in most cases the devices were designed for electronic rather than illumination functions. While advances made in the past have been remarkable, today the light-source industry may be on the verge of a revolution. Just as the p-n junction revolutionized the amplifying and switching device areas of the electronic components industry, the light-emitting p-n junction may revolutionize the light-source industry, both in types of devices that will be produced and in the scope of their applications. The most dramatic advances during the past 5 to 10 years have been made in gas, insulator-type, and semiconductor laser devices.

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At present, the most widely used types of solid-state optical sources are the tungsten filament and the electroluminescent phosphors employed in cathode-ray tubes and television screens. The former is a black-body radiator and uses only a portion of the continuous spectrum in any one application. In the latter an electron beam is used to excite the phosphor, and a series of intense lines is produced rather than a continuum. The tungsten lamp has found little application in electronic functions because of the poor frequency response of its radiation to high-frequency electrical signals. Electroluminescent phosphors exhibit a frequency response several orders of magnitude higher. Laser-type devices and p-n junction light emitters exhibit even higher frequency response, approaching 1 GHz.

Although this paper discusses optical sources as applied to electronic functions, these electronic-type optical sources may also be useful for general illumination applications. The illumination market is well in excess of $1 billion per year.

Types of Light Sources

For many years scientists have worked to obtain all-solid-state light sources to perform such electronic functions as transmitting information over light beams and to serve as efficient, inexpensive sources that might replace the cathode-ray type and other types of displays. Although the electron beam as an exciting medium offers some attractive features, low-voltage operation and flat or mura-style display are desirable at price and performance levels which would be competitive with present-day devices.

One type of all-solid-state source which has been under intensive study is the high-field AC and DC electroluminescent device. At the present stage of development, these devices have the disadvantages of low efficiency, poor operating-life characteristics, and high-voltage operation (which makes them incompatible with silicon transistors). If improvements can be made in these areas, however, this type of device would be attractive in some applications for mural displays.

Perhaps the most attractive all-solid-state light source is the p-n junction luminescent diode. Diodes fabricated from many of the varied crystals that exhibit electroluminescence may also be placed in the stimulated-emission mode. The use of this device provides the advantages of high external efficiency in both the incoherent and coherent modes,
long operating life, and compatibility with driving circuit employing silicon devices. In addition, the high external efficiency reduces the driving-power requirements, and may make possible the use of low-cost silicon integrated circuits. In some cases, the same technology may be employed for different crystals, and the further advantage of greatly reduced development cost results. The diodes which have been reported cover the near-infrared and visible portions of the spectrum. The light intensity may be modulated at frequencies approaching 1 GHz.

Applications for p-n junction light emitters range from electroluminescent displays to such electronic functions as card reading, character recognition, sensing, electro-optical switching, optical ranging, illumination, metrology, communication, intrusion alarms, control circuits, and warning devices. The non-laser diode appears to have a substantial advantage over the laser in present-day devices for display applications; however, the laser diode has distinct advantages for electronic-function applications.

In the following section, the nature of p-n junction luminescence is discussed, and the various crystal materials used in light-emitting diodes are classified according to the portion of the spectrum in which each emits energy.

**LIGHT-EMITTING DIODES**

In general, light is emitted from a p-n junction when the diode is forward-biased. Minority carriers are injected into the opposite-conductivity-type material, and a nonequilibrium condition is created which causes the carriers to recombine radiatively. External efficiency is proportional to the injection efficiency of the junction. Because the injection efficiency may approach unity when the junction is properly designed, the external efficiency may also approach unity.

There are many known semiconductor materials, and probably many unknown at this time, which emit light when properly fabricated into diodes. Fig. 1 shows various crystal materials and the portion of the spectrum in which they emit radiation. Table I lists these materials and indicates those which also provide laser action. With the exception of SiC, the materials fall into three groups: the III-V group and the II-VI group of the periodic table and lead salts. The lead salts emit radiation toward the far-infrared portion of the spectrum, while the III-V and II-VI groups cover the near-infrared and visible portions of the spectrum. The latter two groups exhibit considerable
overlap. Continuous coverage of the spectrum from the blue to the near-infrared region can be obtained by use of mixed crystals.

Generally, any one diode emits one strong line that has width in the order of 300 angstroms. The portion of the spectrum in which the diode emits depends on its forbidden-band energy and/or the position that the dopant takes in the forbidden band. Each semiconductor, including the mixed crystals, possesses a unique bandgap energy and emits a characteristic wavelength. With the crystals shown in Table I, the entire spectrum from 0.45 to 3.1 micrometers can be covered. Further investigation will probably extend this coverage out to 8.5 micrometers. If the II-VI compounds do not adequately cover the spectrum in the blue and near-ultraviolet regions, another group of materials will have to be investigated for this region.

GaAs light-emitting diodes have received more attention than other types for several reasons:

1) Existing military and industrial applications require this type of infrared-emitting device.

2) The emission of GaAs devices matches the quality of the p-n junction. It is difficult to form high-injection-efficiency junctions in some crystals. In the lead salts and the III-V compounds, both n- and p-type crystals may be obtained easily; therefore, homojunctions of high quality may be obtained. In the II-VI compounds, however, n- and p-type crystals of the same crystalline material are not always possible; as a result, heterojunctions must be employed. Because heterojunctions are usually inferior to homojunctions, particularly with respect to injection efficiency, the II-VI compounds are used as a last resort.

Crystalline defects are introduced during the construction of heterojunctions as a result of the mismatch (however small) in the crystalline structure of two different types of crystal. These defects produce energy levels in the band gap at the junction region of the diode. In most cases, depending on the defect density and its activation energy, these defect energy levels adversely affect the internal radiative recombination efficiency. The most probable result is that the defect levels cause a nonradiative recombination process which tends to reduce the radiative recombination efficiency. Moreover, heterojunctions usually require more complex technology, and there are problems which make it difficult to obtain reproducibly. If a choice exists, therefore, homojunctions are more desirable.

A disadvantage of using wide-band-gap materials for luminescent diodes is that low contact resistance is more difficult to obtain. These materials (particularly SiC and GeP) cannot be operated at high-current-density values because of their high contact resistance, coupled with the higher thermal resistance of diatomic and ternary compounds. These resistances serve to reduce the brightness of the emitted radiation. In addition, the impurity atoms assume energy levels within the band gap somewhat removed from the band edges, and result in large activation energies. This condition may lead to carrier freeze-out at low temperatures and render the diodes inoperative at such temperatures. However, improvements in technology and crystalline quality may minimize and perhaps even eliminate these problems.

GaAs diodes exhibit higher efficiencies than any other light-emitting diodes. This greater efficiency can be attributed to the higher crystal quality and more advanced fabrication techniques. Improvements must be made in other materials to match the performance of GaAs diodes. In principle, there is nothing to prevent any of the light-emitting diodes from attaining an internal quantum efficiency of unity. The external efficiency is usually low because of reabsorption and a small critical angle in most semiconductor materials.

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LASER STUDIES AT
RCA VICTOR RESEARCH LABORATORIES, MONTREAL
A Review

Laser research has been in progress for several years in the Montreal Laboratories of the RCA Victor Company, Ltd. This work has emphasized gas laser studies, and was a rather natural extension of the interests and technologies already existing as part of the extensive gaseous plasma physics activities in the laboratory. This paper describes laser investigations which have been undertaken in the fields of spectroscopy, interferometry and plasma diagnostics. Also presented is recent work involving the use of lasers for altering the population distributions in gas discharges. Results of several experiments on new, high-power carbon dioxide lasers constructed in the laboratory are also given. These devices have been used to generate watts of cw power with high efficiencies in the infrared and are of interest for several applications. In addition a summary is given of recent work on lithium-drifted silicon photodiodes for fast, high-sensitivity laser detectors.

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LASER research has been in progress for several years in the Montreal Laboratories of the RCA Victor Company, Ltd. This work has emphasized gas lasers and was a rather natural extension of the interests and technologies already existing as part of the extensive gaseous plasma physics research activities in the laboratory. Much of the laser work has centered on the plasma properties of lasing discharges and on the use of lasers as high-frequency coherent electromagnetic wave generators for plasma diagnostic applications. Lasers now provide sources having coherence properties comparable to sources previously existing in the microwave region, so that many of the conventional microwave diagnostic methods can be reapplied at optical frequencies. In addition, at the higher frequencies, new and important phenomena can be observed.

Associated with this work has been a continuing effort to improve the properties and operating characteristics of various solid state photon detectors in the visible and infrared spectral regions. Since the advent of lasers, much of the detector work has been directed towards optimizing certain detector properties (e.g. response time and spectral sensitivity) for particular laser systems.

In this paper the work in these several areas is summarized, and some of the more recent investigations are described in detail.

He-Ne AND CO2 GAS LASERS
Much of the initial work at RCA Victor in Montreal involved the use of helium-neon lasers. The gas discharge technology existing in the laboratory permitted the assembly of a variety of systems for the construction and assessment of lasing He-Ne discharges. A considerable portion of the early work was devoted to an investigation of the dependences of the oscillation properties on the various discharge parameters (i.e. current, pressure, mixture ratio, etc.). For this work a number of gas discharge tube configurations have been employed, involving electrodeless, as well as hot and cold cathode tubes and excitation by direct current and by rf and 60-Hz ac.

As one outcome of this work, RCA Victor has developed a low-cost (under $400) He-Ne laser designed for teaching and demonstrating optics in secondary schools and universities. A photograph of this RCA Victor Educational

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Laser is shown in Fig. 1. The unit incorporates Brewster angle windows and adjustable mirrors to permit access to the resonant cavity for more advanced experimentation. A dark plastic cover reduces the side light from the discharge tube while still permitting visible observation of the interior parts when the laser is turned on. The laser output is from both ends of the tube in two equal intensity beams (approximately 1 mW). This permits two independent experiments to be performed simultaneously with a single unit.

The advanced plasma tube design incorporates a concentric gas reservoir for long life and has unheated electrodes so that a simple power supply can be employed. The tube operates on either high voltage 60-Hz AC or on direct current which is provided from a power supply enclosed in the base. These lasers have been in use for an extended period in our laboratory and a number have been marketed in Canada. Typical tube lifetimes appear to be in excess of six months and several hundred hours of operation. When necessary, tube replacement can be carried out in a few minutes and at a very low cost. With optional modifications, operation can be achieved at any of the three main neon frequencies (i.e. 0.63, 1.15, or 3.93 micrometers).

These lasers can be invaluable for teaching optics as well as for general laboratory application. Fig. 2 illustrates with unretouched photographs how well the laser can be used to demonstrate ray tracing in geometrical optics. The optical components shown in the photographs are fabricated with transparent plastic which has sufficient internal scattering to make the beam visible and smoke is introduced in the air paths to make the photographs. With the intense coherent laser beam it is also easy to demonstrate phenomena associated with polarization, diffraction and interference. A kit of such experiments has been assembled to be marketed with the laser unit.

More recently, much of the research effort on gas lasers has been directed towards an investigation of the high power carbon dioxide laser. Laser oscillation in carbon dioxide was first observed in mid 1964 and by the end of 1965 it had been found that with the addition of nitrogen and helium to the carbon dioxide, very-high-power high-efficiency laser action would be attained. Continuous power outputs of several hundred watts at efficiencies up to about 20% have recently been reported and under pulsed (Q-switched) conditions peak powers of 50-75 kW have been demonstrated. When compared to other gas lasers these values represent and increase in cw power of one or two orders of magnitude and in efficiency of more than two orders of magnitude.

Because of this high power and efficiency, many possible applications for this laser are apparent. The principal output wavelength of the laser is in the infrared at about 10.6 micrometers in the middle of the 8 to 14-micrometer atmospheric “window”. In this wave-length region, absorption by the atmospheric gases is very small (≈ 0.1 drift). It is seen from these results that the oscillation typically occurs simultaneously on a number of the rotational lines in the P-branch of the vibrational band. (P-branch transitions are those in which the rotational quantum number J changes by +1; i.e. ΔJ = +1. In the Q-branch, ΔJ = 0; and for the R-branch, ΔJ = -1.) These lines, as mentioned above, are in the region of 10.6 micrometers and have a separation of about 0.02 micrometers (200 angstroms).

As the cavity is tuned slightly, very large changes in the relative intensities of these lines can be obtained. The

Fig. 5—Low-cost He-Ne laser for teaching and laboratory use developed by RCA Victor Research Labs, Montreal.
Fig. 2—Sample photographs illustrating the usefulness of the Educational Laser for demonstrating optical phenomena. (a) Prism refraction and reflection (internal and external). (b) Multiple refraction and reflection in a thick plate. (c) Multiple internal reflection in a rhomb. (d) Focusing by a simple lens. (e) Ray paths in a focused-beam Michelson interferometer.

Fig. 3—Energy levels of CO₂ and N₂ involved in the operation of the high-power carbon dioxide laser.

Fig. 4—Sample output spectra of the CO₂ laser for different cavity mode settings. Emission occurs on several rotational lines of the P-branch of the 10.6 μm band. Simultaneous oscillation in the R-branch can also occur but with much lower intensity.

Fig. 5—Comparison of the longitudinal mode spectra of the visible He-Ne and infrared CO₂ lasers in a 1.5-meter cavity (C/2L = 100 MHz). (a) Neon gain curve and resonator frequencies. (b) Multimode output spectrum of He-Ne laser. (c) Gain curves for 3 sample rotational levels in CO₂ and the associated resonator frequencies. (d) Single mode output on each of the 3 rotational transitions.
thermal drift can cause frequency and output variations such as those shown in Fig. 4. These variations can be controlled, however, by using appropriate methods to stabilize the optical cavity and to select the desired frequency.

Fig. 6 shows sample variations of the output power of a CO₂-N₂-He laser as a function of the current through the DC discharge at several pressures. Fig. 7 shows a photograph of the laser used to obtain the data of Fig. 6. The tube is 2 inches in diameter and has internal mirrors in the plane-parallel configuration separated by about 1.5 meters. Output coupling is by diffraction through a circular hole in one mirror. Typical optical power levels in the cavity are of the order of 100 watts with efficiencies between 5% and 10%. The same unit can be excited by 60 Hz AC.

As an indication of the power levels available, a 10-watt beam from this unit (obtained by using an output coupling aperture of only 6 mm diameter) unfocussed will ignite paper or wood across the room (10 to 20 ft). At distances up to 2 to 3 ft, an unfocussed 10-watt beam will penetrate asbestos and other refractory materials. The coarse tuning of the laser is most easily achieved by observing the brightness changes of the white-hot spot created as the beam impinges on a fire-brick. (Brightness temperatures measured with a pyrometer of the order of 2,000 degrees are typical.)

Fig. 8 shows a sample plot of the laser output power as a function of the pressure. For the gas mixture used here (approx. 10% CO₂, 10% N₂, and 80% He), Figs. 6 and 8 show that oscillation is attainable over a wide range of discharge conditions.

Since beginning work on the CO₂ laser a variety of discharge configurations have been used. Tube diameters between about 1.5 cm and 5 cm at lengths from 1.5 to 2.5 meters have been investigated and combinations of internal and external mirror systems have been employed. The system shown in Fig. 7 is air-cooled with only modest facilities for cavity stabilization. This unit is used as shown to examine the plasma effects on the laser oscillation. A 16-GHz microwave interferometer (seen in Fig. 7) is used to measure the electron density in the laser tube simultaneously with the other parameters (e.g. output power, current, pressure etc.) The interferometer can record phase shifts as small as 0.1° and permits electron density measurements down to densities of the order of 10¹⁰/cm³ in the laser.

A typical plot of the electron density is shown in Fig. 9 for current and pressure variations. It is interesting to note that the electron densities are of the order of 10¹⁰ with total particle densities of about 10¹³ showing that the degree of ionization in the laser is very small (of the order of 10⁻⁴). This again demonstrates the efficiency of the system since energy present as ionized species represents a loss to the laser output.

In addition to the investigations described above, present work on the CO₂ laser includes spectroscopic studies of the discharges using conventional and stimulated transition spectroscopy (described in the following section). For this work both steady state and pulsed discharges are employed. Propagation through the atmosphere and plasma is also being investigated.

**LASER SPECTROSCOPY**

The Laboratory has been involved for some time with the study of the spontaneous sidelight emission of gas lasers. As a result of this work it has been shown recently that the strong optical frequency field generated by a laser is capable of producing a significant change in the population distribution of the excited atoms in a gas discharge.

Although the primary change in population occurs for those levels which have an energy difference corresponding to the laser frequency, changes of population will also occur for other levels that are connected to the "primary" levels via radiative transitions or via nonradiative collisional transitions.

The changes in population of the various levels can be readily detected by the changes in the intensity of the spontaneous emission. Using a modulated laser beam and a phase-sensitive detection system it is possible to measure very small changes in the spontaneous emission and hence very small changes in the population of the various energy levels involved.

This technique of using a laser to alter populations in a gas discharge and of studying the resultant changes in the spontaneous emission from the...
various levels with phase sensitive technique shall be referred to for brevity, as stimulated transitions spectroscopy (STS). This technique, although similar in some ways to fluorescence spectroscopy differs in several respects. The STS can involve either stimulated emission, or absorption caused by the laser field, depending on the relative populations of the upper and lower "primary" levels. The method can be applied for the study of a variety of radiative and collisional processes in any gas discharge in which there are primary energy levels which are "resonant" at a laser frequency. Because of the "cascading" processes resulting from the change in the population of the primary levels, STS can provide information about energy levels separated by sizeable energy differences (e.g. several eV) from the primary levels. The use of the phase sensitive detection system also provides a direct indication of direction of the change in the population (i.e. an increase or a decrease) from the sign (+ve or -ve) of the signal with reference to the laser beam.

The usefulness of the STS method has been demonstrated by its application to the well-known competition between the 0.6328-micrometer and 3.39-micrometer transitions in a He-Ne laser. The apparatus arrangement used is shown schematically in Fig. 10. A He-Ne gas discharge tube (approximately one meter long) with Brewster-angle windows is positioned between the mirrors in a conventional laser configuration and oscillation is obtained at the desired frequency (0.6328 or 3.39 micrometers). The laser beam is chopped at a convenient frequency (between 10 and 100 Hz) by a rotating chopper inside the optical cavity and a monochromator is positioned to receive (using a lens-mirror arrangement) the spontaneous emission from the side of the discharge tube over a small length ( ΔL). The chopper blade material is selected to ensure that the laser beam is interrupted with minimum perturbation to the other optical frequency fields in the cavity.

The output of the monochromator is fed into a phase-lock amplifier together with a reference signal produced by the chopper. The resultant output signal from the phase-lock amplifier is displayed on an X-Y recorder or oscilloscope. Using this arrangement it is possible to detect the small changes in the spontaneous emission (sidelight) from the discharge brought about by the switching off and on of the laser beam.

Provision is also made to allow the monochromator signal to bypass the phase-lock amplifier and go directly into the recorder to provide a conventional display of the sidelight spectrum. The system is arranged so that a positive signal from the phase-lock system indicates an increase in the sidelight emission when the laser is on, while a negative signal means a decrease in the sidelight intensity when the laser is on. The system can be made to oscillate at either 0.6328 or at 3.39 micrometers separately, or at both frequencies simultaneously by introducing appropriate filters into the optical cavity.

**Fig. 8** — Sample variations of CO₂ laser output power with pressure.

**Fig. 9** — Electron density variations in a CO₂-N₂-He laser discharge, as a function of the discharge current.
With the laser oscillating only at 0.6328 micrometers, a spectrum of the spontaneous emission from the side of the discharge tube as recorded by the phase-lock system is shown in Fig. 11a. As indicated above, the positive peaks in Fig. 11 represent spontaneous transitions that are increased in intensity as a result of the laser beam whereas the negative peaks show transitions that are reduced because of the laser field, hence the positive peaks can be expected to arise from transitions originating from levels whose populations have been increased by the action of the laser field. Conversely, the negative peaks will be associated with transitions from levels whose populations have been decreased.

The information of Fig. 11 can be more meaningfully summarized in the form of the energy level diagram shown in Fig. 12. In this figure, the primary laser transition is shown as a heavy wavy line. The transitions corresponding to the positive peaks in Fig. 11 are indicated by solid lines and those corresponding to the negative peaks by dashed lines.

In Fig. 11b a sample low dispersion phase-lock spectrum of the spontaneous sidelight emission is shown for the laser oscillating at 3.39 micrometers under the same discharge conditions as for the 0.6328-micrometer oscillation.

It will be observed that many of the positive and negative peaks shown in Fig. 11a have reversed polarity in Fig. 11b. This is because of the competition between the 0.6328-micrometer and 3.39-micrometer laser cascades (illustrated in Fig. 12) which have a common upper level.

The sample results presented here illustrate the effectiveness of the srs technique for examining population changes in gas discharges. It has been found that the method is useful for detecting changes in levels which are separated by sizeable energy differences from the "primary" levels stimulated by the laser field. As shown in Fig. 12, population changes resulting from three- and four-step radiative processes are readily detectable by this method. Although the above illustration involves the analysis of a gas discharge in which lasing action is occurring, the method can be applied to any gas discharge system having energy levels resonant with the laser frequency. These systems can be placed either internal or external to the optical cavity of the laser used to provide the primary field. We are at present using the srs method on a variety of gas discharges external to the laser cavity and have found that, by

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Fig. 11—Sample spectra obtained from the phase-lock system in the wavelength range from 0.35 μm to 3.5 μm for laser oscillation at (a) 0.6328 μm, and (b) 3.39 μm.

Fig. 12—Neon energy level diagrams showing the more prominent transitions observed in Fig. 11. The solid lines indicate spontaneous emissions increased by the laser field (+ve peaks in Fig. 11) and the dashed lines indicate emission decreased by the laser field. Laser oscillation is at (a) 0.6328 μm, and (b) 3.39 μm.
focussing the laser field it is readily possible to measure the population changes. Most of the present work is being done with CO₂, N₂, and He discharges because of our interest in the carbon dioxide lasers.

One of the main advantages of the srs method lies in the fact that, because of the phase sensitive detection, only those levels undergoing population changes (via radiative or collisional mechanisms) are recorded in the spectra and the direction of the population change is unambiguously determined from the sign of the output signal. As a result, it is known that any emissions recorded by this method, indicate transitions from only those levels which are interacting with the primary "stimulated" levels. In this way, one is in effect "tagging" the atoms or molecules which undergo the stimulated transition and then observing their redistribution throughout the whole cascade of accessible energy levels. Measurements of the intensity changes in the spontaneous emission recorded by the srs method can be used to provide quantitative information regarding collision cross sections and Einstein coefficients in the discharges but for accurate work of this type it is essential to take into account all of the transitions affecting the population of the levels involved. For energy levels two or three "steps" below the primary levels, the effects of several competing transitions on the population may be difficult to assess.

One final feature of the method should also be pointed out. Since, in the present studies it is shown that the modulation (chopping) of the laser beam intensity is manifested as a modulation of the laser sidelite at a variety of frequencies, any one of these frequencies could be used to monitor variations in the laser signal. For example, the strongly modulated emission at 0.3593 micrometer can be used to measure variations in the 3.39-micrometer laser intensity. This is an advantage since the detectors available at 0.3593 micrometer (e.g. photomultipliers) are more sensitive than those available at 3.39 micrometers. This approach could be used to generalize the plasma diagnostic technique involving a three-mirror laser interferometer system described recently by Ashby and Jephcott. Using a laser which was oscillating at both 0.6328 and 3.39 micrometers, these authors used the variations in the 0.6328 micrometer laser emission to monitor the variations in the 3.39 micrometer signal in the interferometer. However, the 0.3593 micrometer spontaneous emission could equally well have been used with oscillation at 3.39 micrometers only.

**PLASMA DIAGNOSTICS**

There are several possible methods of applying lasers for plasma diagnostics. The most straightforward approach is to use a laser source in an interferometer system to measure the refractive index of the plasma and from this to deduce the plasma properties. For an electromagnetic wave of wavelength λ, traversing a path length L in a plasma with refractive index n, it is known that the phase shift, Δφ of the wave (in radians) with respect to a vacuum path of the same length is given by:

$$\Delta \phi = \frac{2\pi L}{\lambda} (n - 1).$$  

(1)

The quantity (n - 1) is the "refractivity" of the plasma, and in general, a property dependent upon all of the plasma constituents, i.e. electrons, ions and neutral atoms. In fact it is possible to write the refractivity as a sum of terms of the form:

$$n - 1 = (n - 1)_{\text{plasma}} + (n - 1)_{\text{atom}} + (n - 1)_{\text{molecule}} + (n - 1)_{\text{ion}}$$  

(2)

where each term can be expressed in terms of the basic plasma properties. For example, at high frequencies the refractivity of the free electrons is given by:

$$n - 1_{\text{electron}} = \frac{-\omega_p^2}{2\omega^2}$$  

(3)

where ω is the angular electromagnetic wave frequency (ω = 2πf) and ωp is the plasma frequency defined by:

$$\omega_p^2 = N_e \frac{e^2}{m_e}$$  

(4)

with $N_e$ = electron density, $e$ = electron charge, $m$ = electron mass, and $\varepsilon_0$ = permittivity of free-space. Inserting appropriate values of the constants, gives for the electron refractivity the result:

$$(n - 1)_{\text{electron}} \approx -4.47 \times 10^{-18} \lambda N_e$$  

(5)

where λ is in cm and $N_e$ is electrons/cm².

For the atoms (and molecules) it is possible to express the refractivity in terms of the polarizability, α, which is related to the separation of the bound charges in the atom (or molecule) brought about by the applied electric field. The result is of the form

$$(n - 1) = 2\pi N_e \alpha$$  

(6)

where $N_e$ is the number density of the atomic (or molecular) species.

For the ions in the plasma the establishment of the refractivity by either theory or experiment is quite difficult. In many cases of interest the ion value is found to be of the same order as that for the corresponding neutral atom and the usual practice is often to set them equal.

Substitution of Equations 2 through 6 in Equation 1 gives for the total phase shift in the plasma:

$$\Delta \phi = \frac{2\pi L}{\lambda} \left[ \sum_i 2\pi N_i \alpha_i - 4.47 \times 10^{-18} \lambda N_e \right]$$  

(7)

where the summation is over the several atomic, molecular, and ionic species in the plasma. It is seen from Equation 7 that the electrons shift the phase in the opposite direction, to the other plasma constituents and this fact can be utilized to extract the electron effects from the others.

In the microwave region the electron refractivity is the dominant term and the electron density can be determined to a good approximation by retaining only the final term on the rhs of Equation 7. At optical frequencies, however, this is not the case.

Most common neutral gases at NTP have optical refractivities of the order of:

$$n - 1 = 2 \times 10^{-4} \approx 5 \times 10^{-6} N_e$$  

(8)

For an optical wavelength of 1 micrometer (10⁻⁴ cm) the electron refractivity of Equation 5 would be

$$(n - 1)_{\text{electron}} \approx 5 \times 10^{-6} N_e$$  

(9)

Equations 8 and 9 show that the refractivity per particle is generally much larger for electrons than for the other species. Since the minimum optical phase shifts detectable in practice are of the order of 3° (0.01 fringe) it is apparent that for experimental systems the condition $[L(n - 1)/\lambda] > 0.01$ must be satisfied. For a wavelength of 10⁻⁴ cm and a path length of 1 cm, this results in the condition that the refractivity must be greater than 10⁻⁴ (for $L = 100$ cm the refractivity need only be greater than 10⁻³). The required densities of neutral gas and electrons to satisfy this condition can be derived
from equations 8 and 9 and are given in Table 1.

In most plasmas of laboratory interest the degree of ionization is low so that \( N_i \) is generally less than 0.1 \( N_e \). Hence the sample calculations above illustrate why all constituents of the plasma must be included in the analysis of laser interferometry of plasmas. Also, it is apparent that even for rather sizeable path lengths, electron densities can only be measured with any accuracy at optical frequencies if they exceed about \( 10^3 \text{cm}^{-3} \).

This minimum measurable density can be reduced by using longer wavelengths in the infrared region. In considering this approach, however, it is to be noted that although the refractivity increases as \( \lambda^2 \), the phase shift only increases as \( \lambda \), for a given path length \( L \) in the plasma, since there are fewer of the longer wavelengths in the plasma. This wavelength dependence can also be used to separate the electron contribution to the refractivity from the other contributions listed in Equation 2.

In our laboratory, at present the above interferometric techniques are being applied at visible, infrared and millimeter wavelengths to several plasma systems. Of particular interest are plasmas generated in the various laboratory flow facilities designed to simulate re-entry and rocket exhaust plasmas. These plasmas in general exhibit properties which change rapidly in space as well as in time (e.g. turbulence) and in good resolution available with laser beams is a great advantage. Experimentally, however, problems are encountered with the systems at optical frequencies because of the need to suppress all extraneous vibrations in the interferometer before accurate measurements can be made.

Another laser technique for plasma diagnostics involves the measurement of the scattering of laser light by a plasma system. The scattering of light by elastic or acoustic waves is a well known technique for measuring the properties of the waves and the medium involved. Brillouin" in 1922 showed that the angular frequency \( \omega\) of the incident light is shifted to \( \omega_i \) and the frequency shift \( \omega_s \) is given by the equation

\[
\omega_s = \omega_i - \omega = 2\Gamma v \sin \theta/2 \quad (34)
\]

where \( \Gamma \) is the wave number of the light in the medium along its incident direction (equal to the refractive index of the medium times \( \omega/c \)) and \( v \) is the velocity of the acoustic waves in the medium; \( \theta \) is the angle of scattering measured with respect to the incident light.

One may similarly obtain scattering of light from a plasma medium in which electrons have an inherent frequency spectrum of longitudinal oscillations. The scattering of light by electrons is known as Thomson scattering. Since in a plasma, the longitudinal oscillation frequency \( \omega \) of the medium can be anywhere between zero and an upper limit of the order of the plasma frequency, the laser frequency shifts also exhibit this spectrum, with corresponding changes in the direction of the beam. This phenomenon is the cause of "Doppler broadening" of a laser beam in a plasma medium. The Thomson scattering of light by plasma electrons is very difficult to observe experimentally unless an extremely bright monochromatic laser and a high density plasma interact, because the cross-section for Thomson scattering is very small. Great care must be taken to reduce the stray scattering of the laser beam in the apparatus so that the plasma scattering can be measured.

Theoretically, a detailed examination of the laser-plasma interaction shows that the scattering cross-section in a plasma medium is not given only by the Thomson scattering cross-section (applicable to free electrons), but by a very complicated relation. The scattering is a function of plasma parameters such as electron and ion temperatures and densities, and of the laser frequency, the angle of scattering, the frequency shift of the scattered radiation, the bandwidth of the detector and the solid angle subtended at the receiver.

At Montreal, considerable theoretical work on laser scattering by plasma has been carried out by Dr. Shkarofsky. In addition to a detailed analysis of the Thomson scattering, Dr. Shkarofsky has investigated a variety of ways in which a scattered laser beam can be utilized to measure the statistical single particle distribution functions for plasmas in the density range from \( 10^6 \) to \( 10^9 \) charge-carriers/cm\(^3\). Starting with an investigation of the Thomson scattering off ambient plasma oscillations, the work has been extended to consider multiple-beam scattering systems in which the laser beam is scattered off oscillations induced in the plasma. It is planned to undertake the experimental investigation of these phenomena in the near future.

**STUDIES OF FOCUSED COHERENT BEAMS**

As part of our laser research program there has been an active investigation of some of the special properties of highly focused coherent beams. The interest in the focal properties of coherent beams arises on the one hand from a desire to know more about the ultimate in "resolution" attainable with focused laser beams and on the other by the desire to utilize focused laser radiation for the generation of optical frequency fields with extremely high field strengths and energy densities.

In such studies we have found it extremely useful to examine the focal properties at millimeter-wave frequencies instead of at the optical frequencies. In the microwave wavelength range between about 2 and 8 mm, 150-GHz to 35-GHz "optical" systems can be set up (i.e. systems whose dimensions are much greater than the wavelength) and the electromagnetic fields can be probed directly for amplitude and phase information much more accurately than at optical frequencies. Two such recent investigations are described below.

**Resolving Power of Focusing Systems with Coherent Illumination**

In any real focusing system, the image of each source point is a diffraction pattern of finite extent whose shape and dimensions depend on the geometry of the system and the wavelength of the radiation.

Where the source points are completely incoherent, the resultant intensity pattern in the focal plane is obtained by the direct summation of the individual intensities at each point. In order to perform these summations it is necessary to have a complete and accurate knowledge of the coherent nature of each point source. This knowledge is often available in the form of the amplitude and phase of the field at each point source. In order to specify these quantities for each point source, the intensity and angular spectrum of the laser must be known. The laser intensity spectrum is usually specified by the laser power radiated per unit frequency.
this case, it has been found convenient to apply the so-called Rayleigh criterion for the limit of resolution. This criterion states that two source points are resolvable when their image separation is greater than the separation between the central intensity maximum and the first minimum in the diffraction pattern of either image.

If the energy radiated by the source points is coherent, the composite pattern in the focal plane can only be obtained by summing (vectorially) the individual field amplitudes, taking into account the phase relations existing between them\(^1\)\(^,\)\(^2\). The resultant is then squared to give the true intensity distribution. When this is done, it is found that sizeable variations in the limit of resolutions can be obtained depending on the relative phases of the source points.

The variation of the resolving power of a focussed system has been examined theoretically for the three following cases:

1) two incoherent source points,
2) two in-phase coherent source points,
3) two antiphase coherent source points.

This was done by computing the resultant intensity pattern in the focal plane from two image diffraction patterns of unit maximum intensity of properties corresponding to the three above cases, for various separation distances between the individual patterns.

Fig. 13 shows two of a series of composite plots corresponding to separation distances \(\delta\) of 4.19 and 4.91 respectively which illustrate clearly the effects of coherent sources on resolving power. It is observed that while the resultant pattern for incoherent source points is well resolved, that for the coherent ones is still unresolved. On the other hand, it is apparent that the antiphase coherent sources because of the symmetry of the system will always produce a zero intensity image at the midpoint \((q = 0)\) of the pattern and in this respect, will always be resolved no matter how small \(\delta\) is made.

The large variations in the resultant of the coherent energy patterns caused by side lobe effects are evidenced in Fig. 13. For \(\delta = 4.91\) the main lobe of one pattern coincides closely with the first side lobe of the other. With uniform illumination the amplitude of the first side lobe is only 0.132 for a contribution of about 2\% to the total intensity. In the case of coherent sources, the side lobe effects are much more pronounced. For in-phase sources, the overlapping lobes are 180 degrees out of phase and the resultant intensity is given by \((1 - 0.132)^2 \approx 0.75\) showing a 27\% reduction from the corresponding incoherent intensity. Conversely, for antiphase coherent sources the effect of the side lobe is additive and the resulting intensity is increased by 26\% over that of the incoherent case.

It is apparent from the results that, the in-phase coherent source points are not resolved as easily as the incoherent ones. This situation is clearly illustrated in Fig. 14 where the value of the intensity \(I_\infty\) at the central minimum of the composite intensity pattern is compared to the intensity \(I_s\) of the side maxima as function of separation \(\delta\). A pattern is defined as resolved when \((I_\infty/I_s) < 1\), and the smaller the ratio, the better the resolution. [For antiphased sources, \((I_\infty/I_s) \equiv 0\).] One can observe that for a given resolution the minimum achievable \(\delta\) separation values are always less in the case of incoherent source points.

In an effort to examine how well the foregoing simple theory would describe the conditions attainable in a real focussing system, experimental measurements of the resolving power of a single lens system were conducted using coherent electromagnetic waves at microwave frequencies (34.45 GHz, wavelength 8.7 mm).

The system used for the measurement is shown schematically in Fig. 15. From a single klystron source the transmission line divides into two flexible branches terminated by open ended waveguide antennas that can be symmetrically positioned on either side of the system axis. Calibrated variable attenuators and 360\° phase shifter inserted at appropriate positions provide accurate adjustment of signal intensities and variation of relative phase.

Two series of experimental measurements were carried out. One with the in-phase sources \((\Delta \phi = 0)\) and one with the antiphase sources \((\Delta \phi = 180\°)\). Sample results are shown in Fig. 16 for two different separation distances \(\delta\) in the case of in-phase sources. The agreement with theoretical computations is very good. The effects of the side lobes on the composite patterns are readily apparent in the experimental curves where the intensity at the peaks of the composite plot is about 30\% lower than the intensity of the individual sources because of the overlapping of oppositely phased main lobe and side lobes.

The results obtained with antiphase sources show similar effects and also a close agreement with the theoretical computations. In addition, measurements were made for several values of the relative phase between the two above extremes. As would be expected, the results present effects intermediate to those described.

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**Fig. 14**—(a) Sample of a resolved pattern, (b) comparison of the resolution for coherent and incoherent source points as a function of their separation \(\delta\).

**Fig. 15**—Schematic diagram of the microwave system (34.5 GHz).
Longitudinal Electromagnetic Field at the Focus of a Coherent Beam

In a recent paper, Boivin and Wolf have published a detailed theoretical analysis of the structure of the electromagnetic field in the region of the focus of a coherent beam which emerges from an aplanatic imaging system. Since their analysis was not limited to a scalar diffraction theory, they were able to exhibit the vectorial features of the focussed beam. As a result, it was found that the field has a strong longitudinal component in certain regions in the neighborhood of the focus. An experimental examination of this phenomenon was undertaken in the laboratory and the measurement of this longitudinal component in a wide-aperture microwave lens system has been achieved.

The apparatus used was a simplification of that shown in Fig. 15. The orientation of the receiving waveguide could be adjusted to detect either the longitudinal or transverse electric field intensity \( I_L \) and \( I_T \), respectively, by coupling to the \( TE \) mode of the waveguide. The angle subtended by the lens at the focus was \( 46^\circ \) (i.e., the notation of Reference 13, \( \alpha = 23^\circ \)). The test was conducted at a microwave frequency of 34.5 GHz (8.7-mm wavelength).

In Fig. 17, superimposed results are shown for scan of the transverse and longitudinal field intensities in the focal plane. The scan was made in the direction of the incident-field electric vector (i.e., \( \phi = 0 \) in Reference 13). The field intensities \( I_T \) and \( I_L \) (proportional to the squares of the electric field amplitudes) are shown, on a decibel scale, as a function of the transverse position in the beam.

Since Boivin and Wolf have given computations only for \( \alpha = 45^\circ \) and the experiments are for \( \alpha = 23^\circ \), it is not possible to make a complete comparison, but, in general, the results (e.g., Fig. 17) are in good agreement with the theoretical predictions. The measured “dipole” nature of the field contours is essentially identical to that computed theoretically. The longitudinal field intensity is seen to have a “zero” value at the focus and in the \( \phi = \pi/2 \) direction, but to show a series of peaks symmetrically placed on opposite sides of the optic axis in the \( \phi = 0 \) direction.

Scaling the results of Reference 13 for the present system indicates that the maximum value of \( I_L \) should occur in the \( \phi = 0 \) direction at about 0.9 wavelengths from the axis, and this is very close to the experimentally measured position shown in Fig. 17. The relative positions of the maxima and minima of \( I_T \) and \( I_L \) shown in Fig. 17 are also in agreement with the theory.

Similar good agreement between the theory and experiment is found in the relative peak magnitudes of \( I_L \) and \( I_T \). The peak longitudinal field amplitude computed by Boivin and Wolf is about 28% of the peak transverse field amplitude and the measured value is \(-11\) dB which gives a longitudinal field amplitude about 29% of the transverse field. This excellent agreement may be somewhat fortuitous since the computations were for a wider aperture system, and the experimental measurements will undoubtedly show some errors arising from field perturbations caused by the receiver. However, the results demonstrate clearly the existence of the strong longitudinal field in the focal region.

In addition to the results shown, some measurements have been made with sources having nonuniform amplitude distribution across the lens. Since the microwave beams can be “shaped” rather conveniently, measurements at microwave frequencies can be used to obtain information on the longitudinal field distribution for focussed laser beams having more complex amplitude distribution.

**Fig. 16**—Sample comparison of experimental and theoretical field distributions in the focal plane for two coherent, in-phase source points.

**Fig. 17**—Measured variations in the transverse and longitudinal electric field intensities \( I_L \) and \( I_T \) in the focal plane. Scan is in direction of \( E \)-vector of the source.

**Fig. 18**—Quantum efficiency of a conventional silicon p-n diode and lithium drifted diode as a function of wavelength.

**Silicon Photodiode Laser Detectors**

Both the mesa and planar types of silicon diode developed in these laboratories make excellent photodiodes for a wide variety of applications in the visible part of the spectrum. However, with the advent of near-infrared lasers there has been an increasing need for fast detectors in the 0.7 to 1.15 region, and the conventional photodiode is not especially suitable for this purpose for three reasons, all of which hinge on the relatively very thin depletion layer attainable. Firstly, a thin depletion layer gives a high capacitance per unit area which, particularly for large-area devices reduces a system’s high frequency performance; and secondly, at these near-infrared wavelengths the absorption coefficient of silicon be-
comes small, causing poor quantum efficiency unless the absorbing region is relatively wide. Thirdly, unless the total thickness of the conventional device is very small it cannot be fully depleted, so that the residual base material acts as an undesirable series resistance which again handicaps the device's speed of response. For certain applications, restriction of the area of conventional photodiodes to about 2 cm² (for technological reasons) is also undesirable. These limitations have now been overcome in our laboratory by the development of a special type of thin-window lithium-drifted diode fabricated from a p-type silicon wafer about 1 mm thick having an area up to 4 cm². After performing a shallow diffusion of boron on one side, lithium is diffused into the opposite side and then drifted through to the boron layer. The diode is then encapsulated in such a way that radiation can enter through the boron-diffused surface. Since the entire body of the device is compensated, the depletion layer created by a reverse bias extends completely across from the n⁺ layer to the p⁺ layer, resulting in good quantum absorption, low capacitance, and negligible series resistance. Such photodiodes, when antireflective coated, have quantum efficiencies exceeding 80% at 0.7 and 0.9 micrometers 60% at 1.06 micrometers, and 20% at 1.15 micrometers with a collection time of less than 40 ns, a leakage current of about 1 µA/cm² and a capacitance of 10 pF/cm². Sample spectral response of these devices is shown in Fig. 18 and response time data is given in Fig. 19.

This new form of photodiode also enables multi-element devices such as arrays or four-quadrant configurations to be readily made by ultrasonically cutting into the depletion layer from the lithium-diffused (rear) surface, as shown in Fig. 20. This technique gives excellent electrical isolation between elements together with remarkably narrow blur widths (as little as 0.1 mm) and yet no dead space between elements. Photographs of completed units are shown in Fig. 21.

Another feature of the device is that, if it is reversed before encapsulation, the inherently thick dead layer met by radiation entering through the lithium-diffused surface results in a narrow wavelength region of sensitivity (about 0.1 micrometer wide, centered on 1.06 micrometers). This aspect becomes important if the device is used to detect radiation from the 1.06-micrometer neodymium laser in the presence of strong background, such as sunlight.

CONCLUSION

This article has outlined a number of areas of laser research currently being undertaken at the RCA Victor Research Laboratories in Montreal. Because of the rapid state of development in the whole laser field it is difficult to predict with any accuracy the fields of greatest activity in the future. However, as far as gas lasers are concerned it is evident that in the next few years, there will be a considerable effort made to develop more and better molecular lasers with frequencies extending further out into the infrared and submillimeter range.

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BIBLIOGRAPHY

QUANTUM ELECTRONICS RESEARCH
AT RCA LABORATORIES

An Introduction

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Several years ago in an introductory article on laser research it was necessary to try to explain how the laser works. In one way, that was fortunate because at that time there were few working laser devices and even fewer applications. In the absence of anything more concrete, discussions of the physics of quantum electronics, of "promising" new materials and of rather grand applications—a thousand TV channels carried on a single light beam—were in order. Today, however, the situation is quite different. Technical people are accustomed to the laser and are now available with a wide variety of operating characteristics. A very encouraging aspect is the undiminished rate of progress in devices; for example, in the past 18 months a gas laser (CO₂) has been developed with an efficiency 2 orders of magnitude better than that previously available. Time, and the availability of better devices have provided some specific applications and the issue in which this article appears contains accounts of a number of applications of interest to RCA. Thus we can afford to abandon background material and discuss meatier topics.

One role of the Laboratory in quantum electronics has been to supply basic knowledge and specific devices to the operating divisions of RCA for application. The applications which have come along earliest are in the military field because in that era a very small margin of improvement can be well worth exploiting. The more difficult problem of commercial applications is being pursued largely at the Laboratory, but here there is less which can be currently discussed. This is a result both of the proprietary nature of such work and of the slower rate of progress towards more difficult goals. It is interesting to speculate, however, on the apparent decrease in discussion of commercial laser applications in the public press in the past year. It may very well mark the transition from dream-applications, which can be freely discussed, to real ones.

A good example of the Laboratories' role in Corporate work in quantum electronics lies in the injection laser. A technique of liquid-phase epitaxy developed by H. Nelson produces superior laser diodes for room-temperature applications; the technique itself has been adopted for production at the Somerville plant by Lamorte. At the same time devices developed by J. I. Pankove, H. Nelson, and G. C. Dousmanis have been incorporated into novel communications and radar systems by W. J. Hannan and his co-workers at DEP Camden. With superior diodes DEP has been able to get increased government support for its development work. To hold this kind of advantageous position the Laboratory must continue to explore new techniques for producing still better injection lasers. One possibility is in the use of vapor-phase growth of alloys emitting at shorter wavelengths; J. Tietjen, I. J. Hegyi, H. Nelson, and J. I. Pankove are investigating this possibility with GaAsP.

In the components field, K. G. Herquist and J. R. Forsley have developed a superior argon gas laser that offers substantially better life than any announced by our competitors. It has given RCA Lancaster the opportunity to enter into the laser field with a new and valuable device. Z. J. Kiss, R. C. Duncan, and R. J. Pressley have produced a new optically pumped laser, the first in which pump efficiency is improved by "cross-relaxation." In this kind of device an ion with appropriate absorption bands (trivalent chromium) absorbs energy from a mercury lamp and then transfers it to a different ion (trivalent neodymium) with a favorable emission line for laser purposes. The host material for these ions is yttrium aluminum garnet from which a device has been made which generates an average of 10 watts of power in the infrared. Detection of infrared radiation still presents problems because the conventional photoconductive detector is either insensitive or slow. H. S. Sommers and E. K. Gatchell have demonstrated that greatly improved detectors can be achieved by using a microwave bias for the photoconductor.

Starting with some ideas which were an outgrowth of the work on optically pumped lasers, C. H. Anderson and E. S. Sabisky have produced an optically-pumped, low-noise microwave amplifier. This work represents the first new development in some years in the first of the quantum-electronic devices, the maser. L. Morris, at Applied Research Camden is currently carrying out further experiments to evaluate its practical promise. In the applications area, H. J. Gerritsen, D. L. Greenaway, and E. G. Ramberg have been working for some time with holograms, to evaluate their potential for display systems. Similarly, D. Vilkomerson and R. Mezrich have been interested in hologram memories for computers.

Many other commercial applications of the laser are possible. To realize them, we need not only better lasers, but improved components of all kinds to go with them. These components include modulators, detectors, and new recording media. In the future, the Laboratory will continue to look for new ways to improve and use these components. At the same time, it will expand its use of the laser as a very advanced tool for new scientific studies.

DR. HENRY R. LEWIS received AB, MA, and PhD degrees from Harvard University in 1948, 1949, and 1956 respectively. In 1950 and 1951 he was a teaching fellow in physics at Harvard. His PhD thesis was a study of distortions observed in nuclear resonances using the molecular beam technique. From 1951 to 1953, and for a year after receiving the doctorate, he worked with the Operations Evaluation Group of the Massachusetts Institute of Technology on various problems in naval warfare. Dr. Lewis joined the Technical Staff of RCA Laboratories in 1957 and worked on new paramagnetic materials for masers. In 1960 he became head of the Quantum Electronics Group whose projects included masers, lasers, and associated devices. He is now Director of the Electronic Research Laboratory.
ARGON LASERS

In argon lasers excited ions produce the laser radiation. From the laser physics point of view there are several advantages in using charged particles for lasing. The associated laser tube construction problems have recently been overcome, making it possible to manufacture reliable, long life argon lasers. In spite of the low efficiencies presently attainable, several promising applications are being studied where the continuous-duty argon laser operation in the visible wavelength region is made use of.

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In gas lasers, excitation of atoms for lasing is due to impact by fast electrons. The interaction takes place in a gas discharge type plasma. Such a plasma consists of neutral atoms, ions, and fast moving electrons. A characteristic, and for laser operation very important, property of such plasmas is the high electron temperature, which may be several orders of magnitude higher than the temperature of the neutral gas or the ions.

GAS LASERS USING THE NEUTRAL GAS FOR LASING

In one class of gas lasers, of which the famous He-Ne laser is a member, the excited neutral atoms do the lasing. These lasers yield only low power and, except for the He-Ne laser, are limited to wavelengths in the infrared region. The limitations of this type of gas laser are exemplified by the energy level scheme sketched in Fig. 1. Generally, electrons excite ground-state atoms both to the upper and lower laser level. For population inversion to occur the lifetime of the upper level must be much longer than that of the lower level. This means that the radiative transition probability from state $u$ to state $g$ must be low and that corresponding to the transition $l$ to $g$ must be high. In order to overpopulate the upper level the opposite would be desirable for the probability of impact excitation by the electrons. Unfortunately a correlation exists between the radiative transition probability and the impact excitation probability. If one is high the other is high. Another difficulty concerns the reabsorption of radiation corresponding to the $l-g$ transition (resonance radiation). Not only must the lifetime of state $l$ of the individual atoms be low but the radiation must immediately leave the plasma region. This requirement sets limits on the neutral gas pressure and thus on the number of available lasing atoms.

GAS LASERS USING THE IONIZED GAS FOR LASING

Both of the above discussed limitations are alleviated in the more recently discovered ion lasers. Here the ions are excited to do the lasing. Excitation is achieved by electron impact. Since this excitation interaction takes place between two charged particles, Coulomb forces affect the excitation probability. It is then possible to have a high excitation probability and a low radiative transition probability. Another advantage of having the lasing particles charged has to do with the outlet of resonance radiation from the plasma. The ions can be preferentially accelerated by electric fields to give the equivalence of a high ion temperature which broadens the lines and minimizes the absorption of the resonance radiation corresponding to the transition below the lower lasing level. A price has to be paid for these advantages in terms of a more difficult tube-building technology. Since the ions are in effect a continuously produced “lasing gas,” a high plasma density is called for to obtain a sufficient number of lasing particles. This high density plasma has a destructive influence on the plasma-confining structure as will be discussed further below.

The “ion gas” produced in these lasers has electronic properties quite different from those of the neutral gas. These properties and the above-mentioned ad-

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Fig. 1—Energy level diagram illustrating gas laser operation.
Advantages have made possible a large number of new gas laser transitions throughout the visible part of the spectrum. Many gases and metal vapors have been made to lase in the ionized state. From the tube construction point of view, the noble gases are easiest to handle. Of the different gases argon is the most efficient in lasing.

**Properties of Low Pressure Laser Discharges**

The most common type of discharge tube used for gas lasers is shown schematically in Fig. 2. It consists of a thermionic cathode and an anode separated by the long plasma confinement structure. The confinement structure constrains the discharge into a narrow straight column allowing line of sight passage between the two Brewster angle windows and along the axis of the tube. The two external mirrors form the optical resonator.

The type of discharge taking place in the argon ion laser is characterized by a very high current density (500 to 1,000 A/cm²) in the narrow bore and a relatively low gas density (corresponding to an equivalent pressure of a few hundredths of a torr). This type of low pressure discharge was studied in detail by Tonks and Langmuir. One significant consequence of the low pressure operation is a long ion mean free path. Ions generated in the plasma travel quickly to the walls and very rarely make collisions with the neutral gas atoms. For typical laser operation the electron plasma temperature is about 50,000 K. The potential distribution established in the plasma confining structure corresponds to a uniform axial gradient and a transverse distribution as shown schematically in Fig. 3. The axial field is very weak compared to the average transverse field so that ions formed in the plasma are accelerated towards the wall. Typically there is a potential difference of about 5 volts between the axis and the periphery of the plasma column. There exists an approximately 20-volt potential drop in a thin space-charge sheath separating the plasma from the wall. Ions formed at the axis thus have an impact energy at the wall of about 25 volts. As a consequence of the potential drop within the plasma there exists a large radial velocity spread for the ions. This velocity spread increases in magnitude towards the periphery of the plasma. Because of the Doppler shift this large radial velocity spread minimizes the self-absorption of the resonance radiation, which is so important for efficient laser operation. Since the axial ion velocity is not affected by the transverse field, the linewidth of the laser radiation (viewed along the laser axis) remains small, corresponding to the thermal velocity of the ions. Thus the ion gas has properties equivalent to a high "radial temperature" but a low "axial temperature."

**Laser Tube Construction Problems**

As discussed above, the high density, low pressure plasma offers several advantages as a laser medium. However, the intense ion bombardment creates severe problems in tube construction. The ion energies are near threshold for sputtering of many common tube construction materials. Two methods of construction of the plasma confining structure have been tested.

One type of construction uses a long, unbroken water-cooled insulator tube made of quartz or a ceramic material as shown schematically in Fig. 2. This type of construction suffers from several drawbacks. The intense ion bombardment of the wall causes sputtering decomposition. As a consequence, cathode poisoning gases accumulate in the tube and residues are left on the tube walls. These residues may lead to formation of "hot-spots" on the wall. Secondly, the gas-pumping effects of the plasma cause a pressure gradient in these long tubes, preventing the operation of the whole length of discharge tube at optimum pressure. Thirdly, the poor heat conductivity of most insulators causes severe limitations in power density, thus limiting the attainable efficiencies. From several points of view a more satisfactory type of construction uses a series of short bored metal discs lining the inside of a large diameter quartz tubing shown in Fig. 4. Since a voltage gradient exists along the plasma column these discs must be electrically isolated from each other. The wall potential follows the uniform axial potential in a stepwise fashion. This type of construction eliminates many of the drawbacks of the insulator tube construction, such as the freecing of the cathode poisoning gases, pressure nonuniformity (separate gas return is provided for each section), and the poor heat transport properties. Using metal discs, however, one is still faced with the sputtering problem which results in gas clean-up and electrode erosion.

A recent development at RCA Laboratories has greatly alleviated some of these problems. In a joint program by J. R. Fendley, Jr. and the author, it has been found that high purity graphite has outstanding properties as a construction material for the plasma confining structure. In a comparison test, tantalum and molybdenum were seriously damaged by sputtering but graphite was unaffected. In a successful 1,000-hour
life test only slight sputtering damage was observed for a graphite structure.

A typical graphite construction of a long-life argon laser is shown schematically in Fig. 4. The cathode is a barium impregnated tungsten matrix cathode. To reduce noise and instabilities a symmetrical construction is chosen and the cathode is placed relatively close to the plasma confining structure. A gradual transition to the main bore size is provided both at the cathode end and at the anode end to minimize sputtering effects. The graphite structure operates at about 1,000°C during use, and the dissipated heat radiates through the large diameter quartz tubing.

Two types of argon reservoirs are employed as shown in Fig. 4. One is a ballast tank communicating with the main part of the tube. It serves to smooth out the pressure variations during start-up periods and also to extend the time between refilling the tube. A manually or electrically operated leak valve is used to replenish argon lost due to the clean-up effect. An automatic refill system is contemplated to assure constant pressure in the discharge tube.

Using these construction techniques it is possible to manufacture reliable argon lasers having life expectancy of a thousand hours or more. Several such laser tubes constructed at RCA Laboratories range in power output from 50 mw (Fig. 5) to 1.5 watts (Fig. 6). The heat can radiate directly into the room or it can be captured on water-cooled plates (Fig. 6). An axial magnetic field needed for optimum output can be obtained using permanent magnets as shown in Fig. 6.

**PERFORMANCE CHARACTERISTICS OF ION LASERS**

Noble-gas ion lasers yield continuous duty oscillations at wave-lengths throughout most of the visible spectrum as shown in Fig. 7. The most efficient is the 4,880-angstrom line of argon. Generally, oscillation at the krypton and xenon lines is less efficient than that of the principal argon lines. Neon lines have been made to oscillate in the ultraviolet region. Of the different oscillating lines for a particular gas several may oscillate simultaneously. Wave-length selection can be made by means of a prism in the cavity.

In general, the output power of a particular line increases approximately as the square of the current. Output powers as high as several tens of watts have been reported. Ultimate limits appear not to have been reached yet.

Efficiency is the most unsatisfactory performance parameter of noble gas ion lasers. Typically for power outputs of the order of one watt, the efficiency is less than a tenth of a percent. The useful laser oscillation is a volume effect and the losses (mostly power transported to the plasma confining structure by the particles) are surface effects. Therefore, for a given discharge current density the efficiency tends to increase as the volume to surface ratio of the plasma region increases. That is to say, the larger the device the higher is the efficiency. Presently attainable efficiency limits are not of fundamental nature, but are inherent in the particular discharge configuration used. Considerable future improvements in efficiency should therefore not be surprising.

**APPLICATIONS OF ARGON LASERS**

Due to its present low efficiency the noble gas ion laser is not a serious competitor in applications where heating effects of the radiation is of primary concern. However, where high density continuous duty quantum delivery in the energy range 2 to 4 eV is desired, the ion laser is unique among presently available lasers.

Generally, quantum detectors have higher sensitivity in the visible wave-length range than in the infrared region where more efficient lasers are available. This is the reason why argon cw lasers are seriously considered for ranging and space communications. In applications where direct visual read-out is required, the noble-gas ion lasers are capable of almost complete color coverage. A large-screen laser display built for the Air Force by Texas Instruments was demonstrated at a recent IEEE Convention. This system used electromechanical scanning and electro-optic modulator to display a picture.

Several applications using an argon laser to produce photochemical effects are presently being studied. Examples of these are hologram exposure and read-out, photo-resist exposure, photo-bleaching, and polymerization.

**BIBLIOGRAPHY**


Fig. 7—Typical noble-gas ion laser wave-lengths shown in their relation to human eye color perception.
Nd:Cr:YAG

HIGH-EFFICIENCY HIGH-POWER
SOLID-STATE LASER SYSTEM

Following the initial success of Kiss and Duncan of the RCA Laboratories in demonstrating that the Nd$^{3+}$:YAG laser could be improved by incorporating Cr$^{3+}$ as an energy transfer agent,¹,² a systematic study of the parameters and characteristics of this system was undertaken. This led to an optically pumped laser system with an average output of 10 watts at 10,640 angstroms. This paper discusses the theoretical limits imposed on any optically pumped laser system, outlines the experimental approach taken to optimize the Nd:Cr:YAG system and presents the operating characteristics of a Nd:Cr:YAG system representing the current state of the art.

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All optically pumped laser systems have an inherent energy loss, since the pump photons must be of higher energy than the emitted radiation. This loss can in principle be minimized by using a monochromatic optical pump at an energy only marginally greater than the laser. Such monochromatic pumps are at present relatively inefficient, of limited intensity and available at only a few wavelengths. The usual situation is a broad band emitter and a laser material having an absorption spectrum that can utilize only a fraction of the energy emitted by the pump.

### THEORY

A first estimate of the overall efficiency limits set by using conventional broadband optical pumps is shown in Fig. 1. This plots the fraction of the electric energy input that is emitted at wavelengths shorter than any given wavelength. For long wavelength laser systems, a tungsten lamp is the most efficient pump lamp for systems with absorption over the visible region.

Fig. 1—First estimate of overall efficiency limits set by using conventional broadband optical pumps.

The high pressure mercury lamp is theoretically the most efficient pump lamp for systems with absorption over the visible region.

There are, of course, other losses in the laser operation. In order to achieve the limiting efficiencies of Fig. 1 it is necessary that 1) all of the pump energy is imaged on the crystal; 2) all of this energy is absorbed and passes through...
the upper metastable laser level; 3) operation is sufficiently above threshold that stimulated emission predominates over spontaneous emission and 4) the output coupling is large enough so that internal scattering and absorption losses are negligible.

Items 1), 3), and 4) can be approached experimentally, since linear ellipses or other optical systems for coupling the lamp and crystal image more than 50% of the lamp output on the crystal depending on the relative dimensions of the lamp and crystal and the complexity and size that one is willing to design into them. Fluorescent efficiencies approaching 100% have been measured and thresholds in the infrared are low enough so that operation at levels as high as ten times threshold are easily obtainable with output coupling losses much larger than all internal losses.

The most serious limitation on the laser efficiency is in 2), the absorption of the broadband pump emission by the crystal. Fig. 2 shows the absorption of Nd:YAG alone while Fig. 3 shows the additional bands that the Cr³⁺ introduces.

The additional pumping that this Cr³⁺ introduces depends upon the Cr³⁺ concentration as well as crystal size and pump lamp. In order to give an estimate of the improvement for various pump lamps, Table I combines the efficiencies of the various steps with the maximum theoretical emission from various optical pumps to give theoretical laser power and efficiency for Nd:Cr:YAG lasers and various lamps. The entries in Table I are explained as follows:

**Line 1**—The efficiency of conversion of electrical-to-optical output at wavelengths shorter than the laser output.

**Line 2**—The efficiency of conversion of electrical input to optical output in the Nd³⁺ YAG absorption bands assuming side pumping of a typical 3-mm rod of 1.5% Nd³⁺ doping.

**Line 3**—The efficiency of conversion of electrical input to optical output in the

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**Fig. 3—Additional bands introduced by Cr³⁺.**

**Fig. 4—Number of excited ions versus time.**

Dr. ROBERT J. PRESSLEY received his B.S. in 1954 from Michigan State University, majoring in physics. He joined RCA Laboratories in 1954 as a member of the research training program. Following this he engaged in research on infrared sensitive photoconductive surfaces for imaging systems. Upon receipt of a David Sarnoff Fellowship in 1956, he took a leave of absence and entered Princeton University Graduate School. He received his MA in 1958 and his PhD in 1962, both in physics. During this time he also returned to RCA on projects involving ammonia gas masers, communications systems studies, and optical beating experiments in sodium vapor. His thesis research was an investigation of the interaction of electron spins and nuclear magnetic moments in very pure lithium metal, an experimental investigation using simultaneous-ESR and NMR monitoring of the same sample in thousand-gauss fields. During the 1961-62 academic year, Dr. Pressley served as an instructor at Princeton University setting up laboratory courses in optics and electromagnetic theory. He returned to RCA Laboratories in 1962 and has been associated with the Quantum Electronics Group. He has worked in optical masers with the emphasis upon laser operation and characteristics, in particular, the optimization of the CaF₂:Y and the Nd³⁺:YAG systems. He has also been active in preparing and testing of new materials particularly in the organic laser field investigating various rare earth chelates. This work has resulted in several new organic laser systems. He is a member of the American Physical Society, and the Society of Sigma Xi.
The overall ideal efficiency for a non-linear ellipse with a 5-cm source and 5-cm side-pumped Nd:YAG crystal is obtained by multiplying lines (2)×(4)×(5).

Line 4—Typical imaging efficiency of a linear ellipse is obtained by multiplying lines (3)×(4)×(6).

Line 10—One factor of importance for total output is the total power that can be emitted for a lamp of the same dimensions as the laser rod (2 mm x 5 cm). The value for sodium lamps is uncertain as they are not yet well developed. It could be a good bit higher.

ENERGY TRANSFER

One requirement that is important in this double-doped system is that the transfer time from the excited Cr³⁺ to Nd³⁺ be short compared with the Cr³⁺ fluorescent decay time. This transfer time is found to decrease with an increase in either the Nd³⁺ or Cr³⁺ concentration at a rate characteristic of a dipole-dipole interaction between both the Nd³⁺ → Cr³⁺ neighbors and the Cr³⁺ → Nd³⁺ neighbors. This transfer time can be measured by observing the buildup and decay of the Nd³⁺ fluorescence when the excitation is only in the Cr³⁺ absorption bands.

**TABLE I—Overall Laser Efficiency**

<table>
<thead>
<tr>
<th>LINE</th>
<th>TUNGSTEN</th>
<th>DC XENON</th>
<th>MERCURY HIGH PRESSURE</th>
<th>SODIUM HIGH PRESSURE</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>Total optical output efficiency</td>
<td>Optical Watts × electrical Watts</td>
<td>300°F blackbody</td>
<td>20%</td>
</tr>
<tr>
<td>2</td>
<td>Optical efficiency into Nd:YAG bands</td>
<td>3.5%</td>
<td>5.0%</td>
<td>&lt;1%</td>
</tr>
<tr>
<td>3</td>
<td>Optical efficiency into Cr:YAG bands</td>
<td>5.0%</td>
<td>8.0%</td>
<td>50%</td>
</tr>
<tr>
<td>4</td>
<td>Imaging efficiency of linear ellipse</td>
<td>50%</td>
<td>50%</td>
<td>50%</td>
</tr>
<tr>
<td>5</td>
<td>Nd:YAG absorption to Nd:YAG emission efficiency</td>
<td>50%</td>
<td>50%</td>
<td>50%</td>
</tr>
<tr>
<td>6</td>
<td>Cr:YAG absorption to Nd:YAG emission efficiency</td>
<td>50%</td>
<td>50%</td>
<td>50%</td>
</tr>
<tr>
<td>7</td>
<td>Overall ideal Nd:YAG efficiency</td>
<td>2x4x5</td>
<td>2x4x5</td>
<td>2x4x5</td>
</tr>
<tr>
<td>8</td>
<td>Overall ideal Cr:YAG efficiency</td>
<td>2x4x5</td>
<td>2x4x5</td>
<td>2x4x5</td>
</tr>
<tr>
<td>9</td>
<td>7 + 8—overlap</td>
<td>2x4x5</td>
<td>2x4x5</td>
<td>2x4x5</td>
</tr>
<tr>
<td>10</td>
<td>Maximum total emission of 2 mm diam x 5 cm long source</td>
<td>600 W</td>
<td>1000 W</td>
<td>3000 W</td>
</tr>
<tr>
<td>11</td>
<td>Maximum laser output using above source</td>
<td>20 W</td>
<td>30 W</td>
<td>15 W</td>
</tr>
</tbody>
</table>
Typical experimental data for this type of measurement is shown in Fig. 4 where both the Cr" and Nd" fluorescent time dependences are shown. The transfer efficiency in this crystal is 93% indicating that this concentration of Cr" meets the requirements of an absorber that transfers energy well to the active Nd" ion. The discrepancy between experiment and theory in the first 200 ps is due to some direct excitation of the Nd" ions by the pump lamp.

POWER

The experimental arrangement is shown in Fig. 5. It uses a right cylindrical ellipse for coupling the Hg pump lamp to the laser crystal. Using this equipment and water for cooling we were consistently able to obtain powers greater than 1 watt and efficiencies of a few tenths of a percent. The best results were obtained with a laser rod doped with 1.5% Nd" and 0.5% Cr". This is also the largest high quality Nd:Cr:YAG rod that we have obtained. It is 2.00 inches long by 0.187 inch in diameter and is polished with flat ends. Fig. 6 shows the power output vs. pump power for this rod for both 3% and 8% output couplings with a 4-kW Hg pump lamp and at 3% output coupling with a 3-kW lamp. A maximum power of 10 W was obtained with a 4-kW lamp operated at 3 kW. At this level the differential efficiency was 1%. However, since the lamp output spectrum is changing as the electrical input to the lamp is increased some of this may be due to an increasingly good match between the mercury output and the Cr" absorption. This is probably what gives rise to the superlinearity in the output. The overall efficiency at 10-W output was 0.33%. Higher powers and efficiencies could be obtained if the Hg lamps could be operated at their nominal ratings for any length of time.

Again, the shorter 3-kW lamp gave a higher overall efficiency of 0.36%. The laser was operated at the 7.5 W level with less than 2.1 kW into this lamp. In all of these runs 85% of the power output was in the forward beam and 15% out the back due to the reflectivity on the back surface being too low.

Since this rod had only 0.5% Cr" it did not fully absorb the Hg pump light and also did not transfer it to the Nd" with full efficiency. Considerable improvement toward the 5% efficiency predicted in Table I should be possible with smaller-diameter more heavily doped rods.

TIME DEPENDENCE

The time dependence of the laser output may be of two forms for Nd:Cr:YAG rods. Either there is a ripple superimposed upon a continuous output or else there is a train of regular spikes. The particular mode depends upon the radius of curvature of the ends, the diameter of the crystal, and the doping.

This ripple has a characteristic frequency of from 50 to 100 kHz depending upon how much above threshold the laser is operating. If the same laser crystal is operated with flat reflectors and a higher output coupling its output consists of a series of regular spikes with a repetition rate at this same ripple frequency. Fig. 7 shows the repetitive trace of this spiking for a crystal operating at 10-W average power. The time scale is 10 ps per division and goes from right to left. The smearout of the top of the spikes is due to incomplete filtering in the power supply leaving residual 60-Hz ripple on the lamp. The width of the spikes at half amplitude is 0.6 ps and the time between spikes is 10 ps; this gives a ratio of peak to average power of 16. The output is then a train of 160-W spikes of 0.6-μs half-width at a 100-kHz rate.

This laser system can also be operated at elevated temperatures, with only a 50% reduction in power with a coolant at 80°C. This could be important if the system is to be radiatively cooled.

SUMMARY

Incorporation of the Cr" makes possible a more efficient, higher gain, higher power laser system. The advantages of higher efficiency and power are obvious, but the higher gain also makes the use of this system for frequency doubling much easier. In order to obtain frequency doubling a nonlinear optical material, such as lithium niobate, is placed in the optical cavity and a fraction of the 10,641.6-angstrom radiation is converted to 5,320.8 angstroms. The frequency doubling is proportional to the square of the intensity of the optical field in the doubler. The higher gain of the Nd:Cr:YAG system enables us to achieve high field intensities even with the added losses due to the doubler crystal inserted in the optical cavity. Preliminary experiments have produced 1 mW of continuous output at 5,320.8 angstroms, with several orders of magnitude improvement expected with the system optimized. A further increase in the 5,320.8-angstrom output can also be achieved if the laser is made to operate in a repetitive spiking rather than a continuously operating mode.

The repetitive pulse nature of the higher power output at this 100 kHz rate also suggests the possible use of this laser in some form of ranging or 3-D radar system.

This system is still a factor of 5 times less efficient than our theoretical estimates in Table I. The majority of that is due to the Cr" concentration in our crystal being too low. Not all of the pump light is absorbed and not all of the energy is transferred. If Nd:Cr:YAG with higher Cr" concentration could be obtained with sufficiently good optical quality, a factor of 2 to 4 improvement should be immediately available.

ACKNOWLEDGMENTS

This research was conducted in collaboration with P. V. Goedertier. The energy transfer was calculated by W. Zernick. The mechanical design work and assistance of C. J. Kaiser were also important factors in achieving these results.

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SUPERSENSITIVE LASER LIGHT DETECTOR

Recently the RCA Laboratories have demonstrated a significant increase in the sensitivity of broadband infrared detectors which offers the promise of wide-band receivers with signal-to-noise approaching the theoretical limit set by noise-in-signal. Although the work has been concerned with receivers for point-to-point broadband communications, the units also work extremely well as narrowband point detectors which can be modified for problems requiring a low-frequency detector with larger active area.

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IN THIS work on optical receivers, actually what is under consideration is the performance of the front end of an optical receiver (Fig. 1) of which the optical transducer itself is a small but key part. The latter is a speck of photoconductor cemented between the poles pieces of a re-entrant reflection cavity. The voltage is supplied by exciting the cavity (X band in these studies) with a klystron coupled through a circulator. When the amplitude-modulated signal is focused on the photoconductor and the photocurrent follows the optical modulation; this modulates the cavity Q, which transfers the AM input signal to sidebands of the microwave power reflected from the cavity. There follows an RF amplifier and second detector, whose output is a video signal which reproduces the envelope of the optical input.

The work has concentrated on cavity design and fabrication, mounting of the photoconductive samples and performance studies. Standard microwave plumbing, klystrons, amplifiers, and second detectors have been used so as to evaluate the improvement in optical receivers that can be achieved with commercially available microwave components. The studies consisted of terminal measurements of video output and signal-to-noise. The overall sensitivity and frequency response of the receiver was deduced, as well as the performance of the optical transducer.

The bulk of this paper concerns original work not yet published. For RCA groups, additional data can be found in company-private reports by the same authors available in RCA Libraries, to which the RCA reader is referred for greater detail and for a pertinent bibliography on optical detection with microwave cavities. (Standard works on photoconductivity are listed in the bibliography at the end of this paper.) The transmission of the TV picture is described in another RCA company-private report by J. Bordogna, W. Hannan, T. Penn, C. Reno, and R. Tarzaiski of Applied Research, Camden.

PHOTOCURRENT GAIN

A necessary condition for a photoconductor to have high sensitivity is a large ratio of current output to light input, i.e., a high photoconductive gain G:

\[ G = \frac{I}{aF} \]

where \( I \) is the signal current output of the photoconductor and \( F \) is the optical signal flux in photons/sec (Fig. 1); \( a \) is the quantum efficiency of the detector, and \( q \) the fundamental charge. Current gain reduces the noise of the following amplifier, the principal noise source in many important applications.

Conventionally, high-gain photoconductivity is associated with materials in which only one carrier is mobile. In homogeneous materials, single-carrier photoconduction occurs if one carrier of the photo-produced pair is very quickly localized in a deep center while the other remains free to conduct, as in insulating lattices by proper doping. An equivalent result is achieved by constructing inhomogeneous regions to localize the pair, as in the phototransistor. None of these single-carrier photoconductors has given

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a wideband infrared detector as sensitive as junction diodes.

A recent theoretical analysis has shown that a two-carrier photoconductor, with an RF bias instead of the dc bias that is normally applied to photoconductors, can have very high current gain, frequency response, and sensitivity. The rapid reversal of the electric field localizes the induced photo pairs in the sample as effectively as does a deep trapping center or internal barrier. This permits the use of the high purity transistor materials, which have both excellent high-frequency properties and band gaps narrow enough to respond to infrared radiation. With dc bias the high-frequency response of these materials has not been good because their long minority carrier lifetimes limit the gain-bandwidth product.

The photocurrent gain and the gain-bandwidth product of the photoconductor in the RF cavity can be expressed in terms of measurable parameters of the cavity and semiconductor.

\[
G = \left[\frac{v_1\tau_d}{(1 + \omega^2\tau_d^2)^{1/2}}\right] + \left[\frac{v_2\tau_a}{(1 + \omega^2\tau_a^2)^{1/2}}\right] \cdot \frac{E}{W^{1/2}} \cdot \left[\frac{1}{2\pi R\Delta f}\right]^{1/2}
\]

\[
G \cdot B = \frac{v}{2\pi W^{1/2}} \cdot \left[\frac{1}{2\pi R\Delta f}\right]^{1/2}
\]

Symbols:
- \(G\): gain
- \(v\): drift velocities of carriers 1 and 2
- \(\tau_d, \tau_a\): their photoconductive lifetimes.
- \(C\): electric field at the position of the photoconductor, \(W\): stored energy, \(\Delta f\): bandwidth (in Hz).
- \(A\): amplifier; \(R\): input impedance.
- \(B\): video bandwidth of demodulator in Hz (assumed less than \(\Delta f\)).

The ratio \(E/W^{1/2}\) is a figure of merit of the cavity, a geometrical parameter describing the interaction of the photoelectrons with the stored energy which is similar to the figure of merit of a klystron.

The desired bandwidth \(B\), a design parameter dictated by the communication problem, determines the characteristics of the following amplifiers. It also prescribes the preferred \(\Delta f\) of the cavity, which should be about \(3B\). In practice, however, the klystron frequency largely determines \(\Delta f\), since with conventional design and matching techniques the loaded \(Q\) of the cavity can range only between about 50 and 300.

**ALIGNMENT OF RECEIVER**

Although SNR is the preferred measure of receiver sensitivity, there is a sufficiently close correspondence between the maximum of SNR and of photocurrent gain to permit the gain to be used as a check of operational performance. This greatly simplifies the problem of adjusting the front end of the receiver, so that in spite of the extra complexity that one associates with microwave circuits, the receiver alignment is routine. In fact, the only precise step is pointing the optics at the target, a problem not properly associated with the receiver alignment but with operation. (The difficulty of pointing is intensified by the very small angular coverage of high-performance communication receivers, which require high angular resolution to reduce background interference.)

The alignment steps are listed to give some idea of what is involved in a detector with microwave bias. The only monitor needed is the output signal, which indicates the current gain. With a packaged system, these are factory adjustments.

1. Tune klystron to cavity resonance and lock on with AFC.
2. Match cavity to waveguide with adjustable coupling (zero reflected power as indicated by second detector bias).
3. Overcouple cavity to give sufficient reflected power to bias second detector into linear region (about 25 mV dc bias for IN23B crystal). Steps 2) and 3) are simultaneous.
4. Focus infrared onto photoconductor. This requires an appropriate source of chopped light.
5. Adjust microwave power for maximum

---

**Fig. 1** — Photoconductive demodulator, front end of optical receiver.

**Fig. 2** — Response of germanium photoconductor, gain vs modulation frequency.
At room temperature, the lifetime of this germanium sample was 50 ns, producing the break at 3 MHz. The low-frequency gain was almost 1,000, and the gain-bandwidth product nearly 10^9 Hz. It is a good broadband optical transducer over the range where G·B is constant, which means modulation frequency from 1 MHz up to the cavity cutoff (to 20 MHz.) Immersed in liquid air, the only important change is the great increase in photoconductive lifetime to a couple of milliseconds, which enhances the low-frequency response. Now it is an exceedingly high performance detector for modulation bandwidths anywhere from 100 Hz to 20 MHz. (Proper surface treatment of the germanium should give the long lifetime at room temperature.)

On this graph we have indicated $G_r$, the gain at each bandwidth needed to reduce the amplifier noise until it is less than the noise-in-signal at unity SNR. The gain $G_r$ can be thought of as the minimum condition that the amplifier not degrade the information in any useful signal. The comparison is somewhat arbitrary, but representative of a class of problems in broad-band communications, with amplifier input impedance of 50 ohms and noise figure 3 DB, for which an acceptable signal requires $SNR$ of only a few dB. If no other source of noise were present, the germanium in liquid air would be ideal for bandwidths from 1 Hz to 10 KHz, since here the measured gain exceeds $G_r$; actually, $1/f$ noise in the system precluded the goal of being signal/noise limited at low level. It seems technically feasible to reach this limit with further refinements. Actually this would then count single events, giving a high efficiency photon counter.

Studies with photoconductors of Si, InAs, and InSb give comparable results, covering the range of wavelengths from the visible to beyond 5 micrometers. Extension to the important region of 10 micrometers has not yet been done, but is easily possible. The quality at the longer wavelengths will depend to a large extent on the optical absorption coefficient of available materials.

**COMPARISON WITH AVAILABLE HIGH-QUALITY FAST DETECTORS**

The easiest demonstration of the improvement offered by the receiver using a microwave cavity is a direct comparison with more familiar infrared detectors. Of these, the most sensitive for the 8,400 angstrom light from a gallium arsenide laser is the 7102 photomultiplier. Its serious disadvantages are a quantum efficiency of only 1/5% and high dark current. The latter can be greatly reduced by cooling in dry ice.

We have several comparisons with the 7102. Fig. 3 upper trace shows a scope trace of a pulse from an InSb photoconductive detector, which has good high speed response and is sensitive to wavelengths to 5.5 micrometers. The pulse of risetime 20 ns contains $10^6$ photons, a high enough intensity so that no noise is apparent with the photoconductor. The lower trace is the 7102, showing considerable noise-in-signal at this light level. Clearly in this case the photoconductive receiver is outperforming the photomulti-

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**Fig. 3**—Comparison of response of germanium photoconductor and 7102 photomultiplier. Pulse rise-time = 20 ns; $10^5$ photons/pulse; 8,400-angstrom light.

**Fig. 4**—Comparison of response of germanium photoconductor and silicon photoconductor at low signal level. Pulse risetime = 100 ns; $10^6$ photons/pulse; 8,400-angstrom light.

**Fig. 5**—Comparison of germanium photoconductor and silicon photodiode. Pulse risetime = 200 ns; $10^5$ photons/pulse; 8,400-angstrom light.
plier, its good quantum efficiency overcoming the advantage of the very high noise-free charge multiplication in the 7102. As for any InSb detector, the device was cooled, to liquid air temperature in this photo.

The relative performance of the photomultiplier increases as the light is reduced because its dependence of SNR on light is of lower order than for these solid state detectors. Hence the most stringent test of the photoconductor is near the limt of minimum detectable signal. Fig. 4 is such a case; both the photoconductor and the 7102 are cooled to give optimum performance. The middle trace is the response of a germanium crystal to a pulse of 1/2 μs duration containing about 10⁷ photons. The trace shows considerable noise, but has a clearly defined signal whose amplitude can be determined with fair accuracy. Compare this with the lower trace, the cooled photomultiplier with the same input signal; only the presence of a signal is determined, the shot noise being so large that the signal amplitude cannot be estimated (SNR < 1). Quality equivalent to the photoconductor requires 50 times as much light (upper trace).

Fig. 5 shows a cooled germanium photoco nductive detector and a quality silicon photodiode, Philco L-4501. The diode response is optimized by using a high impedance amplifier so that the effective input impedance is set by the shunt capacitance of the 6 inches of coaxial cable between diode and amplifier. The microsecond pulse here has much higher intensity, for the germanium (top trace) shows no noise. The signal from the Si diode is hardly discernable.

Closer to the interest of RCA is the final example, a TV picture transmitted as a single sideband FM modulation on a 5-MHz subcarrier impressed on the beam of a 1.15-micrometer laser (Fig. 6). The competition is a detector custom-made from the best available components (a Philco L-4530 InAs photodiode mounted in the front end of a low noise preamplifier with 3-dB noise figure and 1,000-ohm input impedance). The photo on the right shows the test pattern received by the diode with 10⁻⁷ watts of signal. The germanium photconductor operated at room temperature gives an equivalent signal output with about 2% of the input - left picture. Cooled to 145°K, it would have required 1/10 of this light.

OTHER APPROACHES TO IMPROVED DEMODULATORS
Clearly the photoconductive detector with microwave bias has shown a great improvement in sensitivity of infrared receivers. In its present form it is well suited to wavelengths out to 5 micrometers and to problems in which the incoming signal can be focused on the small area detector. It seems reasonable that design modifications can significantly increase the area of the detector area with no worse effect than the usual trade-off between area and sensitivity (minimum detectable signal varying as the reciprocal square of the area) and to the 10-micrometer region.

One can expect other approaches to give improved detectors. These results with RF bias should precipitate a flurry of work to increase the response of photodetectors with DC bias, which have the inherent advantage of their circuit simplicity. However, a number of factors tend to compensate for the extra cost of the microwave bias. The microwave circuit permits capacitance coupling to the photoconductor, which greatly simplifies the fabrication and mounting and eliminates a troublesome source of low-frequency noise. Also standard high-purity materials can be used, the high concentrations of deep levels which is required with dc bias not being necessary. The presence of these impurities can be expected to enhance the free-carrier trapping, which degrades the high-frequency response. Also there are suggestions that DC bias cannot have as large a gain-bandwidth product, although this theoretical question is not fully resolved. Finally, the pace of development of solid state X-band components promises to reduce the complexity of microwave equipment to the point where the decision between RF and DC bias will be determined by performance.

Another coming detector is the avalanche diode. This photodiode is operated at such a high field that the photocarriers are multiplied by free-carrier generation as they traverse the junction. It promises very fast response, but the difficulty of controlling the multiplication limits it to modest microwave gain. As yet, no high performance has been reported for input light longer than 1.5 micrometers. It seems most suitable for very broad bandwidths or extreme modulation frequency in the gigahertz region.

CONCLUSION
The photoconductive detector with microwave bias has given the first low-level infrared receiver offering the promise of a sensitivity approaching the ideal limit set by noise-in-signal. Receivers already demonstrated are point detectors with very high sensitivity for light from the visible to 5 micrometers, and for information bandwidths up to 100 MHz. Future developments should bring their sensitivity close to the ideal limit; extend the spectrum to the 10-micrometer region, and the frequency response to the RF; and increase the detector area. While it is possible that other classes of devices with simpler circuits will be developed to match this performance, the burden of proof is now definitely on them.

BIBLIOGRAPHY
UNDERWATER LASER TRANSMISSION CHARACTERISTICS

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Characteristics of the transmission of visual radiation in water are discussed and underwater transmission data applying to extended ranges are presented. Measurements have been made with an intense, narrow-beam, coherent radiation source which has a spectral peak at 5.300 angstroms and a bandwidth of 24 angstroms.

A great deal of experimental and theoretical work conducted during the past few decades has contributed significantly to our knowledge of the transmission properties of optical radiation in oceanic and limnetic waters. Measurements have been made with increasingly greater sophistication, and theoretical developments have been increasingly more extensive. Despite important advances and significant contributions, however, our understanding in this area is still severely limited. This becomes particularly evident in the design of underwater optical equipment when one attempts to evaluate the performance of a system. In many such applications, it is only possible to make rough estimates.

The development of high-power, pulsed laser devices operating in the green part of the spectrum where water transmission is maximal, enhances the feasibility of underwater optical systems which heretofore were not practical. This development has, therefore, heightened the interest in such systems and has emphasized the immediate practical need for an improved understanding of transmission of visual radiation in water.

The exposition which follows is essentially divided into two parts. The first part consists of a discussion of the transmission characteristics of visual radiation in water; the second part consists of a description and analysis of a transmission experiment with a high-power, narrow-beam, coherent source.

TRANSMISSION OF VISUAL RADIATION IN WATER

Attenuation Coefficient \( \alpha \)

Two attenuation coefficients which characterize the transmission medium will be referred to in the discussion which follows. These coefficients are the same as those generally found in the literature on transmission. For clarification, however, the one denoted by \( \alpha \) will be defined under this heading. The second coefficient, denoted by \( k \), will be defined under the next heading.

Let us examine the attenuation in a specific example which is pertinent to the experiment to be described later. Consider a collimated beam with narrow cross section passing through an attenuating medium, and consider the measurement of this radiation with a detector which has an aperture of sufficient size to permit reception of the entire beam. The attenuation determined by measurements made with the detector over short distances can be expressed in terms of a simple exponential function known as Lambert's law of absorption or Beer's law. That is, if \( I \) is the intensity at range \( R \) and \( I_0 \) is the intensity at \( R = 0 \), then:

\[
I = I_0 \exp(-\alpha R) \tag{1}
\]

where \( \alpha \) is a constant characterizing the medium and usually referred to as the attenuation constant or the volume attenuation coefficient. For analytical purposes, the attenuation constant \( \alpha \) can be considered to be the sum of two terms. One term is an indication of the amount of atomic absorption of radiation; the other term is an indication of the amount of radiation scattered out of the beam. Experimentally, however, the components of \( \alpha \) are determined indirectly; measurements of the type described here always yield the composite \( \alpha \). There are many experimental data obtained over short ranges supporting the exponential relationship expressed in


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Eq. 1. As the range over which measurements are made is increased, however, the experimental data will be found to depart significantly from this relationship. The measured intensities will be considerably higher than those predicted by this formula with the use of an \( a \) value determined by measurements over short ranges. The reason for this increase is the presence in the detected radiation of a component which was originally scattered out of the beam and then re-scattered so that it eventually enters the detector aperture. That is, a portion of the radiation which was originally scattered out of the beam and considered lost, is, in fact, returned to the beam by multiple scattering.

In our experiment, the observed intensity is greater than that predicted by the simple exponential relationship expressed in Eq. 1. For the effect to be observable, however, the path traversed by the radiation must be long enough so that a large number of scattering interactions have taken place.

**Monopath and Multipath Irradiance, and Attenuation Coefficient \( k \)**

It is convenient to discuss transmission characteristics of water in terms of irradiance. Irradiance is defined as the radiation power per unit solid angle, dimensions of power per unit solid angle, \( R \) is the range or distance from the source and \( a \) is the attenuation coefficient defined in Eq. 1.

Neglecting diffraction effects, Eq. 3 holds also for a special kind of idealized point source, namely, a point source which only emits radiation within a specified solid angle which is less than \( 4\pi \) steradians. The expression holds only within the region of this solid angle since, by definition, there is no radiation external to it.

A correspondingly accurate relationship for multipath irradiance has not yet evolved. A number of theories have been proposed and developed to various states of completion, but these appear to have been only partially successful in providing an adequate model. The four most prominent theories of transmission have been briefly summarized in Ref. 1. One of these, the diffusion theory, leads to a particularly simple solution. Motivation for its development came from a recognition of the phenomenological similarities between optical transmission and neutron transmission.

Neutron transmission in homogenous materials has been explained successfully by the use of diffusion theory\(^4\), and theorists have suggested that an analogous development in optical transmission would be equally successful. Along with these phenomenological similarities there are differences which make the use of diffusion theory approach questionable. Also, natural hydrosols existing in oceans and lakes are far from uniform. Therefore, any method based on homogenous properties of the medium will be of limited usefulness. Despite these shortcomings, there appears to be sufficient correspondence between the expression derived from the theory and irradiance measurements to warrant its use in estimating underwater transmission.

Inverse range and exponential dependencies are the essential features of the solution obtained for the differential equations of the theory. For a point source, the irradiance is expressed symbolically as:

\[
H_r = \frac{J}{4\pi R} e^{-kR}
\]

where \( k \) is the second coefficient characterizing the transmission medium, \( J \),
as before, is the radiant intensity and $R$ is the range. We shall refer to $k$ as the multipath attenuation coefficient. The complete expression for the total irradiance due to a point source is:

$$H_t = \frac{J \exp(-\alpha R)}{R^2} + \frac{J k \exp(-\alpha R)}{4\pi R}$$

(Duntley$^2$ has conducted a series of measurements in lake water to determine the validity of Eq. 5. In water which has an $\alpha = 0.20 \text{ ft}^{-1}$ and $k = 0.057 \text{ ft}^{-1}$, the agreement is excellent except at the intermediate ranges. This is evident in Fig. 1 which is a plot of the total irradiance data measured by an irradiance photometer; the solid dots are the values computed from Eq. 5. (Fig. 1 has been reproduced here from Ref. 5. An additional scale of attenuation lengths has been added to facilitate comparison with irradiance plots presented later. An attenuation length is defined here in 1/$\alpha$.)

In a report on another series of experiments in lake water, Duntley$^4$ has developed an empirically modified form of the point source equation for sources having beamwidths from 20° to 360°.

Experimental data available for sources which are highly collimated have been reported by Duntley$^1$ and by Knestrick and Curcio$^1$ for measurements made over propagation lengths of less than 8 attenuation lengths. The experiment which will be described in the next section has resulted in data from measurements made over a distance of 30 to 50 attenuation lengths, a region characterized by a predominance of the multipath irradiance component of total irradiance. It will be shown that in this region the irradiance due to a highly collimated beam can be expressed by the formula derived for a point source, Eq. 5, with the addition of a multiplicative constant.

**EXPERIMENTAL PROGRAM**

A measurement program was undertaken in November 1963 at the David Taylor Model Basin in Carderock, Maryland, for the purpose of determining the transmission characteristics of high-power green laser radiation in water. The equipment consisted of a submersible laser transmitter and a submersible receiver. Each unit was held 5 feet below the surface of the water by a support attached to an electrically driven carriage which spanned the channel in which the measurements were made. The range over which the measurements were made could be varied by moving the carriages to any position along the channel. The channel was 20 feet wide and varied in depth from 20 to 10 feet. The water in the channel was filtered Potomac River water.

**Transmitter and Receiver**

The transmitter is a completely self-contained battery-powered, coherent green radiation source, housed in a waterproof container designed to operate at a maximum depth of 1,000 feet. The unit is fitted with electrical connectors and cables to permit remote operation and remote recharging of the batteries. In addition, an RF coaxial transmission line cable, also connected to the unit, permits a remote photoelectric measurement of a signal from a photocell which monitors the green output power. High-power coherent green radiation pulses are obtained by the generation of second harmonic radiation in a potassium dihydrogen phosphate crystal, utilizing techniques described in Ref. 8. Fig. 2 is a schematic diagram of the transmitter. The fundamental radiation is derived from a Q-switched neodymium-glass laser which has an output centered at 10,600 angstroms. The second harmonic radiation is centered at 5,300 angstroms and consists of 80 evenly spaced mode lines, a few of which are shown by the spectrometer tracing in Fig. 3. The overall spectral width is about 24 angstroms.

The output waveform of the second harmonic radiation consists of a pulse of short duration. Fig. 4 shows a typical 200-kW pulse measured with a calibrated vacuum photodiode and a circuit with a response time of 15 ns. The beam, which has a non-circular cross section, has maximum and minimum angular spreads of 3 and 1 milliradians, respectively.

The receiver consists essentially of an RCA-IP39 multiplier phototube (S-4 spectral response) mounted in a submersible housing. The collecting area of the receiver is about 1 cm². Its field of view is determined by the aperture in a Gershman tube mounted external to the housing. The receiver signals were relayed by a properly terminated transmission line to the input of a wideband amplifier, and then they were displayed on an oscilloscope. When used in this manner, the receiver has a signal-to-noise ratio of one when the radiant signal power incident on the photocathode is $5 \times 10^{-5}$ watt and there is no background radiation.

**Measurement of Attenuation Coefficient $\alpha$**

Attenuation coefficient $\alpha$ of the water in the channel was measured in situ with a commercial transmissometer (Marine Advisors, Inc., Model C-2A). The instrument consists essentially of a tungsten light source imaged on a photodetector with a separation between source and detector of one meter. A No. 58 Wratten filter placed over the source aperture results in an output...
Transmission Measurements with the High Power Source

Measurements were made with the transmitter attached to one of the channel carriages which was kept in a fixed position at one end of the channel. Figs 6a and 6b depict two views of the transmitter mounted on the carriage. The receiver (shown in Fig. 7) was attached to another carriage which was moved along the channel with measurements being taken at 50- or 100-foot intervals. The carriages moved on precision tracks so that the transmitter and receiver remained aligned during the experiment.

Fig. 8 is a photograph of the transmitter 5 feet below the surface of the water in the channel at the David Taylor Model Basin. Scattering from the beam is clearly visible at short ranges.

The peak power output of the transmitter for these measurements was 130 kW which yields a radiant intensity of $3.9 \times 10^9$ watts per steradian for an average beam width of 2 milliradians.
The measurements with the laser were made by photographically recording an oscilloscope trace of the received signal, and at a later time reading the signal amplitudes on the film. Measurements were made for two receiver fields of view: 26° and 36 milliradians. These data are plotted in Figs. 9 and 10 as a function of transmission path length (1/α). The end points of the vertical lines on the graph mark the maximum and minimum readings recorded at each indicated range, and the dots represent the average value of all measurements taken in each case. The cause of the scatter in the measurements has not been established. This uncertainty in the data, which appears to become greater as the signal decreases in amplitude, corresponds to an uncertainty in the deduction of a form for the irradiance function. It is reasonable, however, to expect that as long as a and k do not vary, the relationship must be representable by a smooth and regular curve. The most reasonable curves under these circumstances appear to be the ones displayed in Figs. 9 and 10.

On applying the receiver transfer characteristic to those curves, one obtains a value for the combined monopath and multipath irradiance. The monopath irradiance can be computed from Eq. 3 utilizing the value of α measured with the transmissometer. Since (H, H') = H, a, the multipath irradiance can also be obtained.

True irradiance should be measured with a receiver having a field of view of 180° × 180° (2π steradians) for there will be some contribution of multipath radiation which is incident on the receiver at angles out to 90°. Dunty has measured irradiance characteristics of light scattered from narrow beams of small divergence, and the results seem to indicate that the contribution to true irradiance from radiation which enters the detector at angles of incidence greater than 13° is quite small, and for most cases, negligible. On the other hand, a significant portion of the multipath irradiance will be excluded for a receiver field of view of 2°.

This is evident in Fig. 11, which is a plot of the ratio of monopath to multipath irradiance determined from the measurements made with two different fields of view. Here, one can see that at any given distance the ratio for the 2° field of view is approximately two orders of magnitude greater than the ratio for the 26° field of view.

Another observation of interest is that if the multipath irradiance function (H') given in Eq. 4 is multiplied by a constant factor C which is considerably less than one, it can be made to fit the experimentally derived irradiance curve. That this expression must be multiplied by a factor considerably less than one is not surprising if we recall that it was derived for a point source (which emits radiation in all directions). In the experiment, however, the source emits radiation in directions confined only to a small solid angle. It is clear that for this latter source there would be no contribution to the multipath irradiance from primary radiation which, in the case of a true-point source, would be emitted in directions outside the small solid angle. In view of the fit obtained in this manner, it is interesting to examine both the monopath irradiance and the multipath irradiance functions over extended region. This has been done in Fig. 12 for the 26° field of view for which the appropriate multiplicative constant is C = 4.00 × 10^-4.

The total irradiance can be obtained by graphically summing the two curves in Fig. 12. The curves have been normalized for an arbitrary value of J. Additional specific data related to these measurements can be found in Ref. 7. The dashed lines indicate extrapolation; solid lines are based on measurement. Attenuation coefficient k used in these graphs is obtained in the following way. At extended ranges, the total irradiance function H is approximately equal to H, a and eventually the exponential factor exp(-kR) becomes the dominant factor. In this region then:

\[ k = \ln H_{a} - \ln H_{r} \]

where: \( H_{a} \) is the irradiance at a distance \( R_{a} \) and \( H_{r} \) is the irradiance at distance \( R_{r} \).

CONCLUSIONS

We have examined the point source multipath irradiance function obtained from diffusion theory with respect to irradiance produced at extended ranges by intense pulses of laser radiation. The correlation between the measured values and the values predicted by the expression modified simply by a multiplicative constant suggests the correctness of the general functional form. A logical extension of this work would be to test the formula for other values of a and to examine the character of constant C as a function of beamwidth.

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Fig. 11—Ratio of monopath to multipath irradiance versus range.

Fig. 12—Logarithm of irradiance versus range.
APPLICATION OF INJECTION LASERS TO COMMUNICATION AND RADAR SYSTEMS

This paper describes the application of the GaAs room-temperature laser diode to laser communication and radar systems. Since this GaAs diode requires a threshold drive current of only 10 amperes, simple and reliable drive circuits can be used, while elimination of the need for refrigeration reduces power input, and size and weight.

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UNTIL RCA achieved laser operation with a GaAs diode at room temperature, the major deterrent to the use of a laser diode was the need to operate it at low temperature. Laser operation can now be achieved with a GaAs diode at room temperature and at a threshold drive current of only 10 A. The low threshold permits simple, reliable drive circuits to be used, while elimination of refrigeration considerably reduces power input, size, and weight.

CHARACTERISTICS OF THE INJECTION LASER

Figs. 1, 2, 3 and 4 show the performance of the RCA laser diode tested during room temperature operation. Fig. 1 is a photograph of a dual-beam oscilloscope trace showing current input to the laser diode and the light output from it. The light pulse emitted from one end of the laser diode is shown in the lower trace and the diode current input is shown in the upper trace. Note that a peak output power of 10 W is achieved at a peak drive current of 40 A. This represents the performance of a typical diode; however, some diodes emit as much as 18 W with the same drive current.

Fig. 2 is a plot of output power radiated from one end of the diode as a function of drive current. The region around the lower knee of the curve, where the slope suddenly changes, represents the laser threshold of the diode. Typically the threshold current \( I_0 \) is 10 A. For currents above \( I_0 \), the laser output increases steadily until heating effects cause the output to taper off.

Fig. 3 shows the measured spectrum of the light radiated from the diode. The spectrum consists of four longitudinal modes spaced approximately 6 angstroms apart, in agreement with the mode spacing calculated from the length of the Fabry-Perot cavity formed by the diode. At room temperature, the center of the laser emission spectrum occurs at about 9020 angstroms, with a temperature-dependent shift of about 2 angstroms per degree Celsius, as shown in Fig. 4.

Radiation from the laser diode is collected and focused into the desired beamwidth by a small lens. Fig. 5a shows that when the laser is placed in the focal plane of the lens, the radiation pattern is fan-shaped with an aspect ratio of about 10:1. Fig. 5b shows that by defocusing the lens it is possible to obtain a far-field pattern with a 1:1 aspect ratio. Far field power measurements have shown that defocusing, to the extent that a 1:1 aspect ratio is achieved, does not introduce significant side lobes in the beam.

The laser module shown in Fig. 6 was developed for use in communication and radar systems. This module consists of a laser diode and beam collimating lens, mounted in a cylindrical housing with a precision machined tapered seat. The laser diode and its lens are accurately aligned along the axis of the cylinder, focused for a suitable beam pattern, and permanently fixed in position. This module fits into a mating precision-tapered hole in the transmitter housing, allowing for easy replacement of the laser emitter without the need for critical optical realignment procedures.
INJECTION LASER COMMUNICATION SYSTEMS

To date, injection laser communication systems have been developed mainly for military applications where the narrow beamwidth, narrow spectral width and non-visible features of the injection laser are exploited to obtain communication security. When the manufacturing cost of the injection laser is reduced, it is expected that this type communication system will also be used for commercial applications such as localized communications for museums, fairs, etc.

A block diagram of an injection laser communication system is shown in Fig. 7. When driven by short, high-current pulses, the GaAs diode emits coherent light in a fan-shaped beam with an angular divergence of less than 15°. The transmitter lens focuses this radiation into the desired beamwidth and voice signals are transmitted over it by pulse frequency modulation.

The received laser beam is collected by a parabolic reflector and focused on a photodiode. The detected pulses are amplified, limited and sent through a pulse-frequency demodulator to produce the audio output signal.

The basic equations which define the performance of a laser communication system are shown in Table 1. Typical parameter values for a state-of-the-art injection laser communication system and the corresponding transmitter power vs range curves (derived from the above the equations in Table 1) are given in Fig. 8. This data shows, for example, that a 10-W transmitter will provide a 20-dB fading margin at a range of 5 miles, for the given set of parameters.

Fig. 9 shows three different laser transmitters that have been developed by Applied Research. Fig. 9a shows a miniature laser transmitter developed for an intrusion alarm system; Fig. 9b shows a wide beamwidth transmitter (about 15°) developed for a short range, hand-held communication system; and Fig. 9c shows the transmitter developed for NASA's GEMINI 7 experiment.
TABLE I—Basic Equations for Laser Communications System

\[
\frac{S}{N} = \frac{2eB (\rho P_s + \rho P_b + I_d) R_G G^2}{G^2 + 2FkTB}
\]

(1)

\[
P_s = \frac{M \alpha_n^2 T_n T_s R_{opt}}{4}
\]

(2)

\[
T_n = e^{-\alpha R}
\]

(3)

\[
B = \frac{0.4}{\tau}
\]

(4)

\[
q = \tau f = 3\tau B_n
\]

(5)

\[
R_1 = \frac{1}{2\pi BC}
\]

(6)

\[
P_{tr} = \frac{P_o \alpha_i^2 R_i^2}{4 \pi \tau^2 T_s T_n}
\]

(7)

\[
P_{tr} = \text{transmitter power (W)}
\]

\[
\rho = \text{responsivity of photodetector (A/W)}
\]

\[
P_r = \text{received signal power (W)}
\]

\[
P_b = \text{received background power (W)}
\]

\[
R_1 = \text{load resistance (ohms)}
\]

\[
e = \text{charge on an electron (1.6 \times 10^{-19} \text{ C})}
\]

\[
B = \text{bandwidth (Hz)}
\]

\[
F = \text{noise factor of preamplifier}
\]

\[
k = \text{Boltzmann's constant (1.38 \times 10^{-23} \text{ J/}^\circ\text{K})}
\]

\[
T = \text{temperature (}^\circ\text{K)}
\]

\[
I_d = \text{detector dark current (A)}
\]

\[
G = \text{internal gain of photodetector}
\]

\[
M = \text{signal to noise ratio}
\]

\[
\alpha_n = \text{receiver beamwidth (rad)}
\]

\[
A_r = \text{area of receiver optics (m}^2\text{)}
\]

\[
T_r = \text{transmission of atmosphere}
\]

\[
T_s = \text{transmission of optical filter (A)}
\]

\[
\tau = \text{pulse duration (sec)}
\]

\[
C = \text{capacitance shunting detector load}
\]

\[
\alpha_t = \text{transmitter beamwidth (rad)}
\]

\[
\delta = \text{atmospheric attenuation coefficient (m}^{-1}\text{)}
\]

\[
q = \text{duty factor of transmitter}
\]

\[
B_{opt} = \text{passband of optical filter (A)}
\]

\[
\xi = \text{reflection coefficient}
\]

INJECTION LASER RADAR SYSTEMS

The power output capability of an injection laser is relatively low compared to the power available from a crystal laser (e.g., such as a ruby laser). Moreover, the emission wavelength of the injection laser does not fall within a region where sensitive multiplier phototubes are available. As a result, the maximum operating range of an injection laser radar is relatively short compared to that of a crystal laser radar. On the other hand, the injection laser is much smaller and more efficient than crystal lasers and it can be operated at much higher pulse repetition rates. Hence, there are certain applications where an injection laser radar can be used to advantage.

The basic equations which define the performance of a laser radar are the same as those given for the communication system, (see Table I), except for Eq. 7, which indicates required communications transmitter power \(P_{tr}\). If the target is a diffuse reflector that intercepts the entire laser beam, the required transmitter power \(P_{tr}\) is:

\[
P_{tr} = \frac{\pi P_o R^2}{A \tau T_s T_n}
\]

(8)

where \(\xi\) is the target reflectivity.

Typical parameter values for a state-of-the-art injection laser radar and the corresponding radar transmitter power vs range curves (derived from the Equations 1-6 of Table I and 8 above) are given in Fig. 10. This data shows that a multiplier phototube receiver provides greater operating range than a photodiode receiver and, for the given set of parameter values, the maximum range with a 10-W transmitter is about 300 meters.

It is interesting to note that a multiplier phototube provides best performance in radar systems whereas a silicon photodiode provides best performance in most communication systems. This situation occurs because the field of view of communication receivers is usually much wider than the field of view of radar receivers and, therefore, the communication receiver is plagued by a much higher level of background radiation. For this condition it can be shown that the higher responsivity of the photodiode (at 9,000 angstroms) more than offsets the advantage offered by the multiplier phototube's high, essentially noise free internal gain.

The range measurement accuracy of a pulsed radar is

\[
\frac{c}{4B\sqrt{S/N}}
\]

(9)

where \(c\) is the velocity of light (3x10^8 m/s). This equation indicates that range accuracy can be improved by increasing receiver bandwidth. However, with regard to a room temperature operated injection laser radar, a point of diminishing returns is reached at a bandwidth of about 20 MHz. Beyond 20 MHz the rise time of the pulses remains essentially constant, at a value determined by the rise time of the laser drive circuit.

Further improvement of range accuracy can be obtained only by increasing SNR. This can be done by increasing transmitter power, by increasing receiver-sensitivity, or by employing multiple pulse integration. With the latter method, the range accuracy improvement factor is between \(N\) and \(\sqrt{N}\), depending on the type integrator used, where \(N\) is the number of pulses that occur during the integration period. For example, if 100 pulses occur during the measurement period the measurement accuracy could be improved by a factor of 10 or more. Thus it is clear that the high pulse repetition rate capability of the injection laser can be used to advantage in obtaining good range accuracy.

As previously mentioned, the peak output power of a typical injection laser diode is 5 to 10 watts. Larger peak output power can be realized by assembling an array of laser diodes.

Fig. 11 shows peak output power vs array size as a function of transmitter beamwidth, based on state-of-the-art laser diodes which have a peak output power of 10 W and an active width of 0.963 inch. The size of the array increases as the transmitter beamwidth is reduced because the longer focal length lenses (needed to reduce beamwidth) must have larger diameters to collect the 5° x 15° fanshaped radiation from the laser diodes. Fig. 12 shows the optics of a laser array designed to generate a peak output power of 280 watts in an 8 mrad beam.

For short range applications that require extremely good range accuracy, the triangulation range finding tech-
Fig. 9—Injection laser transmitters.

Fig. 10—Transmitter power vs range.

**SYSTEM PARAMETERS**

(Fig. 10)

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>Diode</td>
<td>0.4 in.</td>
</tr>
<tr>
<td>Diode current</td>
<td>0.3 A/W</td>
</tr>
<tr>
<td>Phototube current</td>
<td>$3 \times 10^{-4}$ A/W</td>
</tr>
<tr>
<td>Laser wavelength</td>
<td>6500 angstroms</td>
</tr>
<tr>
<td>FWHM</td>
<td>3 mrad</td>
</tr>
<tr>
<td>Beamwidth</td>
<td>2 mrad</td>
</tr>
<tr>
<td>NAR</td>
<td>10 dB</td>
</tr>
<tr>
<td>SNR</td>
<td>60 dB</td>
</tr>
<tr>
<td>$B_1$</td>
<td>1000 kHz</td>
</tr>
<tr>
<td>$B$</td>
<td>2 MHz</td>
</tr>
<tr>
<td>$r$</td>
<td>75 ns</td>
</tr>
<tr>
<td>$E$</td>
<td>0.1 W/m²/angstrom</td>
</tr>
<tr>
<td>$E_{phototube}$</td>
<td>100 angstroms</td>
</tr>
<tr>
<td>$I_{phototube}$</td>
<td>$1 \times 10^{-10}$ ampere</td>
</tr>
</tbody>
</table>

Fig. 11—Peak output power vs size of laser array.

Fig. 12—Optics for a 28 element laser array.
Technique illustrated in Fig. 13 offers a possible solution. This technique relies on the fact that a radar return is detected only when a target is within the intersection of the transmitter beam and the receiver field of view. Thus, range can be measured to an accuracy on the order of inches simply by geometric triangulation. Achieving comparable range accuracy with conventional radar calls for measuring time delays on the order of a fraction of a nanosecond, a difficult task requiring large, complex equipment.

Referring to the detailed system geometry shown in Fig. 14, one can show that the range resolution of a triangulation radar is given by

\[ \Delta x = \frac{p(2y - A) \left[ a + \left( \frac{R - t_1}{l_1} \right) D \right]}{(2y - A)^2 - \left( \frac{R - t_1}{l_1} \right) D^2} \]

The performance that could be expected from a laser triangulation radar is indicated in Fig. 15. For the given set of system parameters, the maximum range measurement error vs range and the signal-to-noise ratio vs range are plotted in Figs. 15a and 15b, respectively.

The range of a laser radar can be extended considerably by mounting a retroreflector on the target. From the simple geometric relationships indicated in Fig. 16, the relationship between transmitted \( P_{tr} \) and received \( P_r \) power, of a system employing a retroreflector is

\[ P_{tr} = \frac{\pi P_{0 \varphi} a_l^2 R^2}{4 A_{l x} T_2 \varphi_a} \quad R < \frac{D_r}{\varphi_a} \]

\[ P_r = \frac{\pi P_0 \varphi \phi_{rx} R}{16 A_{l x} \varphi_a T_2} \quad \frac{D_r}{\varphi_a} < R \]

where: \( \varphi_a \) = diffraction limited beamwidth of retroreflector (1.22\( \lambda \)/\( d_{rx} \) rad), \( A_{l x} \) = area of retroreflector (m²), and \( D_r \) = diameter of receiver optics (m). Using the same parameter values as those given in Fig. 10, one can show that a 1-inch retroreflector can be tracked out to a range of about 5 miles.

ACKNOWLEDGEMENTS

The equipment described here was developed by D. Karlsons, C. Reno, T. Penn and C. Clubine of the Applied Research Laser group. The laser diodes were developed by the Quantum Electronics group (RCAL) under the direction of Dr. H. Lewis.

BIBLIOGRAPHY

LASER
SPECTROSCOPY

This paper summarizes some main areas of research and technol­ogy based upon spectroscopy using lasers. It discusses how the monochromaticity of the laser allows very great precision in line shape and line position measurements. The high light intensity obtainable from lasers offers the possibility of detecting emission lines previously undetectable, and also gives rise to a large group of new phenomena in the field of nonlinear optics.

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SPECTROSCOPY in the usual sense consists of measurements of transmittance of light through a material. The light used contains a narrow spread of wavelengths, obtained by selecting a fraction of the radiant energy from a hot body by means of a dispersing element such as a prism, grating, or Fabry-Perot interferometer.

For the purpose of this discussion, such a definition is too restricted. For example, it is not uncommon that one is interested in the spectral distribution of a hot emitting body rather than in its transmittance. Other experiments may be designed to measure frequency shifts when light falls on some material as, for example, in the case of Raman spectroscopy.

In what follows we discuss some uses of the laser in these various fields. A somewhat arbitrary division is made between active spectroscopy in which deliberate tuning is used, and passive spectroscopy in which one detects shifts and broadening, experienced by mono­chromatic, untuned, laser light when it is scattered by optical density fluctuations in some material.

ACTIVE SPECTROSCOPY

Laser Monochromaticity

If one wants to use a laser as the light source in spectroscopy, the first thoughts that come to mind are the advantages offered by such a very monochromatic source, and the need to tune the frequency of this source. If such tuning is not readily possible, one needs to change the frequency of the substance whose transmittance is to be measured. The latter can be done with electric or magnetic fields. As to the first point, the advantage of monochromaticity of the laser, some caution should be noted. All three major types of lasers, paramagnetic crystals, gases, and injection lasers usually operate at a number of rather independent wavelengths (so-called modes) simultaneously. These different modes are individually usually very monochromatic. The reason for the mode multiplicity is that the optical resonant structures used are often so large compared to the wavelength of the laser light, that several resonant modes exist within the emission bandwidth of the active laser medium.

Sometimes the absorption lines one wants to measure are broad enough that the multimoding is not objectionable. In other cases mode control will be necessary in order to permit the selection of one single wavelength. From the previous discussion, it follows that mode control is easier with the longer wavelengths, and for that reason medium and far-infrared gaseous or semiconducting lasers operate often in a single mode.

The choices for frequency tuning, particularly over a wide range, are at present still rather restricted. Some details about the tuning techniques available follow.

Large Frequency Changes

Nonlinear effects were historically the first to be used in obtaining large shifts in the frequency of a laser. Particularly useful in this respect is Raman scattering, which is the process whereby a molecule adds to or subtracts from the incident photon of the laser—a photon corresponding to one of the energy jumps allowed for the molecule either to a lower or a higher energy level. The first case is called an anti-Stokes process, the latter a Stokes process. The emission wavelength of these Raman lines, incidentally, offers a way to identify the nature and temperature of the emitting material, and when powerful lasers are used, should allow one to do spectroscopy of the atmosphere using the Raman component in the backscatter of the

![Fig. 1—Tuned laser spectrogram of CH3F. High reflectivity mirrors were used resulting in a 290 MHz laser width. Path length was 15.5 cm; CH3F pressure was 4 mm; upper curve: empty cell; lower curve: cell filled with CH3F.](attachment:image1.png)

![Fig. 2—Tuned laser spectrogram of C2H6 using high reflectivity mirrors. Path length was 7.7 cm; C2H6 pressure was 11 mm; upper curve: empty cell; lower curve: cell filled with C2H6.](attachment:image2.png)
laser. It was discovered that when a Raman active material is placed in the beam of a high-power laser, typically a Q-switched laser with an output of the order of 10 MW/cm², stimulated emission occurred at additional wavelengths, separated from the exciting laser wavelength by Stokes or anti-Stokes frequencies. In particular, the stimulated Stokes radiation can be quite strong. It has been reported that 20% of the 6,943-angstrom radiation from the ruby laser can be converted to the Stokes line at 992 cm⁻¹ to longer wavelength using benzene. By choosing other liquids such as water, nitrobenzene, cyclohexane, etc., or certain solids, (calcite or diamond), a large variety of new wavelengths has been obtained. This choice of wavelengths permits a discontinuous-type laser spectroscopy that has found use so far in a few isolated cases such as, for example, in measurements of the two-quantum photoionization of Cs and Cd.¹ For continuous-frequency laser spectroscopy one would have to use one of the methods of fine tuning on the different Raman lines. A listing of different Raman active liquids used for laser tuning appeared recently. Also, if continuous rather than pulsed output is desired, it appears likely that the threshold for stimulated Raman emission can be reached by using high-power cw argon or CO₂ lasers and placing the sample in the focal point of a near concentric laser mirror configuration with highly reflecting mirrors. In passing, it might be mentioned that particularly in the far infrared region the obtainable resolution has usually been low because of the lack of strong light sources and efficient detectors. The cascade of some significance that it was recently reported that the stimulated Stokes and the laser beam that excited this radiation can be mixed in a nonlinear crystal, here CdS, to give rise to pulses of 0.3 watt at the difference frequency which was in the 10-micrometer region. [Editor's Note: the IEEE standard term micrometer (10⁻⁶ meter) is used throughout to denote "micron."]¹

For active spectroscopy, however, injection lasers are more important because they have the property that the frequency of laser emission can be changed by large amounts if one prepares an alloy. For example, by changing the ratio of InAs to GaAs one can cover the region from 3.11 to 0.84 micrometers. Fine tuning is then possible in a variety of ways such as by changing the temperature of by applying stress or a magnetic field. A spectrometer consisting of a set of alloyed injection lasers to cover the desired frequency range, each tunable over a few cm⁻¹ and generating single modes, seems an attractive possibility, perhaps realizable in the future.

More recently, injection lasers of PbS and PbSe were operated whose frequency could be changed from 7 to 11 micrometers in a continuous fashion. A complication is, apart from the fact that these lasers were pulsed and operated at 77°C, that a few modes oscillated simultaneously.

Finally, another large-range tuning technique, based on parametric down-conversion⁵ appears quite promising for spectroscopic purposes. In this approach the Q-switch pulse from a neodymium laser was first converted to 5,290-angstrom green light by second-harmonic generation. This light was then used to pump a lithium niobate crystal. The nonlinear crystal gives rise to a coupling between the pump wave and two virtual waves for which the crystal cavity has resonances. In order that the two waves can experience large gain, the sum of their frequencies must equal the pump frequency, and furthermore the beams must move in such directions in the crystal that phase matching can occur, which means that the sum of their momenta equals the pump momentum. Under these conditions the two waves can build up and oscillate. This condition is temperature dependent and frequency tuning in the 9,500-to-12,000-angstrom region was obtained by varying the temperature of the crystal from 50°C to 60°C. The tuning is fairly smooth with occasional jumps of the order of 100 cm⁻¹ due to the discrete optical mode structure in the cavity. Additional tuning with a biasing electric field could probably reduce this difficulty. A 0.1% efficiency from laser pump to parametric laser output was reported with very good monochromaticity.

It has been suggested that parametric down-conversion can be used to make a cw tunable oscillator in the 15-to-25 micrometer region using a cw high-power CO₂ laser at 10.6 micrometers as the pump and a tellurium crystal as the nonlinear element. Appreciable powers may be expected.

Fine-Frequency Tuning Methods

Earlier we mentioned that external fields such as magnetic and pressure fields can be used to tune injection lasers. The tuning by magnetic field can also be applied to high-gain gas lasers and was used in one of the early investigations of tuned laser spectroscopy. The tuning range is not large, 1-cm⁻¹ tuning requires magnetic fields of the order of 5 kilogauss. Such large fields usually have a deteriorating effect on the power output of the gas lasers. Moreover, they require expensive solenoids.

Another method with an even smaller tuning range is to displace the light beam by a traveling acoustical wave. The frequency of the dislocated light waves is now increased or decreased by a multiple of the acoustical frequency. Since acoustical waves above about 2 GHz undergo strong attenuation except for low temperatures, tuning beyond 0.1 cm⁻¹ is difficult.

The small tuning range mentioned above can in principle also be obtained by cavity-pulling, that is, by changing the laser wavelength by making a small change in the distance between the end reflectors. The accuracy obtainable in that case is probably less than if one uses acoustical tuning; nevertheless this method has been used to measure the
Abbreviated temperature in a xenon gas dis-

A modest amount of tuning has also been obtained by mixing the laser fre-

PASSIVE SPECTROSCOPY

In order to discuss the type of new infor-

Rayleigh Scattering

Rayleigh scattering could be defined in a slightly unfair way as that fraction of the light, scattered by a medium, which before the use of lasers was treated as having the same spectral distribution as the incident light. The pre-laser experi-

Rayleigh scattering is spectrally broader than the incident laser light26 and used this information to derive particle size and the presence of local velocities in the liquid. These experiments measured laser line broaden-

Rayleigh line determines the decay time of fluctuation of that particular wave-

Brillouin Scattering

Let us briefly review the theory of lattice modes in solids. If one plots frequency of vibration as a function of the reciprocal of the corresponding wavelength, one finds that there are several branches. From the origin out, one has a longi-

Brillouin Scattering

The authors report a relaxation in toluene by measuring both velocity and absorption versus the wavelength of the hypersonic phonon. Other areas of interest where lattice interactions are impor-

NONLINEAR SPECTROSCOPY

When the light fields used to excite the Brillouin or Raman vibration are very strong, stimulated emission can occur at the Brillouin or Raman shifted frequencies. This phenomenon was already men-

SOME USES OF LASER SPECTROSCOPY

It is not feasible in the limited space to cover this subject in great detail. From the previous discussion it is clear that an appreciable increase in our knowledge of materials has and is taking place due to laser spectroscopy. This knowledge is probably opening up new fields of study, such as detailed understanding of liquid-solid phase transitions. As another application of passive spectroscopy, let us consider the studies of plasmas.

One of the early experiments of this kind28 was done with the goal to measure plasma density as a function of time during a discharge. This measurement was made by placing the discharge tube inside the laser interferometer. The plasma density could then be determined by counting the number of passing fringes. This method has been developed to the point where plasma densities above 10^16 electrons/cm^3 can be measured with a 0.25-mm spatial resolution and a time resolution below 1 ps. Also cooperative
electrostatic oscillations have recently been observed by measuring the spectral distribution of ruby laser light from a dense plasma. If a laser is used based on gas transitions similar to those occurring in a given discharge, the laser can then serve as a probe to measure, for example, the density of an excited state or temperature as a function of position in a discharge tube.

An example of active laser spectroscopy is the experiment referred to earlier in which line shapes and relative line positions were determined with a high precision. The line shapes measured were used to determine collision diameters in methane and other gases. Also information about Stark splitting in gases has been obtained using the same technique. The saturation observed in the experiments leads one to believe that this type of selective excitation may be useful in synthetic chemistry. One limitation to very high resolution studies is that at room temperature and low enough pressure that collision broadening is negligible (in practice this means less than about 10-torr pressure), the Doppler linewidth of a gas having the density of air is 0.007 cm⁻¹. The natural linewidth of a gaseous absorption line, however, is determined by the spontaneous emission lifetime and is often two orders of magnitude or more below the Doppler linewidth. It was shown by Javan and coworkers that when enough laser power is available to saturate the gaseous absorption line, the frequency width is given by the inverse natural lifetime and not by the much broader Doppler width.

As to some applications of laser spectroscopy, it is evident that it has use in the field of analytical chemistry. Trace amounts of gases can be detected using lasers. Methane can be detected easily at very low concentrations by its absorption, using a HeNe laser. Isotope ratios in tracer experiments may be determined readily. Raman radiation can be used for identification of materials. The laser has also been used as a microprobe. A Q-switched laser is focused on a surface and the vapor plume coming off is then excited by passing it through a dischargeable spark gap. Enough light is then available to photograph the spectrum. This method has some advantages and also disadvantages compared with the electron microprobe. Advantages are: it works on heavy as well as light elements and is rather inexpensive. Disadvantages are mainly in the errors involved in absolute concentration measurements and in its rather large (≈ 60 micrometer) spot size.

Conclusion

Although certain measurements can be made with greater precision, or have been made possible at all when the laser is used in place of conventional sources, laser techniques have not as yet developed to a stage where they can compete with general-use spectroscopes. Any meaningful evaluation of the technological usefulness of stimulated-type lasers, is still premature. In addition to the possible uses already mentioned in the foregoing text, the following may be noted:

1) A new phenomenon observed is that intense hyperonemic waves can be generated that they often damage the crystals in which they are excited.  
2) Anti-Stokes stimulated emission could be useful for sophisticated low-temperature cooling.  
3) The possibility of Raman tunability in the Q-switched lasers may allow one to make three-dimensional holograms of fast-moving objects at such a wavelength that coincidence can be chosen with an existing cw gas laser for steady-state viewing.

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LASER DIGITAL DEVICES

As opposed to most applications in which lasers are used basically as special sources of radiation, this program is concerned with whether laser components could form a new generation of switching circuits for digital computers. This paper describes only laser digital devices in which all of the processing signals are in the form of optical energy. These devices could be used as general-purpose logic circuits in the same way that transistors are presently used for this purpose, except that all of the processing would be done with optical rather than electrical signals. The operation of the laser digital devices is based on a signal gain derived from a laser amplifier and on nonlinear (saturable) interaction of intense optical signals with laser materials. The two basic nonlinear processes are quenching of the output of a laser oscillator and saturation of optical absorption. This paper is condensed from the material contained in Ref. 1, plus summaries of some of the recent results obtained under a new contract with Rome Air Development Center. A bibliography of RCA efforts in this area is given by Ref. 2-6.

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The operation of laser switching devices can be based on amplification of optical signals by a laser amplifier and the two nonlinear processes: saturation of gain (quenching), and saturation of optical absorption. Our present work is centered on the study and development of GaAs inverter circuits whose operation is based on the amplification of an input signal by a laser amplifier and quenching of the output of a laser oscillator. Another class of laser switching device can be constructed by placing saturable absorber material inside a cavity that also contains emissive (laser) material. Depending on the relation between the material constants of the absorber and emitter, these devices can operate either as bistable or monostable circuits. A bistable circuit, operating as a laser oscillator that can be triggered on and off by externally applied optical signals, can be made using semiconductor laser materials. However, it is not very likely that a proper saturable absorber can be found to make semiconductor monostable circuits. We have, however, demonstrated the operation of a monostable circuit, using a ruby laser as the emitter and different solutions of phthalocyanine as the saturable absorber. These ruby laser devices were also operated as relaxation oscillators, more commonly known as passive Q-switch lasers.

The processes of optical absorption and stimulated emission are distinguishable only because of the difference in the occupation of the energy levels involved in the optical transitions. Therefore, basically the same criteria can be used to estimate the optical signal levels needed to cause an appreciable change in the populations of the energy levels for either of these processes.

The condition of steady state saturation is applicable when the duration of the applied optical signal is longer than the spontaneous recovery times of the material. In this case, the absorption (or the gain) is reduced to one-half its low signal value when the stimulated transition rate becomes equal to the recovery rate associated with spontaneous transitions. For a material with a purely radiative recovery process, the signal power density $P_s$ in watts/cm$^2$ required to reach this condition can be estimated by:

$$P_s = \frac{12 \pi n^2 \Delta \gamma}{\lambda^2}$$

where $\lambda$ is the wavelength in micrometers, $n$ is the index of refraction, and $\Delta \gamma$ is the homogeneously broadened linewidth in wave numbers, cm$^{-1}$. For most available materials, the expression in Eq. 1 must be multiplied by the ratio of the radiative lifetime $T_s$ to the actual recovery time that tends to bring the system towards the steady state condition. For optical pulse signals whose durations are considerably shorter than the spontaneous recovery time constants of the materials, the minimum energy density $W_s$ in joules/cm$^2$ required to reduce the absorption (or the gain) coefficient to 0.37 of its low signal value is:

$$W_s = \frac{h \gamma}{2 \sigma}$$

where $h \gamma$ is in Joules/photon and the absorption cross sections $\sigma = a/N$ where $a$ is the absorption coefficient in cm$^2$ and $N$ is the density of the absorbing sites. For material with homogeneously broadened absorption lines, the energy density $W_s$ in joules/cm$^2$ can also be estimated by an expression analogous to Eq. 1:

$$W_s = \frac{12 \pi n^2 \Delta \gamma T_s}{\lambda^2}$$

Since the radiative lifetimes of optically pumped solid-state lasers are of the order of a millisecond while the radiative lifetimes of semiconductor lasers are of the order of a nanosecond, optically pumped lasers are more suitable as high energy pulse generators. However, semiconductor lasers are the most suitable components for small signal switching devices as the energy density that must be developed within a laser digital device for one switching operation is proportional to the homogeneously broadened linewidth $\Delta \gamma$ and the radiative lifetime $T_s$ of the optical transitions. Although materials with strong optical transitions and short radiative lifetimes also tend to have somewhat wider linewidths, the energy required to cause one switching operation in optically pumped lasers, such as ruby or neodymium lasers, can be estimated to be about five orders of magnitude higher than for GaAs lasers. The upper bound on the switching time of a laser digital device is determined by the effective recovery time toward a steady-state condition. A reasonable estimate of the recovery time for optically pumped solid-state lasers is $10^{-6}$ seconds in comparison to $10^{-9}$ seconds for GaAs lasers.

![Fig. 1—GaAs laser inverter. (a) pictorial view; (b) schematic of active laser region.](image)
Dr. WALTER F. KOSONOCKY received the BS and MS in Electrical Engineering from Newark College of Engineering, Newark, N. J., in 1955 and 1957, respectively. In 1965 he was awarded Sc.D. degree in Engineering by Columbia University, New York, N. Y. Since June 1955 he has been employed at RCA Laboratories, Princeton, N. J., where after one year as a Research Trainee, he became a Member of the Technical Staff in the Computer Research Laboratory. His work has included: development of the ferrite aperture plate memory system, application of transistors in computer circuits, investigation of the use of ferrite cores and micromagnetic techniques for high speed computers, application of tunnel diodes for digital computer logic and memory systems, development of tunnel-diode/transfer high-speed computer circuits, and a study of pattern recognition systems. Since April 1962, Dr. Kosonocky has been engaged in a feasibility study of the use of lasers as digital computer components. He received an RCA Laboratories Achievement Award in 1959 for his contributions related to the application of parametric devices for digital computer logic and memory systems; and in 1963 he received an RCA Laboratories Achievement Award for his contributions to applications of tunnel diodes and transistors for high speed computer systems. He was also awarded the David Sarnoff Fellowship for the academic year 1958-1959. Dr. Kosonocky is an Adjunct Professor at Electrical Engineering Department of Newark College of Engineering. He is a member of Sigma Xi, Tau Beta Pi, Eta Kappa Nu, and IEEE.

ROY H. CORNELY received the BS in Electrical Engineering from Newark College of Technology in June 1960. As part of the cooperative industry program at Drexel, he was employed by the Telecaster Company, Stanford, Conn. In 1961, he attended the Moore School of Electrical Engineering at the University of Pennsylvania and was a part-time instructor of Physics at Drexel. In 1962, he received a Master's degree in electrical engineering from Drexel. He joined the Technical Staff at RCA Laboratories. His initial assignments were in the magnetics section where he worked on high speed memory and magnetic flux logic devices. He made a basic study of magnetic flux reversal processes in ferrites. Since June 1963, he has been concerned with the application of optical phenomena to new digital devices.

We have experimentally verified the validity of Eq. 2 in a study of the saturation of absorption of an unpumped ruby crystal illuminated by pulses from a ruby laser. Our subsequent experiments with solution of phthalocyanines indicated that the steady state saturation process appropriately describes the response of these solutions when they are illuminated by pulses from a Q-switched ruby laser. The absorption spectra of these solutions are reduced to a band to band transitions would be very complex, our experimental results suggest that essentially the same analysis as that applied to transitions between discrete levels can also be applied in the case of GaAs lasers. Our recent work on the large signal response of the GaAs laser amplifier points out that the gain coefficient in the amplifier also saturates at a flux power density on the order of 0.1 MW/cm².

GaAs Laser Inverter

Basic logic operations such as or-not and and-not can be performed by a laser digital device that operates as an optical inverter-amplifier. The inverter consists of a laser amplifier wherein part of the amplifier junction area is utilized as an oscillator. The construction and operation of the laser inverter is shown schematically in Fig. 1. In the absence of an input φm, the oscillator section of the device produces an output signal φout. As the input signal φm is increased, the gain in the oscillator section decreases to the point where the output φout of the laser oscillator is quenched. The amplified input signal φm may be used as an input to another inverter or it can be dissipated in an appropriate termination.

For construction of laser inverters we try to use GaAs laser materials that lase uniformly across the whole junction region. A laser amplifier can be formed between sides 1 and 2 by using nonreflective coatings or by lapping side 2 at a vertical angle with respect to side 1, thus destroying the laser cavity between these two sides. The laser amplifier described is formed by lapping side 2 at a vertical angle of 15°. The laser oscillator is between the cleaved sides 3 and 4. Sides 5 and 6 are roughened by abrasive paper to prevent external oscillations in the laser amplifier structure. A typical unit is 4 mils high, sides 1 and 2 are 10 mils wide, sides 5 and 6 are 26 mils long, and sides 3 and 4 are 4 mils wide.

The operation of the laser inverter was demonstrated using an external input signal derived from a laser oscillator. Both devices were made from the same GaAs wafer. Lenses were used to refocus the output of the source laser on the active laser region of side 1 of the inverter. The laser devices were individually mounted in two small vacuum chambers on cold fingers cooled by liquid nitrogen. The test results are shown in Fig. 2. The waveforms of the input signal φm, the amplified input φA, and the inverter output φout are shown in Fig. 2a, b, and c, respectively. The input signal is applied 80 ns after the inverter is energized, so that amplification and quenching take place only during the pulse overlap period. These waveforms...
were detected by an RCA 7102 photomultiplier with an aperture sufficiently large to capture most of the optical signal in each case. The peak intensities of these signals are $I_\text{in} = 150$ mW, $I_\text{out} = 50$ mW, and $I_\text{sat} = 10$ mW. The input signal $I_\text{in}$ was measured by removing the inverter from the path of the source beam.

Therefore, the value of $I_\text{in}$ does not equal the signal actually coupled into the laser inverter, but rather it represents the total signal available from the source laser.

We are studying the quenching characteristics of a GaAs laser oscillator using a dual laser oscillator such as shown in Fig. 3. Typically, the dual laser-oscillator contains two resonators within one laser structure, one 10 by 4 mils and the other 10 by 30 mils. Isolation in the described unit was achieved by saving a groove through the top metal contact into part of the semiconductor material while monitoring the leakage conductance. The isolation resistance between the two diodes is about one ohm, which is sufficiently large to allow separate electrical control of the two oscillators. However, we can also achieve complete electrical isolation, as well as coupling optical signals between two laser regions, by using a specially prepared laser material in which, as is shown in Fig. 4, a 5-micrometer P-region is sandwiched between two parts of the N-region of a GaAs laser wafer. A test dual laser-oscillator was made from the same wafer that was used for the laser inverter. The operation of the dual laser-oscillator is illustrated in Figs. 5 and 6. Fig. 5a shows the waveforms of the applied currents to the small oscillator $I_s$ and to the large oscillator $I_L$. Fig. 5b shows the variation of the output of the small laser as a function of the output of the large laser. Note that: 1) the quenching is a linear process, and 2) excluding coupling losses, the amplifier portion of the laser inverter must provide a signal gain of more than 10 for complete quenching of the inverter output and a fanout of two. We have found that in the case of certain specially prepared GaAs laser materials the quenching ratio, defined as the slope $\Delta I_\text{in}/\Delta I_\text{out}$ in Fig. 6, can approach a value of 0.5. In our opinion, the quenching ratio is determined by the ratio of the effective thickness of the inverted population region to the thickness of the optical beam guided by the GaAs laser. Thus materials with wider inverted population regions would tend to have more efficient quenching characteristics. Our study of radiation confinement in GaAs lasers points out that at 77°K the optical beam is about 1 micron wide. This result based on near-field emission measurements is also consistent with the diffraction limited far-field emission pattern of GaAs lasers.

**GaAs Laser Amplifiers**

Typical performance of the amplifier part of the inverter is illustrated by the waveforms of Fig. 7. In this test special care was taken to detect only the output signal of the amplifier. The laser amplifier dimensions were 5 by 30 mils. Its output facet was lapped at a 15° vertical angle. The output spectrum of the source laser overlapped the peak of the amplifier fluorescence spectrum of the amplifier. The output of the source laser was focused onto the input facet of the amplifier using the experimental setup shown in Fig. 8. The devices were operated at 77°K. Both units were driven by equal 120-ns-duration and 8.0-amper-amplitude partially-overlapping current pulses. There is a ratio of 80 between the scales in part a and part b. Both parts of the figure, however, show the same detected output signal. The detected output signal, therefore, consists of three different output levels. The first portion of the output $S_n$, which is clearly visible in the lower photograph, represents the transmission of the source signal when no current is applied to the laser amplifier. The second output level $S_n$ represents the amplified input signal. The third output level $S_n$ is due to super-radiance of the amplifier. The detected signal amplification defined as $(S_n-S_n)/S_n$ was found to be as high as 500. The net transmission signal gain, defined as $(S_n-S_n)/S_n$, where $S_n$ is the total output of the source laser, was about unity for large input signals and approached a value of only 5 for very low input signals.

To achieve better signal coupling between the oscillator and the amplifier, we have constructed directly coupled GaAs laser devices in which the separation (on the order of one micron) between the oscillator and the amplifier is made by cleaving. A photograph of the side view of such an oscillator-amplifier pair is shown in Fig. 9. In the tests of the directly coupled amplifier, a net signal gain of about 20 for low input signals (of about 10 mW) was obtained. The gain coefficient saturates to one-half of its low signal value at a signal flux power density in excess of 0.1 MW/cm². The saturation of the gain coefficient can be observed from the measurement of the transmission gain and from the reduction of the amplifier fluorescence spectrum due to the application of an input signal.

The GaAs laser amplifier is expected to have a very large gain-bandwidth product. The delay time for passing a signal through the amplifier can be estimated...
ated to be on the order of $10^{-9}$ second. A simplified theory of the operation of GaAs laser amplifiers predicts a signal gain as high as 10 for an amplifier current that is 8.5 times larger than the laser threshold current for an equivalent laser oscillator. However, on the basis of our measurements, we expect that a signal transmission gain between 10 to 100 is a more realistic figure due to the gain-saturation effects associated with amplified fluorescence. One of the main limitations of a GaAs laser amplifier, which in true for laser amplifiers in general, is that it has a very large noise signal due to amplified fluorescence. Since the signal amplified by the amplifier portion of the inverter is not used directly as an output signal, the GaAs laser inverter is an example of a device that takes advantage of the high gain characteristics of the laser amplifier while it still discriminates against the noise signal.

**GaAs Laser Inverter Switching Circuits**

The GaAs laser inverter is most suitable for performing or and or-not logic functions. It is generally recognized that the transfer characteristic of a digital circuit must have a threshold level, which will prevent the circuit from responding to either low level or noise signals, and a saturation region into which the circuit switches to produce a fixed output level when the applied signal is well above the threshold level. A closer inspection of digital devices points out that both threshold and saturation are needed only for the noninverting devices. An inverter, however does not require threshold for low signals if it has a good cut-off region. This point is illustrated by the sketches in Fig. 10. A network of three cascaded levels of laser inverters is shown in Fig. 10a. The remaining parts b, c, and d give the signal transfer curves for the input signal $P_i$ through one, two, and three levels of inverters. The GaAs laser inverter has a natural capability for a fan-out of two and a fan-in of one. Two approaches for allowing more than one input, without sacrificing the isolation properties of two perpendicular light beams, are shown in Fig. 11.

Presently, we are attempting to establish the basic feasibility of GaAs laser inverter circuits by: 1) using high precision optical equipment, as shown in Fig. 8, for the coupling of signals between laser devices, and 2) by developing techniques for direct coupling of optical signals as, for example, is illustrated in Fig. 9. With these approaches, however, we expect to be able to interconnect only a small number of gates. The only realistic approach is to develop techniques for integrated GaAs laser digital devices. Then, one could visualize an array of active laser circuits in the form of a pattern of strips of high-gain laser amplifiers made into inverters by a set of reflecting boundaries. These inverters, in turn, would be interconnected by low-gain (or low-loss) laser amplifier transmission lines to form logic circuits. The major technological problem that would have to be solved to make this concept a practicality is to find means for making reflecting boundaries which could change part of a laser amplifier into a laser oscillator without physically separating the laser oscillator from the whole GaAs wafer.

At least in principle, semiconductor laser digital devices have several very attractive characteristics for high-bit-rate batch-fabricated digital circuits. The optical interconnections are free from inductive and capacitance effects. There is a natural impedance match between the active device and the transmission medium (both of which may be in the form of semiconductor laser components). The delay time constants associated with any mismatches can be made very short, on the order of $10^{-11}$ second. A single plane crossing of two optical signals should be possible if the planar dimensions of the optical waveguides are large as compared to the wavelength of light. Finally, switching times on the order of $10^{-9}$ to $10^{-10}$ second are possible with GaAs laser digital devices. The only major disadvantage, in terms of the present state of development of GaAs lasers, is that even at liquid-nitrogen temperature a current on the order of an ampere is required for a device having planar dimensions of several hundred square mils. The power requirements per logic element will have to be reduced by at least a factor of 100 in order that laser digital devices be competitive with transistor technology. To accomplish this, a monolithic technology for the fabrication of the GaAs laser devices with planar dimensions on the order of one mil for an individual component must be developed.

**ACKNOWLEDGMENT**

The authors wish to express their appreciation to W. H. Bleacher and W. Romito for their contributions in preparation of GaAs materials and devices.

**BIBLIOGRAPHY**


THE SIGNIFICANCE OF THE LASER IN MEDICINE AND BIOLOGY

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The demonstration of a new and unique form of radiant energy usually results in an immediate speculation as to its possible use in Medicine and Biology. Only a few months after the discovery of the X-ray it was already being used for diagnostic purposes. High frequency diathermy and various nuclear radiations are further examples. Laser radiation is no exception. Unfortunate experience with X-rays in the early days demonstrated the importance of understanding the biological effects of radiation as a means of protecting those who may be exposed to it in the course of their experiments. An enormous amount of information has been accumulated on the biological effects of microwaves, X-rays and other forms of electromagnetic radiation primarily in the study of protective measures.

In the case of the laser, this background was of considerable help in approaching the study of the significance of laser energy in Medicine and Biology. There are three areas of interest:

1) An understanding of the hazards of laser radiation,
2) The possible use of the laser beam as a tool in Medicine and Biology, and
3) The direct interaction of laser radiation with biological materials with a view to its possible therapeutic effects.

HAZARDS

The laser forms the most concentrated source of energy available to man. Power densities many times that found at the surface of the sun can be produced. It is this tremendous flux density that creates the greatest hazard. The possibility of damage when a laser beam falls on the surface of tissues can depend upon several factors:

1) The pigmentation of the tissue—the more concentrated the pigmentation, the more absorption.
2) The available blood circulation which acts as a coolant and will tend to prevent damage due to temperature rise.
3) The spectral absorption of the tissue. If the tissue is of a color that will selectively absorb the specific wavelength being radiated, the possibility of damage will be correspondingly greater.

When a laser beam contacts the skin the immediate effect is an eruption from the surface due to a rapid heating. This in itself would produce only superficial surface damage. However, deep-seated damage has been observed which is out of proportion to the observable damage on the surface. True, the relative transparency of the skin may allow half or more of the radiation to be absorbed at a deeper level. It has been suggested, however, that the primary cause of deep seated lesions is the generation of a pressure wave which inflicts mechanical damage rather than the more obvious thermal effects. This pressure wave might be generated in three ways:

1) Eruption on first contact ejected material at high velocity. Conservation of momentum would account for the generation of an inward pressure wave.
2) Transient heating would result in thermal expansion.
3) Transient heating would generate trapped gases in the interior of the tissue.

In any case, the result seems to be the generation of a shock wave which progresses through the tissues breaking down the cell walls.

The organs of the body are susceptible to specific damage to varying degrees. By far the most sensitive is the eye. The lens and cornea are transparent to the laser radiation and, in addition, can receive the beam directly. The cornea is exposed to 90% of the beam flux, which in turn is converted into heat. The temperature rise of 2°C will result in total vaporization of water.

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Fig. 1 — Laser coagulator. (Photo courtesy Laser Focus magazine.)
concentrate the energy several fold by the normal focusing action onto the surface of the retina where it can do the most damage. Direct exposure to the primary beam is not the only hazard in the case of the eye. Specular reflections from objects in the path of the beam by chance or reflection from a lens surface can be equally dangerous.

Much attention is being given the hazards of laser use and rules of safety concerning their operation, and the permissible thresholds are in a state of constant evaluation and updating.

THE LASER AS A TOOL

The high concentration of energy in the laser beam makes it attractive as a tool in certain biological and medical procedures. The most highly publicized use to which it has been put is in photocoagulation at the retinal surface of the eye. The laser has been used as a photocoagulator with success in many cases. It has not been clearly established, however, that it is superior for this purpose to other sources of light. Some dangers exist in its use because of the high absorption of other parts of the eye such as the iris. It would appear for the moment that the laser as a photocoagulator is useful because it is a convenient source of high intensity light and not because of its unique property of coherence.

Other uses as a tool in cellular studies also make use of the extremely small area into which tremendous power can be concentrated. For example by focusing the beam through a microscope it is possible to reduce the spot to subcellular size. It can thus be used as a probe to selectively hemolyze individual cells for study of their constituents.

THERAPEUTIC USES OF LASERS

One of the more exciting aspects of the use of lasers in medicine is the possibility of selective destruction of tumor cells. A number of experimenters have worked in this area, irradiating both natural and transplanted tumors in animals (Fig. 2) and natural tumors in humans. Tumor tissue is destroyed by laser radiation but this mechanism is not yet understood. A localized thermal effect accounts for a part of the action, but several workers have reported an apparent build up of an effect which may destroy the tumor over a period of days after irradiation even though the immediate effect may be minimal. They speculate on a possible change in the enzyme activity in the material or the generation of a toxic material which causes the tumor to regress over a period of time. Another possibility is the formation of an antigenic material by action of the radiation on protein constituents of the tissue. While these effects, which are not understood, are extremely interesting, one researcher stated that the observations were reported with "suppressed enthusiasm" because as yet there are so many unknowns and the experiments have not been well controlled.

Whether, again, the effects on tumor tissue are thermal, mechanical or due to the high degree of monochromacity and coherence of the radiation, specific effects are being produced which account for the observed results. Electron spin resonance experiments have been conducted with biological material being irradiated by laser radiation in vitro. The results indicated that free radicals were being produced by the laser radiation. The effects of such action in a living tissue are not yet known.

CONCLUSION

As is often the case with a new technique, the early reports of the uses of lasers in medicine were, in many cases, optimistic. A selective means of simply destroying malignant tumors would be so important that every encouraging result is apt to be reported out of proportion to its significance.

At the moment, it appears that the laser is an important tool in microsurgery, and it does appear that there are non-thermal effects in the reaction of laser radiation with tissues. Some of these non-thermal effects have shown some relation to the post-radiation regression of tumors. A large number of competent workers are exploring the field with the latest equipment, with greater emphasis placed on the control of both the equipment and the experiments. The results are certain to be exciting.
LASER SAFETY CONSIDERATIONS

Described here is a program of safety to provide adequate safeguards against the potential hazards of the laser. The program considers matters of sight hazards, since the radiance of a laser can exceed the level which the human eye can safely tolerate. It also considers other factors involving cases where focused or unfocused laser beams can produce burns on tissue or vaporize certain materials. A bibliography of references on laser safety is included.

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Over the past decade, the laser has evolved from its initial position of experimental device to its present position of well-established, highly versatile tool of technology and research. The species of lasers has expanded from the first solid state laser, ruby, to encompass gas lasers and semiconductor lasers. Their frequency range extends from the infrared to the ultraviolet. Generally, either pulsed or continuous mode operation is available; however, some lasers can be operated in both modes. The available power ranges from a few milliwatts to a few hundred watts for continuous wave operation, and up to one gigawatt for pulsed operation.

Lasers are unique sources of light that produce beams characterized by high intensity, high monochromaticity, and divergences of a few milliradians. It is these properties that make the laser such an effective tool for welding, drilling, photocoagulation, photocoagulation, ranging, and the other myriad applications that exploit its capabilities. These remarkable benefits, however, are not available without attendant potentially severe hazards to improperly trained operators. Its radiance, already many times greater than that of the sun at the same wavelength, exceeds the level that the unaided human eye can safely tolerate. Laser beams, both focused and unfocused, can produce burns on tissue and can vaporize certain materials so quickly that the beam must not be permitted to impinge on explosive substances.

Much of the literature dealing with the hazards encountered in work with lasers concentrates on the provision of protection against eye injury. A program of eye protection from laser radiation should have two aspects: 1) provision of protective eye shields, and 2) institution of a hazards control procedure. Goggles are available that have been designed specifically for protection of the eyes from the light emitted by the commonly used lasers. Great care should be taken to use only the goggles that is appropriate protection against the particular laser being used. Several optical equipment manufacturers, such as Bausch & Lomb and the American Optical Company, make these "anti-laser" goggles. Special attention must be given to the necessity of screening out the harmful ultraviolet light produced by the argon laser in addition to attenuating the visible lasing frequencies. Glass and many plastics are almost opaque to emission from the carbon dioxide laser. In fact, it is convenient to enclose both ends of the laser tube in a plexiglass enclosure. A useful listing of laser emission is contained in Reference 13.

Specification of the required optical...
density of the goggle filter at the laser wavelength is the most critical criterion for assuring adequate protection. This optical density should be available in a relatively flat region of the filter absorption characteristic, and not at a point where the filter absorption changes rapidly. In addition to satisfying this criterion, the filter must not craze under impact of radiation from high-power lasers. The choice of a value of optical density will depend upon a selection of a safe dosage of radiation for eye exposure. Unfortunately, there is not general agreement on where this level should be set. To select as this level the minimal radiation dosage that just produces a retinal lesion—lowered by an appropriate safety factor—would seem a reasonable choice. However, the wide variance in the absorption properties of the retinas of different individuals, the incomplete understanding of the effects induced by an apparent breakdown of reciprocity, lack of a determination of any possible chronic effects arising from long-term, repeated low-dosage exposures, and insufficient data to cover the complete species of lasers make it difficult to establish such a level. An upper level of 0.5 mW/cm² incident on the eye is suggested for continuous wave emission. For pulsed operation—durations of milliseconds and shorter—the same level is suggested, but the level now refers to peak power per square centimeter.

The second aspect of the program of eye protection can be formulated in accordance with some of the following general guidelines:

1. Never view an insufficiently attenuated laser beam or its specular reflection.
2. Wear appropriate protective goggles.
4. Keep specular reflectors out of the path of the laser beam.
6. Avoid work environments with low ambient room illumination.
7. Post signs alerting others to the presence of laser radiation.
8. Use count down techniques when firing high-power pulsed neodymium lasers so that room occupants may look away from the direction of the beam.

Although not much attention has been directed toward the hazards associated with semiconductor lasers, such as gallium arsenide, gallium arsenide-phosphide, and indium antimonide, some preliminary observations suggest that the intense 8,400-Angstrom emission from gallium arsenide produces excitation of the eye. It is recommended, therefore, that these laser beams not be viewed with the unaided eye. Image converters can be used to make observations on these lasers. The focused image of the junction of a semiconductor laser has produced charring of paint, hence extreme caution should be exercised when working with optical systems that produce a sharply focused image of the laser junction. Experiments that produce lasering in semiconductors by electron bombardment can also produce X-ray intensities in excess of the maximal permissible dosage. Adequate shielding must be provided for these setups, and X-ray warning signs posted.

High-energy neodymium and ruby lasers with exit energies in excess of a few joules have produced superficial burns on human skin. Investigation of the effects of repeated laser exposures of varying dosages is just now beginning, and although the studies are far from complete, preliminary findings indicate that the avoidance of exposure of the skin to any pulsed laser radiation is not too extreme a precaution. It is noted that the susceptibility of the skin to damage increases with increases in its pigmentation.

The interaction of high intensity laser radiation with matter is very often accompanied by the generation of pressure waves, in solids, photothermal effects in liquids—both of which may result in formation of plumes and sprays—and dielectric breakdown. Shattering of the material or rupture of the containing vessel can occur in the presence of the first two effects, and arcing of high voltage terminals as well as disruptive gas breakdown in instances of the third.

A program of safety that takes into account the laser safety considerations just discussed as well as the more detailed ones treated in the references should provide adequate safeguards against the potential hazards of the laser.

**BIBLIOGRAPHY**

DRILLING OF MICROSCOPIC HOLES IN METALS BY LASER BEAM

This paper investigates the feasibility of drilling microscopic holes in metal by using a beam of light from a laser. A series of experiments on different materials that can be so ablated determined the energy and power required to remove a given volume of target material. The character of the resulting hole was studied, including shape, precision of location, and the repeatability of shapes.

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The high-intensity radiation from lasers can be utilized to ablate structural material and produce holes or cavities. It is possible to drill holes smaller than 0.001 inch in diameter in metal as hard as tungsten with precision and without injurious heating of the metal. This technique of drilling should be particularly useful in fabricating extremely compact micro-energy memory devices.

DESCRIPTION OF LASER EQUIPMENT

Source

The laser chosen for the experiments was a small ruby rod 0.2 inch in diameter and 2.5 inches long. Ruby was selected for its ease of use. Its output wavelength is in the visible region of the spectrum (6,943 angstroms) and its output energy is high relative to other materials.

The ruby was clad in sapphire (0.4-inch outside diameter) and was pumped by an FX-42 lamp with pulses 400 μs in duration. The elliptical cavity was 2 inches in diameter and 3 inches long with 1/4-inch interfocal separation. A 17-inch long interferometer configuration was terminated by a 50% reflector on the output end and by a 99.5% multilayer dielectric reflector directly deposited on the plane ruby face at the other end (see Fig. 1).

Attenuators

Small holes are of interest, so the laser beam must be focused to a fine spot on the specimen resulting in high energy density on a small area. While high energy density is desirable for drilling holes through thick metals it is undesirable for thin metals and deposited film targets. A method for adjusting incident energy was therefore essential. One method considered was the adjustment of laser output by variation of the input pump power. This method has limited applicability because the output from the ruby is still quite high at the threshold of oscillation (i.e., the least energy of excitation at which laser action can occur). Also, the range of output energies obtainable by variation of pump input energy is not great enough for the anticipated needs.

Another means considered for adjusting incident energy was the use of an attenuator. A problem arising from the use of commercially available precision attenuators is lack of durability. At laser energies, some transmission attenuators burn through with one or more exposures; others lose calibration with extended use. Iris diaphragms can suffer damage as their leaves become burned through or welded together. Liquid optical attenuators with an absorbing dye can be used, but they are subject to bleaching or non-linear action.

Neutral density filters, unless especially constructed for this application, might be completely destroyed by the blast from a single shot. Optical filters in general become non-linear at extreme values of incident energy. This non-linear effect has been found useful in saturable absorber Q-switch applications but was avoided in this case.

A good absorber for high intensity ruby emission was found to be an aqueous solution of cupric sulfate. Four liquid cell absorbers using this material were fabricated and tested. The cells were found to be linear over the range of intensities to be used in this series of experiments. They were calibrated at lower light levels using a spectrometer and then checked at the high end of the range with a laser as the source.

The low range accuracy was estimated to be ±0.5% and the high range accuracy to be ±1.5%. The filter transmission percentages are:

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<tr>
<th>Cell 1</th>
<th>4.5%</th>
<th>Cell 3</th>
<th>13.0%</th>
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<tr>
<td>Cell 2</td>
<td>5.2%</td>
<td>Cell 4</td>
<td>7.4%</td>
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Additional attenuation was obtained by use of geometric redistribution of the laser beam cross section. By the arrangement of lenses shown in Fig. 1, the direct output was expanded and recollimated. The beam expander entrance pupil was 5 mm and the beam expanded objective focal length was 32 mm. The beam expanded secondary lens had a focal length of 182 mm. The exit pupil diameter \( D_e \) is given by:

\[ D_e = \frac{l_1}{l_2} D_o \]

where \( l_1 \) is the focal length of the first lens, \( l_2 \) is the focal length of the second lens of the beam expander, and \( D_o \) is the diameter of the entrance pupil; \( D_o \) is seen to be 5.7 times that of the entrance pupil. The energy density ratio is the square of the entrance to exit pupil diameter ratio or 32.5. By adjusting the lenses so as to be confocal, the emergent radiation was made parallel.

The expanded beam was reduced further in intensity by combinations of the four liquid-cell absorbers.

Aperture

To obtain fine continuous adjustment of the beam intensity, an aperture adjust-
The hole diameters were measured by the collimator arrangement shown in Fig. 3, using a microscope objective lens with accurately known focal length. The ablated hole was located in the principal focal plane of the objective. The angular diameter \( \theta \) of the hole was read in the collimating lens which resolved better than 0.5 second of arc.

As in Fig. 3, the hole diameter \( D_h \) was related to the angular diameter by \( D_h = f \theta \), where \( f \) was the focal length of the lens and \( \theta \) was read in the auto collimator directly and photographed by an attachable Polaroid camera. Deviations from circularity were thus recorded. Diameters of ablated areas were determined by 1) direct measurement of circular holes or 2) by calculation of equivalent diameters of irregular areas measured by a planimeter. The results of these computations are shown in Figs. 4 and 5.

As the energy was increased beyond that required to ablate a hole of given size, the radiation first ablated the hole and the remainder passed through the hole. The duration of the laser pulse had an effect on the energy vs hole area relationship and upon the physical nature of the hole.

When the laser was \( Q \)-switched, its pulse was of much shorter duration than when it was statically fired (see Figs. 6a and 6b). The peak power for a given energy output is inversely proportional to the pulse duration. The \( Q \)-switched single pulse was approximately \( 40 \times 10^{-4} \) second long and the conventionally or statically fired pulse was approximately \( 200 \times 10^{-4} \) second long, a time ratio of about one to 5,000. For the same energy then, the power is 5,000 times greater with the \( Q \)-switched pulse. The effect of a static pulse on target is shown in Figs. 7a and 7b to be one of central penetration.
Fig. 7—Example of laser drilling in nickel. a) Hole of 0.0005-inch diameter produced by non-Q-switched laser in 0.003-inch thick nickel. Microscope is focussed at upper surface in order to determine shape of entrance hole and crater. Hole photographed with microscope using illumination from above and below specimen simultaneously, and b) Same as a) above except microscope focussed on lower surface of 0.003-inch thick nickel in order to determine shape of exit hole. (Upper and lower illumination).

Fig. 8—Hole of 0.0005-inch diameter produced in 0.003-inch thick nickel by Q-switched laser. Note the circular shape and absence of crater. (Illumination from above.)

Fig. 9—Example of laser drilling in nickel. a) Hole of 0.002-inch diameter produced by non-Q-switched laser in 0.002-inch thick nickel, upper illumination. (Pulse 50% larger than used for Fig. 6b); and b) Hole of 0.002-inch diameter produced by non-Q-switched laser in 0.002-inch thick nickel, upper illumination. (Pulse 50% shorter than used for Fig. 6b).

Fig. 10—Hole of 0.002-inch diameter mechanically drilled in 0.002-inch thick nickel. (Microscope illuminated from above.)

Fig. 11—Hole of 0.00048-inch diameter drilled in human hair of 0.0042-inch diameter. This was made with a non-Q-switched laser. The accuracy in hole location is seen by noting that the collimator cross hairs were placed at the coordinates of the desired hole center. The laser was then fired and the hole was found to be well centered at the cross hair intersection.

The effect leaving a molten crater edge (which quickly solidifies). However, when the shorter Q-switched pulse is used, the higher power causes a blasting effect and penetration is not accompanied by a crater nor any structural evidence of heating around the edge of the hole (see Fig. 8). This latter effect was observed on thicker targets while the former was observed on both the thin-film targets as well as on the thicker ones. The effect of pulse length on size is shown in Figs. 9a and 9b. For comparison, a hole drilled mechanically is shown in Fig. 10.

Some materials such as mu-metal and certain ferrites are altered structurally and magnetically by drilling with conventional drills or with electron beam boring devices. This unfortunate consequence of state-of-the-art drilling methods limits the application of these materials to magnetic cores for memories and transducers. A Q-switched laser, however, offers promise of drilling holes without disturbing the magnetic properties of the material.

**DETERMINATION OF DRILLING ACCURACY**

To designate a location for a hole and to pre-define its diameter, solutions to the following problems had to be developed:

1) the shape of the hole was not perfectly round in every case.
2) the shape of the hole was not repeatable in successive shots even when attempting to hold all parameters constant.

These problems were found to be caused by the changing distribution of energy in the cross section of the laser beam. Off-axis modes were developing which were different between successive shots. This effect was overcome by devising a mode selector as shown in Fig. 1.

The lens has at its focus an opaque disk with a small hole in its center; another lens, confocal with the first, also contains the small hole at its focus. The radiation from the laser is approximately parallel entering the selector and more nearly parallel leaving it. This device is inserted inside the oscillator cavity, i.e., the Fabry-Perot interferometer.

If an off-axis mode begins to build up within the oscillator, its rays will not come to focus at the center of the mode selector defining aperture. They will be focused at a point near or at the edge of the hole. The light thus obstructed will be attenuated and so oscillations are prevented from building up along this path. That path, with the greatest gain will be along the optical axis which contains the center of the mode selector aperture. Oscillations tend to build up to their final strength along the optic axis, encouraging the pure axial mode in the ruby.
The tendency to burn the edges of the defining aperture is minimized because the off-axis modes which can damage the aperture do not build up sufficiently in the system.

The defining aperture and its associated lenses were chosen to provide a beam of smaller angular divergence than that formed by the focusing lens (Fig. 1) and the unmasked hole diameter. When this condition was met, the holes were circular, and the holes were repeatable in diameter for given input conditions. An example of the accuracy obtainable is seen in Fig. 11—note that the hole is accurately centered in a human hair.

If the defining aperture in the mode selector is not circular, then, of course, the hole made in the target will not be circular. Square holes and long narrow slits have been ablated in sheet metal by placing appropriate masks in the system.

The shape of the defining mask is related to that of the hole by several factors:

1) The placement of the mask in the system.
2) The distribution of gain (hot filaments) in the ruby (ruby optical quality and pump configuration contribute).
3) The accuracy of system alignment.

A more convenient placement for the mask was found to be after, rather than within, the selector. The convenience in using a larger mask or spatial filter area is that the energy density is less than enough to destroy the mask. The spatial filter shape however is the approximate Fourier transform of the energy distribution desired in the target plane, and bears little resemblance to the hole shape desired.

In practice a determination of the mutual intensity function for quasimonochromatic coherent light falling on a transparent object (the desired hole) is made. A transparency is made from this set of determinations which has a pattern of areas of varying density. This plate may be made by hand if the values are known or it may be made photographically by Gabor's technique.

If the mask were placed at the defining aperture position, its shape would be that of the desired hole in the target.

The coordinates of the hole center can be predetermined to an accuracy of ±0.0001 inch by using a precision micro-manipulator to translate the target. The laser beam output direction—v — a well-aligned oscillator cavity with an appropriate mode selector—has an uncertainty of about this amount. Thus, excellent accuracy and repeatability are obtained.

**DRILLING OF THICK METAL TARGETS**

Targets of various thickness were drilled both by the static and Q-switched methods. The metal used was 301 stainless steel in thicknesses from 0.002 to 0.010 inch. The results are plotted in Fig. 12. A factor contributing to the non-linearity of the curve is that the hole is slightly tapered and the incremental volume per unit length of penetration decreases with depth (see Fig. 13). Another factor is that for deeper penetration, the beam evidently passes through a cloud of metal vapor and particles produced as penetration progresses. This may scatter and absorb some photons.

Refractory metals such as tungsten, molybdenum, and platinum were drilled, and, as might be expected, required more energy from static firing than less dense materials of the same thickness.

A striking effect, however, is the relative independence of material density or other characteristics on energy when the Q-switched pulse is used. Aluminum (3-mil thickness) required approximately the same energy to ablate a 1-mil diameter hole as did tungsten.

**VALIDITY OF DATA**

The measurements were taken indirectly, as follows:

1) The laser was fired with a given voltage applied to the capacitor bank and the energy measured with a T.R.G. Laserater (a ballistic thermopile).
2) The target was then inserted in the path and the laser was fired again. Care was taken to avoid variations in any parameter, especially the voltage applied to the capacitor bank. The target hole was measured and recorded.
3) Without any changes except target removal, the laser was fired again into the thermopile for energy measurement.

The energy measurement after drilling was compared to the one before drilling and, if any difference was detected, the data was discarded and a new series begun. The assumption made in these experiments was that the energy incident on the target while drilling was the same as that before and after drilling. The estimated errors were as follows:

1) The voltage applied to the capacitor bank determined the electrical energy applied to the pump. The energy $U$ is given by $U = \frac{1}{2} CE^2$, where $U$ is in joules, $C$ is in farads and $E$ is in volts. An error in $E$ is serious since the $E$ term is squared. This voltage was read to an estimated ±3%. To eliminate hysteresis the voltage was brought up slowly and stopped, always approaching the reading from the same direction. Flash lamp aging was also detected by this means. Sufficient time for thermal equilibrium was allowed between shots.
2) The capacity was known to ±10%.
3) The thermopile was estimated to be ±10% accurate.
4) The microvoltmeter was estimated to be ±5% (reading the thermopile).
5) The combined optical errors in reading diameter were better than ±2%.
6) The errors in reading the thickness of the metal targets were approximately ±0.0002 inch.

**CONCLUSIONS**

The energy versus hole diameter data were plotted for vacuum-deposited thin films and for various thicknesses of stainless steel. Refractory metals such as tungsten, molybdenum, and platinum were also drilled by a laser beam. The energy required for a 0.001-inch diameter hole in a given thickness of metal, using the Q-switched beam, was relatively independent of material. When a conventional long pulse (not Q-switched) beam was used, energy dependence on material was observed. A Q-switched beam produced a clean craterless hole while a beam of longer pulse duration produced a hole with irregular sides caused by the freezing of molten metal.

Repeatability of hole location and diameter was very good.

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Potentially, lasers are useful for remote probing of the atmosphere for meteorological purposes because of the very high power per unit bandwidth available and because of the light scattering properties of the atmosphere itself. Giant pulsed laser systems, some of which have been discussed in this issue, are available with powers of $10^9$ watts in a 20-ns to 40-ns pulse, beam half-angles of a few milliradians, and bandwidths of a few angstroms. These laser characteristics, in conjunction with the light scattering properties of the atmosphere, provide a basis for remote measurement of pressure, temperature, and humidity. Initially, a simple system is envisioned. It employs a q-spoiled ruby laser system for a transmitter. The receiver consists of a mirror in conjunction with a multiplier phototube and implemented with optical filters for appropriate frequency discrimination. Ranging is easily achieved because of the pulsed nature of the transmitter. Time gating of the multiplier phototube sets resolution volume.

A ccording to a theory established by Lord Rayleigh, visible light is scattered by the gaseous constituents of the atmosphere. The blue of the sky and the redness of sunsets are accounted for in Rayleigh's theory. Originally, the color of the sky was attributed to particles suspended in air. This view appears to have originated with Leonardo da Vinci. In 1873, J. C. Maxwell concluded from Lord Rayleigh's work that the air molecules themselves were the scattering particles. In 1899, Lord Rayleigh revived these ideas and formed the scattering theory which bears his name.

In 1923, Smekal, using primitive quantum considerations, discussed the effect of a light quantum of any frequency on atomic transitions, conserving the energy by means of light quanta. Stimulated by Smekal's work, Kramers and Heisenberg derived, first, the classical wave theory and, then, the quantum theoretical scattering formula. The latter investigation is far more important than the particular problem dealt with, since it provided considerable impetus to modern quantum theory.

For this paper, however, the work is important in that it stimulated the experimental studies of Raman and his coworkers, resulting in the verification of the presence of scattered radiation at a frequency different from the incident frequency (the so-called Raman effect). Raman scatter is significant in that it may allow unambiguous measurement of density and temperature with significant aerosol concentrations present.

According to Rayleigh's theory, the scattering intensity increases as the fourth power of the frequency; therefore, an increase of a factor of two in frequency causes an increase in the scattering intensity by a factor of 16. Assuming a plane wave of initial intensity $I_0$, the variation of intensity with distance traversed is given as:

$$I = I_0 \exp(\xi_{n}h)$$

where $h$ is the distance traversed and $\xi_{n}$ is linear extinction coefficient due to Rayleigh scattering. The formula for $\xi_{n}$, in terms of the optical refractive index of the medium traversed, is:

$$\xi_{n} = \frac{8\pi^2(n^2 - 1)^2}{3N\lambda^4}$$

where $n$ is the optical refractive index; $\lambda$ is the wavelength of the light; and $N$ is the number of molecules in a unit volume.

**Fig. 1—Vibrational-rotational energy level scheme.**
The linear extinction coefficient $\xi_e$ can also be expressed in terms of atomic properties:

$$\xi_e = \frac{8\pi^{3/2}N\alpha^3}{3e^2\lambda^4}$$

where $\alpha$ is the atomic polarizability and $\varepsilon$ is the dielectric constant of free space. This latter form of the linear extinction coefficient more clearly expresses the dependence of the scattering phenomenon on the number density of scattering centers.

**AEROSOL SCATTER**

One might expect to be able to monitor the Rayleigh return as a measure of gas density. However, recent measurements of nonresonant scatter, involving laser probing of the atmosphere above 10 km, have been made with ground-based lasers; back-scattered returns larger than the anticipated Rayleigh signal were encountered. These returns were attributed to a high aerosol background. (As indicated above, the particulate materials suspended in the atmosphere are effective in scattering radiation.)

Moreover, it is well known that in the lowest portions of the atmosphere the effective aerosol cross-sections can greatly exceed the non-resonant Rayleigh cross-sections. Thus, remotely probing the atmosphere with lasers using Rayleigh interaction at a nonresonant frequency to obtain meteorological information such as density profiles present significant problems. According to Elterman’s tables, the extinction due to aerosols exceeds that due to gaseous scatter by a factor of 5 at sea level for 0.4 micrometers, and by a factor of 94 for 0.7 micrometers. The Rayleigh and aerosol extinction coefficients are listed as a function of altitude in Table I.

In a classic work, Gerhard Mie solved the problem of the diffraction of a plane wave by a conducting sphere in a quite general manner. Unfortunately, these solutions are very complicated and are not susceptible to simple approximations in the range of parameters of meteorological interest. Thus, the light scattering studies of the real atmosphere (e.g., solar-radiative energy balances) are burdened with an extremely cumbersome theory. One offshoot of this difficulty is that a class of “computer experiments” has arisen in an attempt to find numerical shortcuts. Slowly, the study of this problem of aerosol scattering is yielding results; however, in measurement problems it promises to remain a “thorn in the side” to those interested in the light scattering properties of this atmosphere.

**RAMAN SCATTER**

Presumably, the aerosol scatter on hazy days is considerably larger than that given in Table I. Thus the aerosol scatter will almost always obscure the Rayleigh scatter; however, about 0.1% to 4% of the Rayleigh scatter is frequency-shifted by the Raman effect mentioned above. This effect is due primarily to the interaction of the photons with the vibrational and rotational levels of the atmospheric molecules. As a result, the molecule undergoes a change of state and the scattered photon is frequency shifted.

In principle, the molecular changes of state may be either electronic, vibrational, or rotational. In practice, most Raman spectra are either vibrational, rotational, or some combination of both. To cite a simple and useful example, the frequency-displaced scattered radiation from an $O_2$ molecule will undergo a Raman shift of 1,555 cm$^{-1}$ corresponding to a change from the $V_0=0$ to $V_1=1$ vibrational state. This is a somewhat broadened line ($\approx 100$ angstroms at room temperature) and under high resolution exhibits a rotational fine structure with lines a few angstroms apart. At an exciting line of 5,900 angstroms, the Stokes component of the vibrational Raman line would appear at 5,421.5 angstroms. Since this is greater than a 400-angstrom shift, filtering of the exciting line is a minor problem. To see most of the details of the rotational fine structure, a resolution of 1.5 angstroms would be required. The simplified energy-level diagram is shown in Fig. 1 and a repre-

---

**TABLE I—Comparison of the Linear Extinction Coefficients Arising From Rayleigh and Aerosol Scattering**

<table>
<thead>
<tr>
<th>$h$ (km)</th>
<th>Rayleigh Attenuation Coefficient (km$^{-1}$)</th>
<th>Aerosol Attenuation Coefficient (km$^{-1}$)</th>
</tr>
</thead>
<tbody>
<tr>
<td>0</td>
<td>$4.3 \times 10^{-6}$</td>
<td>$2.0 \times 10^{-1}$</td>
</tr>
<tr>
<td>1</td>
<td>$3.5 \times 10^{-7}$</td>
<td>$9.2 \times 10^{-1}$</td>
</tr>
<tr>
<td>2</td>
<td>$3.1 \times 10^{-8}$</td>
<td>$1.6 \times 10^{-1}$</td>
</tr>
<tr>
<td>3</td>
<td>$2.6 \times 10^{-9}$</td>
<td>$7.2 \times 10^{-1}$</td>
</tr>
<tr>
<td>4</td>
<td>$5.4 \times 10^{-11}$</td>
<td>$3.2 \times 10^{-1}$</td>
</tr>
<tr>
<td>5</td>
<td>$2.8 \times 10^{-11}$</td>
<td>$1.6 \times 10^{-1}$</td>
</tr>
<tr>
<td>10</td>
<td>$1.4 \times 10^{-11}$</td>
<td>$2.6 \times 10^{-1}$</td>
</tr>
<tr>
<td>15</td>
<td>$2.2 \times 10^{-11}$</td>
<td>$1.6 \times 10^{-1}$</td>
</tr>
<tr>
<td>20</td>
<td>$3.2 \times 10^{-11}$</td>
<td>$9.0 \times 10^{-1}$</td>
</tr>
<tr>
<td>30</td>
<td>$6.5 \times 10^{-11}$</td>
<td>$2.0 \times 10^{-1}$</td>
</tr>
</tbody>
</table>

Note: $\lambda = 0.4$

---

Fig. 2—Resolved rotational spectrum of $O_2$

Fig. 3—Satellite geometry.
Measurement problems

In any practical system the measurement error is important. Thus, it is of interest to consider some sources of error which will exist for almost any measurement system. Aside from the usual systematic errors which may not necessarily be easily overcome and which will not be fully determinable until working systems are built, there are certain sources of error which are pretty much inherent in the concept and about which some preliminary statements can be made.

An important consideration in dealing with low-level signals is the error due to the statistical nature of the photo-electronic process. For example, the average fractional deviation, because Poisson statistics are involved, is proportional to the reciprocal of the square root of the average number of electrons coming from the photocathode. To obtain an average deviation of 1%, some 10^9 photoelectrons are required, and for a quantum efficiency of 0.3, approximately 3 x 10^9 photons are necessary at the receiver. Therefore, at present power levels, resolution depths at the lower altitudes in the nonresonant scatter mode must be approximately 1 km.

Although aerosol scattering from the resolution volume is irrelevant when monitoring Raman scatter, it is of interest because of transmission losses. Only on very clear days is it possible to ignore the effects for vertical probing, and then probably only above 10 km. Most upper-atmospheric probing measurements to date suggest that only above 30 km can one safely ignore aerosol scatter most of the time. In actual measurements, the presence of aerosols should be made apparent by an anomalous change in scale height. Thus a radar-type A-scan return would have local maxima superimposed on the signal.

Because of the complexity of the scatter pattern from aerosols, an optimum technique for measuring extinction is far from obvious. There are certain
general features of aerosol scatter, however, which bear examination. To begin with, laser output can be made highly linearly polarized. Aerosols will depolarize to a much greater extent than molecules. Hence, the orthogonal component of polarization provides an index of the extent of aerosol scatter. In addition, with a laser mounted on a satellite a total atmospheric extinction coefficient measurement can be made by bouncing a signal from the earth's surface; this measurement will be somewhat uncertain, primarily because of the lack of knowledge of the surface reflection coefficient. If surface reflection were known, this along with the knowledge of differential backscatter could provide a further index, as long as the magnitude of the distribution does not change significantly with altitude.

To get some idea of the extent of the problem, consider the following equation:

\[ \frac{\Delta P_r}{P_{r_0}} = \frac{1}{4\pi^2 h} \int_{\Delta h} dr' \int_{t_1}^{t_2} \frac{i(r, \phi, v, m)}{n(r, h')} dr \]

where \( i(r, \phi, v, m) \) is the Mie intensity function; \( n(r, h') \) is the number density of aerosols as a function of particle size and altitude; \( r \) is the particle radius; \( \phi \) is the angle of scatter; \( v \) is the frequency of radiation; \( m \) is the particle refractive index; \( \Delta P_r \) is the power scattered from altitude interval \( \Delta h \); and \( P_{r_0} \) is the power transmitted to altitude \( h \).

System configuration

Much laser research and development bears a strong resemblance to early microwave communications work, and so future laser systems (communication and otherwise) may well take on the sophistication of present day radar systems. However, to permit reference to present-day systems of measurement, consider a very simple system consisting of a laser transmitter and photomultiplier receiver. Basically, such a system would consist of a ruby rod mounted in a reflecting cavity. The lasing levels in the rod are light pumped by flash lamps mounted in a reflecting cavity. For the so-called Q-spoiled mode, it is possible to employ a device whose optical transparency is controllable. This is mounted in the light beam between the mirrors. The element remains essentially opaque until the rod has been fully pumped. By prearrangement the Q-spoiling device is made transparent, allowing a highly collimated burst of radiation to flow through the end mirror which has been made reasonably transparent.

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Eq. 1 shows the increment per unit time of energy scattered by aerosols. Fig. 5 presents a less mathematical but somewhat clearer idea of the nature of this problem. The curve labelled \( Q \) is measured as the total scattering efficiency normalized to geometrical area as a function of normalized particle radius, for a typical set of parameters. The curve labelled \( \xi \) shows how the backward (\( \approx 180^\circ \)) to forward (\( \approx 0^\circ \)) scatter ratio changes for a given abscissa. Lastly, the curve labelled \( n \) shows a particle-size distribution of aerosols, characteristic of the lower altitudes. These curves are merely representative of the atmospheric aerosols and all three curves undergo variations as a function of space and time.

The changes in values of the parameters, along with the actual fluctuations known to occur in number density, cause considerable difficulty in approximating quantitative values of total aerosol scatter. In addition, recent work\(^b\) has brought out more clearly that natural particle distributions often occur in size groupings, contributing further to the complexity. Thus, direct assessment of the effects of aerosol scatter on transmissivity is not a simple matter. However, as the library of Mie coefficients increases to the point where the appropriate ranges of parameters as are found in the atmosphere are available, then backscatter at a number of frequencies could yield the differential aerosol scatter and give a precise measure of the transmission losses.

**RESONANT SCATTER**

For the upper atmosphere, and the much more highly rarefied constituents, resonance or quasi-resonance scattering is more appropriate. Molecular scattering is called resonant or non-resonant according to whether the transmitter frequency is near to, or far removed from, a resonant frequency of the molecule. It might be assumed that, if the laser frequency could be placed on a resonant line of one of the atmospheric molecules, the signal-to-noise ratio would increase due to the increased interaction cross-section. However, this is not entirely the case; the cross-section increases, giving rise to a significant increase in the backscatter from the region of interest, but the transmission path losses are also increasing. It is possible to make a quantitative estimate of an optimum cross-section.

One can assume that the atmospheric density is an exponential function of height, with regard to both the gaseous and particulate constituents. Then for satellite altitudes, an approximate expression for the ratio of transmitted to return power can be given as:

\[
P(r) = \exp \left( \frac{\alpha_r}{\gamma} \text{exp}(\gamma r) \frac{-\beta_n}{\delta} \text{exp}(\delta r) \right)
\]

where: \( P(r) \) is the power backscattered to the satellite from air volume at a distance \( r \); \( P_s \) is the incident power; \( r_s \) is the satellite altitude; \( \alpha \) is the Rayleigh cross-section; \( \gamma \) is the scale height of gas density; \( \beta \) is the effective aerosol cross-section; \( \delta \) is the scale height of aerosol number density; \( n_a \) is the exponential gas density at satellite altitude; \( N_a \) is the exponential aerosol density at satellite altitude.

Since, relatively speaking, appreciable interaction occurs only in the lower portions of the atmosphere, the specific assumption of the functional dependence of the gas and aerosol density with height in the upper altitudes is irrelevant, so long as it effectively indicates the absence of a measurable interaction at the upper altitudes.

It is possible to use Eq. 2 to estimate the magnitude of an optimum cross-section; Table II lists such cross-sections.

It is not surprising that the basic atmospheric scale properties help determine the optimum cross-section. The numbers in Table II suggest that it is not necessary to use a primary resonance of, say, \( O_3 \) or \( N_a \) in order to maximize return signal. This relaxes both the requirement that the laser line fall on the center of a primary resonance and the corresponding laser stability requirements. Note also the case for a rare gas such as \( O_2 \); here, the simplified calculations imply that primary resonance is necessary to optimize return power.

The above considerations with regard to resonance probing are rather simplified and ignore features which might be usefully exploited. For example, in probing a major constituent such as \( N_a \), the pressure broadening of the lines as a function of decreasing altitude might be utilized. Here the line width at the upper altitudes is less than that at the lower altitudes. Thus, a beam launched from a satellite at a frequency close to, but not right on, the center of a resonance line will suffer relatively smaller attenuations in the upper altitudes because of the narrowed line width. This process would allow one to get somewhat closer in frequency to the center of the resonance than the left-hand column in Table II suggests. In addition, in the course of line selection one would be required to examine the efficiency of production of fluorescence, since this in general represents a relatively broad-band return. Fluorescence would be harmful for remote probing but possibly useful for essentially in situ probing in the upper atmosphere.

**CONCLUSION**

The preceding suggestions have largely been made in terms of a satellite system; however, this is more in the nature of an ultimate goal. Present experimental plans are aimed at ground-based measurements. In fact, work is underway at the RCA Astro-Electronics Division to implement a ground-based system. Here first efforts will be devoted to determining the detailed engineering feasibility of monitoring the Raman radiation referred to above. Additionally, it might be pointed out that there are 10 or so facilities in the U.S. involving various aspects of ground-based lasers in which a variety of meteorological probeings are being made. It is by now trite to say that the laser is an answer looking for a problem. Analogously, such was the situation with traveling wave tubes at one time. As the associated component development proceeds there seems relatively little doubt that the laser will become a key component in a variety of systems. Based upon work to data, lasers systems for the sensing of meteorological state parameters seems to be a potentially fruitful application.

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LASERS AND HOLOGRAMS

Dennis Gabor, in one of his original papers on the subject, describes a hologram as a record which "contains the total information for reconstructing (an) object, which can be two-dimensional or three-dimensional". More specifically, a hologram is a recording of a standing-wave pattern formed by temporally coherent light from an object to be reproduced and from a reference source. When light from an identical reference source is incident on the developed record it gives rise to a diffracted wave identical in amplitude and phase distribution with the original wave from the object. Thus, with illumination from an appropriate reference beam, the object can either be photographed or be viewed directly by looking through the hologram.

Gabor demonstrated the feasibility of holography in 1948, using pinholes illuminated by filtered radiation from a mercury arc to obtain the required coherence. His primary objective was, however, to overcome the limitations imposed by spherical aberration on the resolution of the electron microscope. The procedure originally suggested by him was to place the specimen in front of a fine electron probe formed by electron lenses with their inherent aberration and to record an electron hologram on a plate placed at some distance from the specimen. This was then to be scaled up optically in the ratio of a light wavelength to the electron wavelength and to be illuminated by a reference source of light with the same aberration as the electron source, scaled up in the same proportion. The specimen, scaled up in the ratio of the wavelengths or by a factor of about 100,000, should then be visible through the hologram in a location corresponding to the original specimen position.

Efforts by Haine and Mulvey to exceed the resolution of the conventional electron microscope by a refined version of this technique were defeated by excessive demands on the coherence of the electron source and the stability of the entire system as well as difficulties in reconstruction. Attempts to utilize holography for x-ray microscopy by Baez and El Sum encountered even greater difficulties. However, the advent of the laser, providing light sources of extraordinary monochromaticity and coherence length, gave a new impulse to the field of holography. The introduction of a separate, oblique reference beam, and of diffuse illumination of the object (or diffuse scattering by the object) by Leith and Upatnieks were particularly important steps in extending the potentialities of holography.

The early work of Gabor was concerned entirely with plane holograms, i.e. records which could be regarded as planar sections through the standing-wave pattern. Three-dimensional holograms, formed in a recording medium, with depth large compared to the space periods of the recorded interference patterns have quite distinctive properties, as pointed out by Denisvuk and investigated in more detail by Van Heerden. It will be convenient to consider these two types of holograms separately.

PLANE HOLOGRAMS

Two simple ways of recording plane holograms and reconstructing images from them are illustrated in Figs. 1 and 2. In Fig. 1a, a parallel light beam derived from a laser falls partly on a diffusely reflecting object and partly on a mirror which directs it onto the hologram plate. Here the light scattered by the object interferes with the specularly reflected parallel reference beam, forming a latent image of the hologram pattern on the plate. If the plate is developed and the resulting hologram is illuminated by a parallel laser beam of the same wavelength, the beam is diffracted by the hologram pattern so as to form two images of the original object. The light diffracted in a direction with respect to the reference beam corresponding to that of the light from the object during recording forms the primary image, whereas light diffracted in the opposite direction forms the conjugate image. If the intensity of the light from the object is comparable to that of the reference beam at the hologram plate during recording, light distributions corresponding to higher-order diffractions by the hologram pattern may be observed in addition to the two images just mentioned.

With a parallel reference beam during recording and reconstruction, the primary image is virtual and the conjugate image is real. Furthermore, if the reference beam is incident in the same direction as during recording, the virtual image appears in the same position as the object with respect to the hologram plate, and, viewed through the hologram plate, is indistinguishable from the object in its full three-dimensional aspect (Fig. 1b). On the other hand, if the reference beam is incident from the opposite direction (i.e. if the effective source of the reference beam during reconstruction is a mirror image with respect to the hologram plane of that during recording) the conjugate image appears as a real, aberration-free, image in front of the hologram as shown in Fig. 1c. (Turning over the hologram, about an axis normal to the plane of the picture, and leaving the reference beam in its original position has the same effect, except that the real image appears upside down.) This image may be viewed against the hologram as a background. The remaining images—and both images for any other reference beam—are imperfect. Finally, a property which distinguishes the conjugate image from the primary image (and from the object) is that it is depth-inverted. Thus, in viewing the conjugate real image of an object, such as a human face, we see the illuminated surface from the inside. Gerritsen of RCA Labs and Rotz and Friesem have demonstrated that this depth inversion can be nullified.

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Final manuscript received July 11, 1966
by forming a second hologram with the depth-inverted real image formed by a first hologram as object and observing the conjugate real image formed by the conjugate primary virtual image. In practice, the center of the phase plate pattern (corresponding to \( \theta_1 = \alpha \)) is excluded since it would be impossible to view the object through this portion of the hologram without intercepting the direct light of the reference beam. Since for \(| \alpha - \theta_1 | \geq 5°\), \( D < 0.01 \text{ mm} \) the hologram structure is quite generally much too fine to be resolved by direct observation; for the sake of clarity only about every 10th line of maximum intensity is shown on the drawing.

The Fresnel hologram of a real object will consist of a complex superposition of many patterns of the type shown in Fig. 3c, all of them beyond the resolving power of the human eye. A well-prepared hologram appears thus simply as a uniformly fogged plate. However function satisfactorily as a hologram this plate must be capable of resolving separations equal to:

\[
D_{\text{min}} \approx \frac{\lambda}{(\sin \alpha - \sin \theta_j)_{\text{max}}}
\]

Fig. 3c shows that, for a Fresnel hologram, the spacing \( D_1 \), for any object point varies greatly over the hologram area. This is no longer the case if the object is translated to an infinite distance from the hologram by placing it in the focal plane of a lens interposed between the object and the hologram. The waves from any object point now become plane waves. The surfaces of path difference \( n d \) now are also planes and intersect the hologram plane in a series of parallel equally spaced lines. Such a hologram (Fig. 3a) is called a Fraunhofer hologram.

With a reference beam incident normally on the hologram plane, the orientation of the line pattern with sinusoidal intensity variation is given uniquely by the azimuth of the object point with respect to the z-axis and the spacing

\[
D_s = \frac{\lambda}{\sin \theta_j} \tan \theta_j = \frac{r_f}{f}
\]

by the distance \( r_f \) of the object point from the axis \( (f = \text{focal length of lens}) \). Thus the intensity of any one object point in a half plane is represented by the magnitude of a corresponding two-dimensional Fourier component of the intensity at the hologram plate and the hologram pattern is a Fourier transform of the object pattern.

Very nearly the same situation exists for an object a finite distance from the hologram plane, provided that the reference beam diverges from a point in the plane of the object (Fig. 3b). The surfaces of constant path difference \( n d \) are now hyperboloids of revolution with the object point and the reference source as the two foci. The intersections with the hologram plane are hyperbolic arcs which are closely approximated by equispaced parallel lines. This follows from the fact that the difference in the angle of incidence on the hologram plate from the object point and the reference source is very nearly constant. Holograms prepared with the reference source in the object plane are hence commonly called Fourier-transform holograms.

Fourier-transform holograms possess the advantage that, for them, the interference pattern over the entire hologram is essentially the same and that, for a given image field, separation between the reference beam and the image beam can be achieved with the largest minimum spacing or least resolution capability of the hologram plate. This is obtained with the reference source at the edge of the image field (Fig. 2a). The primary and conjugate images are now obtained in the same plane—an aberration-free primary virtual image in the location of the object when the reference beam during reconstruction is identical with that during recording (Fig. 2b), an aberration-free conjugate real image, when the reference beam during reconstruction converges toward the mirror image of the source used in recording (Fig. 2c)

If a reference beam is employed for reconstruction which has the same angle of incidence at the center of the hologram, but a different point of convergence, magnified or reduced images are obtained, which are free of distortion but not stigmatic (Fig. 2d). It may be shown that for very large magnification the maximum number of lines in the image which can be resolved corresponds approximately to \((z_1/\lambda)\)" where \( z_1 \) is the object distance. Thus, by choosing this distance large enough, holography may be employed for high-quality lensless microscopy.

Since for a hologram prepared with a diffusely reflecting or diffusely illuminated object any portion is similar to any other, the complete image can be reproduced with any part of the hologram; the resolution is merely reduced in accord with the laws of diffraction which tell us that the least resolved distance in the image formed by a beam limited by a square aperture of side \( a \) is:

\[
d_{\text{min}} = \frac{z \lambda}{a}
\]

where \( z \) is the image distance, which is equal to the object distance for an aberration-free hologram image. Similarly,
damage to the hologram merely reduces the contrast of the image slightly, having an effect similar to inflicting similar damage to the surface of a lens of the same size forming a similar image. (For certain types of hologram damage, the effect is actually less than for a lens because of the off-axis incidence of the reference beam.)

At the same time any diffusely reflecting surface illuminated by coherent (laser) light exhibits "speckle", i.e. random brightness variations resulting from the interference of the diffusely scattered waves. This speckle is of course transferred to the image of a diffusely reflecting object formed by a hologram. The effective dimensions of the speckle grain are determined by the aperture of the imaging system and are comparable to the limit of resolution of the system. Thus, for direct observation, where the pupil of the eye defines the resolution, speckle is invariably prominent. On the other hand, if the image is recorded, speckle becomes insignificant if the hologram is chosen large enough that the effective speckle grain is smaller than the limit of resolution of the recording medium.

For an object in the form of a transparency speckle can be avoided by illuminating the transparency directly with an undiffused laser beam, as illustrated in Fig. 4. With a hologram prepared in this manner it is not possible to view the image directly, since the pupil of the eye limits the area of the image observed at any one time. Furthermore, the hologram does not possess the desirable property of redundancy, since it is in essence a shadow projection with edge diffraction fringes of the object. Accordingly dust and scratches on a transparency hologram severely affect the reproduced image.

It is of interest to compare the number of picture elements in an image which can be stored in a hologram with that which might be stored by recording the image on the hologram plate directly. Consider a square hologram with side $a$ and a square image field with side $b$. If $\theta_p$ is the angle subtended by half the image side, we have (for small $\theta_p$)

$$b = 2a \sin \theta_p \tag{5}$$

For a Fourier-transform hologram with the reference source placed at the center of an edge of the image field we find in correspondence with Eq. 2:

$$D_{\text{max}} = \frac{\lambda}{\sqrt{5} \sin \theta_p} \tag{6}$$

The total number of picture elements which can be recorded on a hologram plate with a limiting resolution $D_{\text{max}}$.
by direct photography of the object is given by:

\[ N_p = \left( \frac{a}{D_{\text{min}}} \right)^2 \]  

(7)

where \( d_{\text{min}} \) is given by Eq. 4. Together, Eqs. 4 to 8 yield:

\[ \frac{N_h}{N_p} = \frac{4}{5} \]  

(9)

This would make it appear that the number of picture elements which can be recorded on a hologram is practically equal to that which can be recorded directly on a plate of the same size and resolution. It should be noted however, that the effect of the limiting resolution of the plate is quite different with direct photography and holography. In direct photography detail contrast is reduced over the entire picture area in proportion with the sine wave response \( k(d) \), where \( d \) is the period of the Fourier component of the image detail considered and, approximately:

\[ k(d) = \frac{1}{1 + (d/d_0)^2} \]  

(10)

The term \( d_0 \) is characteristic of the emulsion and its development and is, in typical examples, about twice as large as the limiting resolution.

With the hologram, the sine-wave response of the plate has no direct effect on the detail contrast of the image. Instead, the image itself is reduced in intensity in proportion to \( [k(D_0)]^2 \). Since \( D_0 \) decreases, in accord with Eq. 1, as the angular separation between the reference source and the image point increases, the portions of the image farthest from the reference source may become much fainter than those closer to the reference source. Thus, for reasonable uniformity of the brightness of the image, \( D_{\text{min}} \), should certainly not be less than \( d_0 \) or twice the limiting resolution of the hologram plate. Taking this into account,

\[ \frac{N_h}{N_p} = \frac{1}{5} \]  

(11)

may be a more adequate ratio of the number of picture elements which can be stored in the hologram to that which can be stored by direct recording on the hologram plate. Increasing the hologram size to overcome the effect of speckle noise would lead to a still less favorable factor in picture element storage efficiency. However, speckle noise is not inherent in the hologram process.

Some additional properties of the hologram which merit consideration are its ability to reproduce images of tremendous dynamic range with a medium with small photographic latitude, its capacity to store the three-dimensional aspect of any object in a plane, and the possibility of storing numerous images in superposition.

The first property becomes obvious when we consider an object consisting of a single luminous point. While, in this case, the intensity variation in the hologram plane may amount to only a few percent, corresponding to the modulation amplitude of the interference pattern, all of the diffracted light for one order may be concentrated into the diffracted light for one order may be concentrated into the diffraction disk corresponding to the object point. Under these circumstances a dynamic range of the order of 100 dB is entirely within reason.

The viewing of an object over a large solid angle with the aid of a hologram requires a hologram of large size. If the object (or image) is located at the normal viewing distance of 250 mm from the object, seeing the object with normal visual resolution from a single vantage point requires a hologram approximately a pupillar diameter (\( d_p \approx 1 \text{ mm} \)) in size. If the object is to be viewed over a cone of half angle \( \alpha \) (Fig. 5) through a spherical hologram, the hologram area must be increased by a factor:

\[ F = \frac{2\pi (1 - \cos\alpha)}{\pi/2} d_p^2 = 5 \times 10^8 (1 - \cos\alpha) \]  

(12)
For $\omega = 30^\circ$ this is the order of $7 \times 10^4$. If the hologram information were to be transmitted electrically the bandwidth required to transmit the indicated three-dimensional information would have to be $7 \times 10^4$ times greater than that needed for transmitting the 1-mm-diameter hologram.

A number of pictures can be stored in superposition on a plane hologram by varying the direction of the reference beam of the recording wavelength. These possibilities are however quite limited if mutual interference between pictures is to be avoided. Since three-dimensional holograms possess great advantages in this respect, multiple picture storage will be discussed in connection with them.

However we must still consider the conditions which must be fulfilled in the recording of holograms and image reconstruction. Holograms may be either absorption or phase holograms, just as diffraction gratings may be either absorption or phase gratings. In an absorption hologram, variations in intensity in the interference patterns at the hologram plate are translated into variations in absorption by the plate, while in phase holograms variations of intensity are translated into variation in refractive index or thickness of a transparent medium.

The standard material for forming an absorption hologram is a fine-grained photographic plate, such as the Kodak High-Resolution Plate or the comparable red-sensitized Kodak Spectroscopic Plate, Type 649-F. Such plates have a limiting resolution which is better than 2,000 line pairs per millimeter and probably about 3,000 line pairs per millimeter. Putting $D_{\min} = d_e$ equal to twice the least resolvable separation and $\lambda = 6,328$ angstroms (corresponding to a helium-neon laser) in Eq. 6 leads to permissible field angles $2\theta_e$ of $50^\circ$. Holograms with even greater field angles have been made successfully. The exposure required to record a 4x5 in$^2$ hologram on a Kodak 649-F plate with a 10-milliwatt helium-neon cw laser is of the order of a minute. With an argon laser emitting in range from 4,579 to 5,145 angstroms, the exposure may be reduced by an order of magnitude or more.

If the silver grain is bleached out of an absorption hologram a phase hologram is obtained. The optical path variations result here in part from internal variations in refractive index, in part from residual undulations of the surface which correspond to the internal developed image. Deposition of a thin reflecting layer on the surface thus results in a special type of phase hologram—a reflection or mirror hologram—for which the reconstructed images are mirror-reversed.
(Fig. 6). High-quality phase holograms with pattern spacings \( D \), in the range from 1/200 to 1/1000 mm have also been prepared with thermoplastic-film photoconductor sandwiches which possess the advantage of very low random light scattering. Their sensitivity and resolution capability is intermediate between that of special high-resolution plates and the more conventional photographic materials. Photoresist has also been shown to be useful for the preparation of phase holograms. (Private communication by F. Letton and H. J. Gerritsen of RCA Labs.)

Phase holograms have the basic advantage over absorption holograms that they are capable of directing a larger fraction of the light of the reference beam into the desired image; in typical instances this fraction has been found to be about 4% for phase holograms and less than 1% for absorption holograms (according to measurements by D. Greenaway) in good accord with the ratio 5.4 between the maximum values of these fractions for a sinusoidal phase grating and sinusoidal absorption grating.

The nature of the hologram places stringent requirements on the conditions of recording. Plate, object, and reference source should not move with respect to each other in the course of an exposure by more than a fraction of a wavelength to prevent washing out of the fine-grained hologram pattern. Thus the recording of objects in motion requires the use of Q-switched lasers, which can provide enough power for an exposure in a single pulse much less than a microsecond in length. If a light source other than a laser were to be employed, the source size would have to be less than half an interference-pattern spacing \( D \), in size. The requirement for source monochromaticity is also stringent, since the maximum path difference \( d \) between interfering rays must certainly vary by less than a half wavelength. This leads to:

\[
d = \frac{\lambda}{2} \frac{1}{\Delta \lambda}
\]  

Thus, even if the maximum path difference between the interfering rays is only 1 cm, the fractional wavelength-spread of the source should not exceed \( \Delta \lambda / \lambda = 3 \times 10^{-4} \).

The requirements on the size and monochromaticity of the reference source and on mechanical stability during reconstruction are much more easily satisfied. The maximum permissible source size (or the permissible mechanical displacement) corresponds simply to the maximum resolution demanded in the image. Thus the ratio of the angle subtended by the source at the hologram to that subtended by the picture diameter must be less than the reciprocal of the number of picture elements resolved along a picture diameter (i.e. the reciprocal line number \( 1/n \)). Similarly, since the diffraction angle for the image rays is proportional to the wavelength, we must demand:

\[
\frac{\Delta \lambda}{\lambda} < \frac{1}{n}
\]  

For a picture with television resolution \( (n = 500) \) this can be realized readily with continuous sources and an interference filter or gaseous discharge sources with suitable line filters. However, a laser provides the required high brightness and small source size most conveniently.

### THREE-DIMENSIONAL HOLOGRAMS

The distinctive feature of three-dimensional holograms, as compared with plane holograms, is that one and only one image is formed for discrete directions of incidence uniquely related to the wavelength of the incident beam. Thus, if a hologram of an object is formed in precisely the same manner as a plane hologram, with the sole distinction that the hologram medium is very thick in comparison with the wavelength of light, a perfect three-dimensional virtual image is obtained in the position of the original object if the reference beam during reconstruction is identical with the reference beam during recording and a perfect (depth-inverted) three-dimensional real image is formed in the position of the object if the reference beam is simply reversed in direction (Fig. 7). Let us, for the sake of simplicity, consider a Fraunhofer hologram, in which the interfering object and reference waves are plane waves and the surfaces of maximum intensity are consequently a family of equipaced planes. Light will be diffracted by such a system only if, simultaneously, the following two conditions are fulfilled: light scattered by points in any one plane is in phase in the direction of diffraction, corresponding to the condition of reflection at the plane; and light reflected by successive planes is in phase, corresponding to the Bragg condition familiar from the diffraction of x-rays by crystals. These two conditions can be combined in a single vector equation:

\[
e_o - e'_o = (\lambda' / \lambda) (e_r - e_e) = 0
\]

Here, \( e_o \) is the unit vector in the direction of propagation of the diffracted wave, \( e'_o \) that for the reference wave during reconstruction, \( e_r \) that for the object wave, and \( e_e \) that for the reference wave during recording. The \( \lambda' \) and \( \lambda \) are the wavelengths of the radiation used in reconstruction and recording, respectively. Eq. 15 demands that the four vectors in question form a closed (generally three-dimensional) quadrangle. Furthermore, if an extended image is to be reproduced, the condition of Eq. 15 must be preserved (for fixed \( e_o \) and \( e'_o \)).
when \( e_0 \) is varied over a two-dimensional angular range.

This condition can be satisfied only if \( \lambda' = \lambda \) and the reference beams during reconstruction and recording have the same or opposite directions (Fig. 8a), in which case the diffracted waves also have the same or opposite directions, respectively, as the object waves. If the directions of the diffracted wave and reference wave during reconstruction are interchanged (Fig. 8b), closure can be realized only for a limited (linear) range of directions of \( e_\nu \), corresponding to a rotation of the vector pair \( (e_\nu, \pm e_\nu) \) around the fixed endpoints of the vector pair \((-e_\nu, \pm e_\nu)\). A similar condition prevails if the wavelength is changed around the fixed endpoints of the vector \( e_\nu \) of directions of the hologram thickness (assuming this prevails if the wavelength is changed by amounts exceeding the indicated maximal departures of the hologram orientation and in wavelength—i.e., departures from the exact fulfillment of Eq. 15—which lead to appreciable image intensity as inversely proportional to the hologram thickness (assuming this to be small compared to the lateral extent of the hologram). These departures (and the corresponding image displacements) are plotted as function of the angle of incidence of the reference beam in Figs. 9 and 10. If different images are recorded successively in a three-dimensional hologram medium with reference beams differing in angular orientation or wavelength by amounts exceeding the indicated maximal departures, they can be read out separately, without appreciable mutual interference, by changing the direction of incidence or wavelength of the reference beam used in reconstruction so as to correspond to the values used in recording the successive images. The maximum total number of pictures which can thus be stored in the three-dimensional hologram can be shown to be of the order of \( c^3 \lambda \), where \( c \) is the hologram thickness; van Heerden has shown, furthermore, that the total number of picture elements which can be stored in a three-dimensional hologram is equal to the ratio of the hologram volume to \( \lambda^2 \).

It should be noted that, for large angles of incidence of the reference beam, even the extra-thin photographic emulsions used for high resolution work must be regarded as thick; their thickness is commonly of the order of 4 micrometers. Consequently either the conjugate or the primary image—more generally, the off-axis image in Fig. 1—is partly suppressed. Pennington and Lin have furthermore made use of the great wavelength sensitivity of a hologram prepared with a reference beam and object beam incident on opposite sides of the emulsion \( (\theta_\text{obj} > 90^\circ) \) in Fig. 10) to reconstruct two-color images in white light. For this purpose the combined beams from a (red) helium-neon laser and a (blue) argon laser were used as reference beam and for illuminating a color transparency during recording. During reconstruction, the two superposed recorded hologram patterns select narrow wavelength bands centered about the helium-neon laser wavelength and the argon laser wavelength from the white reference beam to form the component red and blue images.

Apart from thick photographic emulsions, which pose special problems with respect to shrinkage and development in depth, alkali halide crystals colored with \( P \)-centers and photochromic glasses have been considered suitable for recording three-dimensional holograms.

**APPLICATONS**

Holography makes possible the compact storage of pictorial information in a form largely immune to physical damage. Its ability to reconstruct the true three-dimensional aspect of an object has been utilized for measuring the instantaneous particle distribution in an aerosol recorded by the pulse of a Q-switched laser. The great sensitivity of the stored pattern to minute object displacements can be used to advantage to measure displacements of fractions of a wavelength on surfaces of arbitrary contour.

**REFERENCES**

COMPONENT PROBLEMS IN A MICROWAVE DEEP-SPACE COMMUNICATION SYSTEM

The problems associated with the development of a microwave data link system for deep-space communication are examined. Factors such as phase and frequency stability, transmitter power, low-noise receivers, and antenna systems are discussed. A system having a 10^6-bit-per-second communication rate is considered feasible within 10 years.

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This paper describes a program of research in the area of microwave technology directed toward the requirements of future deep-space communication systems. The discussion is limited largely to the spacecraft-to-Earth data link. Other communications links important to future missions include the Earth-to-spacecraft command link, spacecraft-to-probe or lander command links, return data links, and, in some systems, a link between the spacecraft and an Earth-orbiting satellite.

A deep-space communications system block diagram (Fig. 1) shows the parts of the system considered as the microwave problem. These include the spacecraft-mounted RF power amplifier with its prime power source, cooling load, and transmitting antenna; the propagation medium, consisting of solar and Earth atmospheres, linking the spacecraft with the Earth receiving terminal; and the Earth-based receiving antenna and low-noise receivers.

THE MICROWAVE PROBLEM

It is convenient to consider a microwave index of performance $M$ for a communications link which effectively relates the communications mission and system requirements to the performance of the microwave components. The performance index is the product of the effective radiated power in watts at the transmitter and the ratio of receiver aperture area to system noise temperature.

The microwave performance index derived in Fig. 2 is simply a rearrangement of terms in the communications range equation which equates the microwave performance factors to the requirements of the communications mission. The magnitude of the microwave performance index is determined largely by the communication range, by the data rate and error probability, and, to a lesser extent, by the information-coding techniques employed. The quality of microwave system performance required in terms of coherence and stability also is determined by these factors. Values of the microwave performance index $M$ are given in Table I for three accomplished missions, for one that is planned, and for two that indicate the requirements for future performance capabilities. The performance index listed for future missions represents a data rate of $10^6$ bits per second for a Mars mission. This is about five orders of magnitude above the performance of the Mariner IV program.

The values of the microwave performance factors, plotted in Fig. 3 as a function of time, illustrate the growth trend of the performance factors. Note that the performance index increases by about 20 dB for each 5 years of research and development effort.

PHASE AND FREQUENCY STABILITY REQUIREMENTS

Before considering the means of achieving greater powers and gains in the microwave subsystem, it is important to determine the effect of signal frequency stability on data rate. An analysis of a frequency-shift-keyed (FSK) system shows (Fig. 4) that for a high-data-rate system, where the ratio of frequency instability to data rate is small, there is less than 1 dB difference in performance between coherent and noncoherent systems. As this ratio becomes large (say 1000-1) and the predetection signal-to-noise ratio is below the detector threshold, a coherent system produces significa-

![Fig. 1—Block diagram of typical microwave deep-space communications system.](image)

**TABLE I—Typical Values of Microwave Performance Index**

<table>
<thead>
<tr>
<th>Program</th>
<th>$M$ (dB)</th>
<th>$P_t$ (Watts)</th>
<th>$G_t$ (db)</th>
<th>$A_r$ (dB)</th>
<th>$T_s$ (°K)</th>
<th>$f$ (MHz)</th>
</tr>
</thead>
<tbody>
<tr>
<td>1959 Pioneer IV</td>
<td>-10.2</td>
<td>0.27</td>
<td>-6.7</td>
<td>2.1</td>
<td>200</td>
<td>24.6</td>
</tr>
<tr>
<td>1962 Mariner II</td>
<td>+24</td>
<td>3</td>
<td>4.8</td>
<td>19</td>
<td>200</td>
<td>24.6</td>
</tr>
<tr>
<td>1965 Mariner IV</td>
<td>+42</td>
<td>10</td>
<td>10</td>
<td>24</td>
<td>290</td>
<td>24.6</td>
</tr>
<tr>
<td>1971 Voyager</td>
<td>50</td>
<td>10</td>
<td>10</td>
<td>45</td>
<td>61,000</td>
<td>40</td>
</tr>
<tr>
<td>Future</td>
<td>50</td>
<td>100</td>
<td>20</td>
<td>40</td>
<td>20,000</td>
<td>43</td>
</tr>
</tbody>
</table>

![Fig. 2—Microwave performance index.](image)
significantly higher data rates than those of a noncoherent system.

State-of-the-art frequency stability is adequate for high-data-rate noncoherent systems. However, for low-data-rate coherent systems, frequency stability should be improved to reduce frequency acquisition time and to reduce doppler noise for orbit tracking purposes. At the same time, very low values of phase jitter (less than 15° RMS) are required for a high probability of maintaining phase lock over long periods of time (Fig. 5). The RMS phase noise given by note 3 of Fig. 5 is 14° for a carrier-to-noise ratio of 9 dB in a 3-Hz (cps) bandwidth. Phase noise contributed by the transmitter and by antenna and atmospheric fluctuation must be added to this. The goal of research in this area is to achieve frequency stability better than 1 part in 10^10 and phase-locked loop bandwidths of less than 1 Hz.

**TRANSMITTER POWER**

There are presently available RF power sources in the 100- to 1000-watt range throughout the microwave region from 1 to 100 GHz (Gc/s). Traveling-wave tubes (RCA A-1318) delivering about 45 watts of power at 40% efficiency at about 2 GHz are presently available as space-qualified components. A space-qualified tube delivering 100 watts at 50% efficiency should be available in 1970. Efficiencies as high as 57% have been demonstrated in the laboratory.

Fig. 6 represents the state of the art in power sources in 1965. The power levels shown can presently be achieved without regard to efficiency or special packaging requirements necessary for space environment. The projected performance of transistors is based upon the present trend in doubling the available power for each year of research and development effort.

Spacecraft transmitter power is limited by the weight of the prime power source. The efficiency of the final amplifier is important not only because of prime power limitations but also because of limitations imposed by the spacecraft cooling system. It is nearly as expensive to eliminate waste power (heat) as it is to provide prime power. Prime power limitations on missions to the outer planets will dictate low transmitter powers where solar sources are used. The solar radiation intensity at Saturn orbit is about 20 dB below that at Earth orbit. However, the use of SNAP power sources, possibly for electrical propulsion, will make high-power spacecraft transmitters much more attractive.

The goal of research for spacecraft transmitters is not to increase the amount
of RF power but rather to improve the quality of transmitter power. Frequency stability and phase coherence of the transmitters must be improved, particularly for relatively low data-rate missions to the outer planets; tube efficiencies must also be improved. Such techniques as beam focusing and the use of tapered helixes and multiple collectors may be used. Solid-state amplifiers should be integrated with the solar cells, antenna, and cooling structures to improve the overall efficiency of the system and minimize the weight of these components.

**LOW-NOISE RECEIVERS**

The present state of the art for low-noise receivers is depicted in Table II. (In Table II and Fig. 7, bath temperature refers to the ambient temperature at the maser.) Maser amplifiers with an effective noise temperature of 8°K are presently available for ground terminal use, and traveling-wave masers with noise temperatures of less than 4°K are under development. These temperatures are already on the order of the temperature contributed by the antenna due to atmospheric and external noise; hence, further reduction in receiver temperature will do little to increase the microwave index of performance.

The use of multi-aperture receiving arrays will require many low-noise receivers at each station. The cost and performance of this component will have a major impact on the design of the receiving antenna, determining in part the number of subapertures in the required total aperture and hence their size. The important characteristics of the receiver in this application, other than temperature, will be cost, reliability, and maintainability. The size, weight, and power demand of the device will become as important for the ground terminal as for the space terminal.

The noise temperature of the traveling-wave maser is limited by the inversion ratio in present material and by the unfavorable gain-loss ratio at elevated temperatures. Basic research in materials, slow-wave structures, and optimum heat stationary techniques should extend the maser art toward higher operating temperatures with small reduction in performance (Fig. 7). The need for maser operation at higher operating temperatures is shown in Fig. 8. It appears that operating temperatures between 16° and 20°K will be the optimum choice, considering the weight and power required for the refrigeration system.

The goal of research in this component should be directed toward improved maser materials and fabrication techniques as well as improved techniques.
The principal constraints on the gain of the spacecraft transmitting antenna are the spacecraft transmitting antenna and surface tolerance. The pointing accuracy can be reckoned in terms of the system. More efficient and lighter weight closed-cycle cryogenic equipment will be required as well as more efficient RF pump sources.

**TRANSMITTING ANTENNA GAIN**

The principal constraints on the gain of the spacecraft transmitting antenna are pointing accuracy and surface tolerance. Pointing accuracy can be reckoned in pounds of control power, and surface tolerance in antenna structure weight. The loss in antenna gain due to pointing error is shown in Fig. 9. To limit gain loss due to pointing error to about 0.12 dB, the antenna beamwidth at the 3-dB points should be about 10 times the pointing accuracy of the antenna structure. A pointing accuracy of 1° (Mariner IV) will support an antenna beamwidth of 10° or a gain of about 24 dB.

![Graph showing antenna gain limits](image)

**TABLE II—Traveling-Wave Masers Operating at 4.2 K Bath Temperatures—Presently Available or Under Development**

<table>
<thead>
<tr>
<th>Freq Range (MHz)</th>
<th>Gain (dB)</th>
<th>Bandwidth (MHz)</th>
<th>Noise Temp (°K)</th>
<th>Packaging</th>
<th>Use</th>
<th>Comments</th>
</tr>
</thead>
<tbody>
<tr>
<td>2.0-3.0</td>
<td>25</td>
<td>5</td>
<td>10</td>
<td>Closed-Cycle refrigerator</td>
<td>Classified</td>
<td>Superconducting (SC) magnet center for operation 3000 ft from antenna</td>
</tr>
<tr>
<td>2.3-2.4</td>
<td>30</td>
<td>12</td>
<td>8</td>
<td>Dewar</td>
<td>Laboratory</td>
<td>For NASA</td>
</tr>
<tr>
<td>3.1-3.2</td>
<td>35</td>
<td>50</td>
<td>8</td>
<td>Dewar</td>
<td>Radioneter</td>
<td>Antenna-mounted for 150-ft dish developed for National Research Council of Canada</td>
</tr>
<tr>
<td>3.0-4.5</td>
<td>30</td>
<td>30</td>
<td>10</td>
<td>Closed-Cycle refrigerator</td>
<td>Classified</td>
<td>SC magnet—new refrigerator with 8000 hours MTBF, 3-channel maser; common SC magnet and pump</td>
</tr>
<tr>
<td>4.5-6.2</td>
<td>30</td>
<td>30</td>
<td>10</td>
<td>Closed-Cycle refrigerator</td>
<td>Classified</td>
<td></td>
</tr>
<tr>
<td>4.125</td>
<td>30</td>
<td>150</td>
<td>8</td>
<td>Closed-Cycle refrigerator</td>
<td>Classified</td>
<td></td>
</tr>
<tr>
<td>5.4-5.9</td>
<td>30</td>
<td>15</td>
<td>10</td>
<td>Dewar and Monopulse radar</td>
<td>Radioneter</td>
<td>For National Bureau of Standards ultra-stability gain ± 0.001 dB</td>
</tr>
<tr>
<td>9.0-11.0</td>
<td>30</td>
<td>20</td>
<td>12</td>
<td>Dewar</td>
<td>Radioneter</td>
<td>For NBS ultra-stability gain ± 0.001 dB</td>
</tr>
<tr>
<td>11.0-12.0</td>
<td>30</td>
<td>20</td>
<td>12</td>
<td>Dewar</td>
<td>Radioneter</td>
<td>For NBS ultra-stability gain ± 0.001 dB</td>
</tr>
<tr>
<td>22.0-37.0</td>
<td>30</td>
<td>20</td>
<td>Less than 20</td>
<td>Dewar</td>
<td>Radioneter</td>
<td></td>
</tr>
</tbody>
</table>

To minimize the acquisition problem introduced by the use of a high-gain antenna on the spacecraft, the antenna beamwidth should be of the same order as the mechanical stabilization. With RF sensing for accurate antenna pointing, a transmitting antenna beamwidth of 1° with about 44 dB gain can be achieved. Because of the limitations imposed by pointing accuracy and acquisition, the transmitting antenna will be beamwidth limited and hence gain limited. Its diameter will be about two orders of magnitude less than that of the receiver, and its surface accuracy will be nearly equal to that of the receiver. The relative surface tolerance (σ/D) required for this antenna will therefore be about two orders of magnitude larger than that of the receiver and should not limit the design.

The goal of research in spacecraft antennas should be the development of a very lightweight antenna taking advantage of the relatively large surface tolerance. Both RF sensing and antenna beam-positioning techniques must be developed to handle beamwidths in the order of 1° or less. Single-channel RF error-sensing techniques should be developed to eliminate the need for additional receiver channels for the sensing function. In addition, techniques for integrating the transmitting antenna, RF power source, prime power source, and cooling structure should be developed to improve overall reliability and reduce the combined weight of these components.

**GROUND ANTENNA SYSTEM**

Finite weight and power limitations on the spacecraft make it necessary to obtain a large part of the increased performance in the communication link at the Earth terminal. This conclusion is also supported by the multiple use of these facilities, which permits cost sharing among many missions. The 210-foot reflector presently being installed at the Deep Space Instrumentation Facility (DSIF), Goldstone Lake, Calif., represents nearly an order of magnitude increase in receiver aperture over the 85-foot reflector used for the Mariner IV mission. Future missions will require an increase of at least another order of magnitude in effective receiver aperture. Disappointing results with reflectors of this size in the past suggests that a new approach is required.

The maximum gain of an antenna is determined by its relative surface tolerance (σ/D), the ratio of surface tolerance to antenna diameter (Fig. 10). A tenfold increase in effective area implies a threefold to fourfold decrease in relative surface tolerance expressed as the...
ratio of rms surface tolerance to antenna diameter ($\sigma/D$). A $\sigma/D$ value of 10° represents the 210-foot reflector and is consistent with a maximum gain of about 62 dB. A relative reflector tolerance of 1.7 $\times$ $10^{-11}$ has been achieved by MIT Lincoln Labs on their 120-foot Haystack antenna inside a radome. The new 140-foot radio telescope for the National Radio Astronomy Observatory at Greenbank, W. Va., has a relative surface tolerance of 2.2 $\times$ $10^{-10}$, achieved without radome protection. Thus single reflectors (using mechanical collimation) of the requisite accuracy can be built with diameters up to about 150 feet. For much larger aperture areas, electronic collimation must be used.

To determine the optimum frequency for the telecommunications system, careful attention must be given to the factors that limit the gain or effective area of the antenna. As an example consider a diameter of 50 feet as a practical aperture limit for future deep-space vehicles, and a diameter of about 700 feet as a limit for the ground-based aperture. Conversely we can assume that the spacecraft antenna beamwidth is limited to about 1° by stabilization requirements and the Earth antenna beamwidth is limited to about 1 arc minute by atmospheric fluctuation. The antenna gain as a function of frequency subject to these constraints is shown in Fig. 11.

The overall performance of the microwave portion of a deep-space communications system using antennas constrained as indicated above is shown as a function of frequency in Fig. 12. In this figure the frequency dependence of atmospheric loss and noise temperature has been included with that of antenna gain and receiver cross-section. Note that the microwave index of performance has a rather broad maximum between 1 and 10 GHz. With a little rain, however, the upper frequencies are rapidly attenuated. Thus the present NASA communications band is expected to see continued use into the foreseeable future.

Multiple apertures have been proposed whose collected energy is summed through phase-locked loops. This technique amounts to a phased array of large elements. Note that the effective area $A_e$ of the receiver is related to the information bandwidth ($\Delta f$), the maximum scan angle $\theta$, the aperture efficiency $\eta$, and the velocity of light $c$ by:

$$A_e = \frac{\pi}{4\pi} \left( \frac{c}{\Delta f \sin \theta} \right)^2$$

when maximum gain is required at the band edges. This results in an area limited to about $3 \times 10^3$ square meters for a 2-MHz bandwidth with the array steered to 60° from zenith. Since even this aperture size would produce a 4-dB drop at the band edges, and since larger apertures will be required, time-delay steering must be used to provide adequate bandwidth, perhaps using delay-locked loops.

To improve performance it is important to maintain at least the present system noise temperature, which requires very close control of the antenna sidelobe structure. Although back lobes are most important in determining the antenna noise temperature, those side-lobes that look through the atmosphere at the lower elevation angles can also contribute significant noise temperature. This requires very low side-lobes beyond about 20° of the main beam. Unusually high side-lobes, such as grating lobes, within 20° of the main beam can cause a serious increase in noise temperature when pointing toward some hot object in the sky. Grating lobes can be particularly troublesome when the propagation path is close to the sun.

The goal of research for an Earth-terminal antenna system should be the development of a large time-delay-collimated, multi-aperture antenna system with noise contribution from the ground and low elevation angles on the order of 4°K. The techniques developed for this application must provide an average side-lobe level of about 80 dB with peak side-lobes or grating lobes of the order of 40 dB below the main beam.

CONCLUSION

A communication rate of 106 bits per second from Mars is clearly feasible as a 10-year goal. The most significant step toward achieving this goal will be the development of a very-large-aperture, low-noise, electronically scanned, receiving antenna at the Earth terminal. The large number of low-noise receivers needed for such a system makes a more efficient design essential.

At the deep-space terminal, weight and power will be critical. Electronic scanning techniques will reduce the stabilization requirements on the spacecraft. Solid-state techniques must be developed for more-efficient power conversion. Integration of thermal and electrical functions in the spacecraft antenna system should provide the high effective radiated power per pound of payload weight required for future long-duration deep-space missions.

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DIMATE—A SPACE-AGE ROBOT

One of the most versatile of the space-age robots is a computer-controlled automatic test set developed by the Aerospace Systems Division. The test set, known as Depot Installed Maintenance Automatic Test Equipment (DIMATE), is installed at an Army Depot. This paper describes the DIMATE system and its operation.

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Automatic Test Equipment Programs

The DIMATE (Depot Installed Automatic Test Equipment), one of the family of automatic test sets developed by RCA for field and depot maintenance support of U.S. Army electronics, performs automatic inspection testing and fault isolation of all U.S. Army radio communication equipments — personal, vehicular, and airborne. DIMATE System No. 1 inspects and tests high-density radio sets.

The advantages of automatic test equipment, as compared to conventional test equipment, are as follows:

1) **Reduction in test time of 3 or more to 1.** This reduction is due to the automatic recording of test data and the elimination of manual adjustments.

2) **Reduction in number of test equipment line items required.**

3) **Standardization of test procedures and test results.** All test instructions, pre-recorded on perforated or magnetic tape, are performed automatically in the same sequence for each unit under test, and all test results are automatically recorded.

4) **Reduction in operator skill level and training requirements.** Prerecorded test instructions are used. The standardization of test procedures and test results and reduced number of line items of test equipment shortens the training time required.

5) **Minimized obsolescence of test equipment.** Introduction of new prime systems into the Army inventory requires new test program tapes rather than new test equipments.

6) **Reduced calibration time and types of calibration equipments required.** DIMATE contains internal standards for self-test and calibration checks; only 19 of the 83 assemblies, or building blocks, require periodic calibration against external standards.

**SYSTEM DESCRIPTION**

The DIMATE computer-controlled automatic test set is actuated by a perforated tape, a magnetic tape, or a manual keyboard input. It is capable of automatic, semiautomatic, and manual testing of U.S. Army communication equipments and many other types of electronic, electrical, and electromechanical equipments.

It consists of seven racks, an operator's control console, and a tape-preparation station containing 83 assemblies of 59 types. These assemblies are interconnected to form five functional subsystems, or groups, as follows: computer/controller group, measurements group, low-frequency stimulus group, direct-current stimulus group, and internal power supply group. Fig. 1 is a rack layout showing the location of the various assemblies, or building blocks, in the system.

**Computer/Controller Group**

Included in this group are the operator's control console (with controls and displays), computer, controller, printer, perforated tape reader, magnetic tape transport, manual input keyboard, and a visual instructor (microfilm viewer). An automatic typewriter with a perforated tape punch and reader is provided for off-line preparation and reproduction of program tapes. The computer/controller group performs the functions of information storage, retrieval, search, identification, selection, and interpretation. Following interpretation of the selected data, it directs and controls the programmable functions of assemblies in the other equipment groups.

The computer/controller group compares the responses of units under test (UUT's) or other assemblies of DIMATE with internal standards or programmed limit values, interprets and evaluates the comparisons, prints the results of the evaluations, and determines and directs subsequent operations.

**Measurements Group**

This group consists of signal-conditioning equipments, analog-to-digital converters, a time-interval and frequency converter, reference standards, switching for the selection of test points and the interconnection of the measurement assemblies, and a test-results display.

The primary function of the measurements group is to convert voltage, resistance, frequency, and time intervals to digital data. Signal-conditioning devices are provided for scaling and to convert power, impedance, or modulation characteristics to voltage and frequency for processing by the analog-to-digital converters. Programmable switches, under control of the computer/controller, select test points and route signals from the UUT's or other DIMATE assemblies to the appropriate adapters and converters for signal conditioning and conversion to digital data. A data output buffer routes the digital data to the computer/controller for processing and comparison. The data output buffer also converts the digital data to a decimal data and function for display on the test-results display.

**Low-Frequency Stimulus Group**

Included in this group are a frequency standard (for frequency and time base reference), a pulse generator, and AC and RF generators. These assemblies provide CW sine-wave signals from 100 Hz (c/s) to 200 MHz (Mc/s), and amplitude, frequency, or pulse-modulated signals with carrier frequencies from 100 kHz to 400 MHz. Programmable routing and application switches interconnect the stimulus assemblies and connect the stimulus to UUT's and assemblies in other DIMATE groups.

**Direct Current Stimulus Group**

This group, containing programmable, regulated dc power supplies, provides dc power of 5 to 850 volts at currents from 200 milliamperes to 20 amperes, depending upon voltage. In addition, two precision dc reference supplies provide 0 to 10 volts at currents up to 100 milliamperes. Application switches switch power or reference signals to UUT's and assemblies in other DIMATE groups.

**Internal Power Supply Group**

This group consists of a primary power control, dc power supplies, voltage regulators, and individual-rack power control. It provides all dc power, both regulated and unregulated, required for the operation of DIMATE. In addition, it provides program-controlled switching to route ac and dc power from the depot power mains to a UUT.

**SYSTEM OPERATION**

The simplified block diagram of DIMATE in Fig. 2 shows the interfaces between the functional subsystems and the routing and distribution of power, control data, stimulus, and response signals.

The first portion of the test program is a confidence test, which automatically self-tests selected stimulus and measurement functions to determine if the DIMATE is within allowable tolerances.
and capable of performing the required tests on the UUT.

The next portion of the test program is a series of static tests (impedance and resistance measurements) on the UUT. These static tests determine the presence of shorts or open circuits in the UUT power and input circuitry and thus prevent damage to both the UUT and the DIMATE (through application of either power or stimulus to a short or open circuit).

If both the DIMATE and the UUT are capable of further testing (as determined by the results of the confidence and static tests), the program continues into the dynamic portion of the test program. During dynamic testing, power is automatically applied to the UUT; selected stimuli are applied sequentially or simultaneously, as required, to the UUT and the response to each stimulus is measured. When required, arithmetic operations are performed on two or more responses to derive secondary measurements, e.g., gain or insertion loss, bandwidth, percent modulation, frequency deviation, and distortion. The response and computed secondary results are compared with programmed upper and lower limits in the comparator/time delay and the results are displayed to the operator by means of the test-results panel and the printer.

When operator participation is required in a test (e.g., adjustment of the UUT or manual test-point selection by means of a probe), the instructions are recorded on the program tape and printed out by the printer. Where identification of controls, parts, or test points is required, photographs or drawings are provided on microfilm and displayed on the visual instructor located above the printer on the operator's control console. Where a manual operation is required during a test, the test is automatically halted and the operator instructions are printed out. Reference to drawings, photographs, or detailed text instructions on microfilm are printed out when required. After performing the necessary adjustments or other manual operations, the operator depresses the proceed switch on the control panel and the test continues automatically.

Fault-isolation test routines are programmed for each probable UUT malfunction. If a test result is within programmed limits, the test is go and the DIMATE automatically proceeds to the next step in the program. If a test result is not within the programmed limits, the test is no-go. Depending upon whether the test result is a negative response, above the upper limit or below the lower limit, the DIMATE automatically selects the proper fault-isolation routine and performs the necessary tests to determine the most probable location and cause of the malfunction. Faults are isolated to one or more modules or replaceable subassemblies in modularized equipment and to one or more discrete circuit functions in nonmodularized equipments.

The value of each measurement is displayed on the test-results panel and all test numbers, test results, and operator instructions are printed out on the printer. When desirable, alignment procedures, repair instructions, and references to handbooks, drawings, and other documentation may be included on the test program tapes along with the fault-isolation routines, and these will be printed out with the appropriate fault indications.

**Fig. 1** — DIMATE rack layout showing location of building blocks.

**Fig. 2** — Simplified block diagram of DIMATE.

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TEMPERATURE-COMPENSATED CRYSTAL OSCILLATORS

Temperature compensated crystal oscillators are finding increasing uses in place of oven controlled oscillators. Design of the TCXO is difficult and costly because of close tolerance requirements. Oscillator circuit design approaches, aimed at minimizing the design cost, are described and mathematically analyzed. Good correlation is obtained between calculated and actual performance.

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Temperature compensated oscillators (TXCO), although well known for a number of years, only recently have been gaining in popularity. This method for a frequency source over wide temperature ranges has a number of important advantages over the better-known oven are:

1) elimination of warm-up time
2) reduction of power drain and size
3) improvement in long term crystal stability because of lower average operating temperature

All TCXO's rely on compensating for crystal frequency drifts with temperature by varying the crystal load capacitance in a pre-determined manner. Accurate control of circuit components and crystal parameters is required to ensure that the compensating network temperature characteristic matches that of the crystal to the specified tolerance limits. The circuit designer will match the crystal to the specified tolerance tolerances. Frequency compensating characteristic is critical requirements are normally placed on crystal itself in terms of better aging and tighter tolerances. Oscillator design approaches described are aimed at minimizing this effect, and consequently, permitting the use of lower cost crystals.

OSCILLATOR ANALYSIS

The model selected for this design analysis is the Colpitts type oscillator shown in Fig. 1, where:

\[ R_1, R_2, R_3 \] provide conventional transistor bias.
\[ R_2, C_3 \] provide by-pass and battery blocking.
\[ C_4 \] is output coupling capacitor.
\[ C_b, C_a \] are fixed capacitors providing correct feedback for oscillation.

In the current generator equivalent circuit of the oscillator (Fig. 2):

\[ R_e = \text{total parallel emitter-to-collector resistance including output resistance.} \]
\[ C_a = \text{total parallel emitter to collector capacitance.} \]
\[ R = \text{parallel combination of bias resistors } R_1 \text{ and } R_2. \]
\[ g_m = \text{transconductance.} \]
\[ X = \text{crystal effective parameters, equivalent to series inductance } L_x \text{ and series resistance } R_e \text{ given approximately by:} \]

\[ L_x = \frac{1}{ \omega_c^2 C_1 f_x \left( 1 - \frac{C_x}{C_1} \right) } \]

\[ R_x = \frac{R_e}{1 - \frac{C_x}{C_1} \frac{2 \Delta f}{f}} \]

where: \( C_x \) = crystal motional capacitance.
\( C_1 \) = crystal shunt capacitance,
\( R_x \) = crystal series resistance, and \( f_x \) = crystal series resonant frequency given by:

\[ \omega_x = \frac{1}{L_x C_1} \]

\( L_x \) = crystal motional inductance.
\( \Delta f \) = frequency change or compensation, \( f_x \) = frequency difference, and \( Df \) = frequency range.

\[ \frac{\Delta f}{f_x} = \left( \frac{C_x + C_1}{2 C_x} \right) \left( 1 + \frac{1}{Q_x Q_1} + \frac{1}{Q_1 Q_x} \right) \]

\[ g_m (\text{stabilized}) = R_x \omega_c C_x C_0 \]

FREQUENCY RELATIONSHIPS*

Solution of the equivalent circuit of Fig. 3 yields the approximate frequency of oscillation in parts per million (ppm) and the minimum \( g_m \) required:

\[ \frac{\Delta f}{f_x} = \left( \frac{C_x + C_1}{2 C_x} \right) \left( 1 + \frac{1}{Q_x Q_1} + \frac{1}{Q_1 Q_x} \right) \]

Fig. 1—Crystal oscillator.

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The required $\Delta C_s$, as a function of temperature, can be provided by a number of temperature sensitive networks, such as a thermistor-capacitor, or thermistor-voltage variable capacitor. The closeness of correlation between $\Delta C_s$ required, and $\Delta C_s$ obtained from the compensating network, will depend on the type and number of networks used.

Referring to Fig. 1, compensating networks can be connected in parallel with any of the circuit capacitances $C_s$, $C_{Sl}$, $C_s$ or in parallel with the crystal. However, since $C_s$ and $C_{Sl}$ are usually large, requiring large $\Delta C$ for a given $\Delta F$, the most common connections are in parallel with $C$ or the crystal.

**TRIMMER EFFECT ON COMPENSATION**

Let us consider the common case where capacitance $C$ is made variable to obtain frequency trimming; compensation is thus applied in parallel with the trimmer capacitor (Fig. 5a).

All equations derived previously under *Oscillator Analysis* apply; from Equation 3a, it is seen that the frequency of oscillation depends also on circuit resistances. However, the effect of resistance can be made negligible by making $R_s C_s$ and $R_{Sl} C_{Sl}$ sufficiently large, the only limitation being the magnitude of transistor transconductance available. Under such conditions a simplified form of Equation 3a is obtained:

$$\frac{\Delta F}{f_s} = \rho \frac{C_s \cdot 10^6}{2(C_s + C_{Sl})} \text{(in ppm)} \quad (6)$$

By differentiation, the frequency sensitivity becomes:

$$\rho C_s = \frac{-C_s \cdot 10^6}{2C_s^2 \left(1 + \frac{C_{Sl}}{C_s}\right)} \text{(in ppm/pF)} \quad (7)$$

Further, by making use of the relationship:

$$\frac{1}{C_s} = \frac{1}{C_s} + \frac{1}{C_{Sl}} + \frac{1}{C}$$

frequency sensitivity $\rho C_s$ to the capacitance change in parallel with $C$ becomes:

$$\rho C_s = \frac{-C_s \cdot 10^6}{2C_s^2 \left(1 + \frac{C_{Sl}}{C_s}\right)} \text{(in ppm/pF)} \quad (8)$$

When $C_s/C_{Sl}$ is small compared to unity (the usual case), frequency sensitivity, and therefore also the frequency compensation, $DF$ of Eq. 5 will be inversely proportional to the square of the value of the trimmer capacitor; this relationship holds true for a given $\Delta c$ at any temperature. When a given variable "trimmer" frequency range $DF$, is required with a corresponding load capacitance change $DC_s$, the ratio of the frequency compensation at the two trimmer capacitor extremes is given by:

$$\frac{DF_1}{DF_2} = 1 + \frac{2DC_s}{C_s + C_{Sl}} \quad (9)$$

where, $DC_s = C_{Sl} - C_s$.

$C_s$ = load capacitance corresponding to high frequency

$C_{Sl}$ = load capacitance corresponding to low frequency

With a typical crystal having $C_s = 6 \mu F$, $C_{Sl} = 24 \mu F$, $C_s = 0.03 \mu F$, and the trimmer capacitance range required of ± 35 ppm, i.e. $DF = 70$ ppm, the compensation change will be 28% giving a variation of
Again, all equations derived under Oscillator Analysis apply for the above relationship of \( C \) in terms of \( C_1 \) and \( C_2 \).

When a small \( \Delta C \) is introduced in parallel with \( C \), rather than in parallel with \( C \), the compensating frequency change due to a given \( \Delta C \) is obtained, by differentiation with respect to \( C_1 \):

\[
\Delta f = \rho C_1 \Delta C
\]

\[
= -\frac{C_1 \Delta C \cdot 10^6}{2C_2^2} \left( 1 + \frac{C_2}{C_1} \right) \text{ (in ppm)}
\]

Since \( C / C_2 \) is small compared with unity, the frequency change is inversely proportional to the square of the fixed capacitance, \( C_2 \), and therefore remains substantially constant within the trimming capacitor range. The amount of variation depends only on the practical value of \( C / C_2 \), relative to unity.

If \( \Delta f_2 \) and \( \Delta f_3 \) are frequency changes at the two frequency trimming extremes, the ratio in this case is given approximately by:

\[
\frac{\Delta f_2}{\Delta f_3} = \left( 1 + \frac{2DC_2}{C_2 + C_1} \right) \left( 1 + \frac{1}{2DC_2} \right)
\]

where:

\[
DC_2 = \frac{2DH}{10^8} \left( \frac{C_2 + C_3}{C_1} \right)^2
\]

With the same typical crystal and the same trimmer frequency range required as in the previous case, the compensation variation within the trimming range will be \( \pm 2.5\% \).

An oscillator was built using an 8.5 MHz crystal with a thermistor-capacitor network to obtain a frequency compensation of 14 ppm at \(-30^\circ C\) with respect to reference temperature of \(25^\circ C\). The two curves, one at \(-35\) ppm and one at \(+35\) ppm are shown in Fig. 7. Total compensation change is seen to be \( \pm 0.5 \) ppm, or \( \pm 3.5\% \).

**Case 2: Trimmer Effect Reduction**

By making use of the resistive effects on frequency, it is possible to design an oscillator that is virtually independent of the variable trimmer capacitor. However, this applies only to such systems as the thermistor-capacitor where the compensation process includes coupling both capacitance and resistance. Both changes, \( \Delta C \), capacitive, and \( \Delta R \), resistive, can be expressed as a function of temperature. In the case of thermistor-capacitor compensation, the two functions are mutually dependent; but, it is possible to think of a network wherein the variables can be independently controlled. In such a method, a modification of Fig. 1 circuit is necessary; Fig. 8 represents this modification where:

\( R_1, R_2, R_3 \) provide conventional transistor bias; but, since \( R_3 \), in this circuit is part of the compensation, the values are carefully selected according to design requirements.

\( C_2, C_3, C_4, C_5 \) make up the crystal load capacitance.

\( C_6 \) variable capacitor to obtain frequency trimming.

\( C_7 \) a fixed capacitor across which a temperature sensitive network \( C_1, R_1 \), is connected.

\( R_5 \) Thermistor, i.e., temperature sensitive resistor.

The voltage equivalent circuit remains as shown in Fig. 3, except that a small series resistive component \( \Delta R \), is added to indicate resistive effect of the thermistor-capacitor network (Fig. 9). Solution of this circuit gives the approximate frequency of oscillation as was done in Equation 3:

\[
\frac{\Delta f}{f_o} = \frac{C_1 \cdot 10^6}{(2(C_1 + C_2))} \left( \frac{1}{C_1} + \frac{1}{C_2} \right)
\]

where:

\[
\Delta R = \frac{C_1 \cdot 10^6}{(2(C_1 + C_2))} \left( \frac{1}{C_1} + \frac{1}{C_2} \right)
\]

and \( C = C_1 + C_2 \) at reference temperature when \( R_3 \) is small and:

\[
R = R_1 + R_3 + R_4 + R_5 + \Delta R
\]

Rewriting Equation 12a, and assuming that \( C_3 R_3 \) can be made much larger than \( C_3 R_2 \):

\[
\frac{\Delta f}{f_o} = \frac{C_1 \cdot 10^6}{2(C_1 + C_2)} \left( \frac{1}{C_1} + \frac{1}{C_2} \right)
\]

Examination of Equation 12a indicates that the frequency of oscillation is made up of two parts, one dependent on \( C_2 \) and independent of \( R_3 \), and the other dependent on \( R_3 \) and almost independent.
of $C_r$, since $C_r/C_e$ is usually small compared to unity.

**FREQUENCY COMPENSATION**

As in previous cases, frequency compensation is achieved by introducing a small capacitance change $\Delta C$ controlled by the temperature sensitive thermistor. As the temperature changes from the reference temperature ($T_r$) where $R_t$ is small and $C = C_0$, to a lower temperature, the thermistor resistance increases and $C$ is reduced by a corresponding $\Delta C$. At the same time, the coupled resistance $\Delta R$, increases from a negligible value so that frequency change is brought about; the magnitude of the change is controlled by the magnitude of $1/C_0 R_t$. These two effects: $\Delta F(C)$, the frequency change due to capacitance change; and $\Delta F(R_t)$, the frequency change due to resistance change; are used to achieve compensation independent of the trimmer capacitor.

From Eq. $12a$, frequency due to $C_r$:

$$ F(C_r) = \frac{C_r \cdot 10^6}{2C(1 + \frac{C_r}{C})} \quad (13) $$

and frequency due to $R_t$:

$$ F(R_t) = \frac{C_r \cdot 10^6}{2C(1 + \frac{C_r}{C})} \left( \frac{R_t}{C_0 R_t} \right) \quad (14) $$

Since these two frequency components are mutually independent as far as $C_r$ and $R_t$ are concerned, the total frequency change, when both $C_r$ and $R_t$ change, can be obtained by differentiating $F(C_r)$ with respect to $C_r$; and $F(R_t)$ with respect to $R_t$, yielding the frequency change due to small $\Delta C_r$:

$$ \Delta F(C_r) = \frac{C_r \cdot 10^6 \Delta C_r}{2C(1 + \frac{C_r}{C})} \quad (15) $$

Frequency change due to small $\Delta R_t$:

$$ \Delta F(R_t) = \frac{C_r \Delta R_t \cdot 10^6}{2C(1 + \frac{C_r}{C})} \frac{R_t}{C_0 R_t} \quad (16) $$

Now, $\Delta C$ is negative (less capacitance), when $\Delta R$ is positive (more resistance). Thus, when the temperature changes from the reference temperature to a lower temperature, both changes are positive, and therefore, the total frequency change is:

$$ \Delta F = \Delta F(C) + \Delta F(R_t) $$

$$ = \frac{C_r \Delta C \cdot 10^6}{2C(1 + \frac{C_r}{C})} + \frac{C_r \Delta R \cdot 10^6}{2C(1 + \frac{C_r}{C}) \cdot \frac{R_t}{C_0 R_t}} $$

The following conditions can be observed from Eq. 17 in considering the two trimmer capacitor extremes:

1) At high trimming frequency, both $C_r$ and $C_0$ are small, so that the first term is small and the second is large.

2) At low trimming frequency, both $C_r$ and $C_0$ are large, so that the first term is large and the second term is small. Therefore, within a given variable trimmer capacitance range, the change in amount of frequency compensation due to the capacitance effect is countered by the opposite change in compensation due to resistive effect.

Conditions for perfect cancellation of these two changes can be obtained by differentiating Eq. 17 with respect to $C_r$ and equating to zero, which yields:

$$ R_t = \frac{\Delta R}{2} \cdot \frac{C_r}{C_0} \cdot \frac{C_r}{C_0} \left( \frac{2C + C_0}{C_0} \right) \quad (18) $$

Thus, the required $R_t$ is given in terms of $\Delta R$, $\Delta C$, $C_r$, and the crystal parameter. Since $C_r/C_0$ is very small compared to unity, $R_t$ is practically independent of $C_r$; therefore, an almost perfect stability of compensation is achieved within the trimmer capacitor range.

In practice, a simple thermistor capacitor compensating network $AR_t$ is dependent on $\Delta C$. Thus, when an exact $\Delta F$ is required according to design requirements, Equation 18 may be inconvenient to use. However, the required component of the compensation $\Delta F(R_t)$ will be usually small compared to $\Delta F(C_r)$; consequently, an approximate $\Delta F$ given by Eq. 15 can be first used to calculate the thermistor-capacitor network in terms of $\Delta C$ alone.

Emitter resistance $R_e$ can then be selected to obtain the best results. At least two steps are usually required: 1) obtain good compensation stability within the trimmer range, and 2) make small readjustments on the thermistor-capacitor network to obtain the desired amount of compensation $\Delta F$.

An oscillator was developed with an 8.5 MHz crystal, compensated for frequency drift in the temperature range from $+26^\circ$C to $-30^\circ$C, using a thermistor-resistor network. The two measured curves corresponding to $\pm 35$ ppm trimmer capacitor extremes are shown in Fig. 10. Note that the total compensation change is less than 0.25 ppm, i.e. less than $\pm 1.0\%$.

**SUMMARY**

Analysis of conventional crystal oscillator circuits can lead to practical modifications producing improved temperature compensated crystal oscillator performance with respect to stability of compensation over the trimmer frequency. Three such oscillator circuits based on the foregoing theoretical analysis have been investigated:

1) **Conventional**; this can be considered a conventional circuit and illustrates the degree of improvement achieved in the other two oscillators. Temperature curves are shown in Fig. 6.

2) **Series oscillator circuit**; the improved results shown in Fig. 7 are achieved through making use of a series circuit that effectively reduces the variations of crystal frequency sensitivity with load capacitance.

3) **Controlled resistive effects**; this is basically the same as the series oscillator (2) where the remaining small variations in frequency sensitivity are eliminated by making use of controlled resistive effects. Temperature curves are shown in Fig. 10.

In each of the three oscillator circuits described in this paper, very good correlation has been obtained between predicted and actual oscillator performance.

**ACKNOWLEDGMENTS**

The author expresses his gratitude to W. J. Sweger for major assistance in the preparation of this paper, and to A. M. Missenda for contributions to the mathematical analysis. Derivations and proofs of the formulas and assumptions used in this paper will be furnished upon request.
DIRECT FORCED-AIR COOLING SYSTEM FOR ELECTRONIC EQUIPMENT

This paper describes a perforated plenum technique for directing forced cooling air at equipment inside a rack enclosure. It is intended to show that this method is a relatively simple means of attaining reliable quantities of metered air directed at various levels within a rack. The data can be used in determining the applicability of this type of cooling to a particular system and to furnish information which can be applied to similar perforated-plenum configurations.

J. M. WARNICK

As electronic packaging techniques become more sophisticated and component density increases, greater reliance is placed on the cooling system to maintain the equipment at a proper operating temperature level. In a single electronic rack enclosure where as high as 10,000 Btu's of heat per hour could be dissipated, a reliable means of cooling temperature-critical components and avoiding hot spots is necessary.

In the design of large systems consisting of many racks of electronics, as is often the case in ground support and shipboard equipment, it is usually necessary to establish the system packaging parameters at the beginning of the program. A standardization effort is made to select an overall chassis configuration, rack enclosure, and cooling system. Each item must be compatible with the others and the electronics which are to be packaged. The decision has to be made as to whether the equipment can be cooled strictly by free convection air or whether forced air is required. Consideration must also be given to the fact that many engineers will be packaging various equipment chassis, each with its own particular cooling requirements.

For high-density packaging, free convection throughout the rack usually is not sufficient. Forcing air through the rack is a minimum requirement. Where temperature-sensitive components are involved, there still may not be enough movement of air in the component area to carry away the heat. Although the air forced into the rack moves around the outside of the chassis, the heat-sensitive components inside may have to depend upon free convection. In such a case it would be advantageous to locate these components close to an air source so that the air can wash directly over them. A known quantity of metered air available at a known location would enable the packaging engineer to cope with this and similar situations.

PERFORATED-PLENUM CONFIGURATION
The plenum is a hollow pressurized duct which can be installed in the side of a rack, using the rack side cover as one of the plenum sides. The holes in the side of the plenum facing the equipment can be located to direct forced air at specific areas, thus providing cooling to nearby hot spots and other areas which are discussed later.

A typical 0.06-inch-thick, sheet-aluminum plenum containing eight rows of 0.375-inch-diameter orifice holes is shown...
in Fig. 1. Since part of the rack frame structure would ordinarily be directly above the plenum installed in the side, a transition duct is required to supply air to the face of the plenum. The transition duct shown in Figs. 1 and 2 gradually angles into the plenum to minimize entrance pressure losses. Air can be furnished to this duct directly from a blower mounted on top or from an overhead air-conditioning header duct.

**ORIFICE HOLE CHARACTERISTICS**
The orifice holes are punched in the plenum. Since it is common shop practice to deburr the sharp side of such holes, consideration should be given to the effect on the hole coefficient of discharge. The coefficient of discharge $C_d$ is based on the relationship

$$\text{Flow} = C_d A \sqrt{2gh}$$

where $A$ is the orifice area; $g$, the acceleration of gravity; and $h$, the pressure differential across the orifice in the height of the fluid. With typical shop-deburred hole edges upstream to the direction of air flow, and with smooth air entry directly into the hole, $C_d$ is 0.71 for 0.06-inch-thick aluminum. For the deburred edges downstream, $C_d$ is 0.65. For undebugged holes, $C_d$ is 0.65 for the burried edges downstream and 0.63 for the burried edges upstream. It is apparent that since $C_d$ is the same when the punched edges of the holes are upstream, regardless of whether the downstream edges are deburred or not, more consistent results will be obtained by punching the plenum from the upstream side.

The plenum in Fig. 1 has its holes punched from the upstream condition. However, since the main flow of air within the plenum is at right angles to the flow through the holes, $C_d$ is reduced to 0.61. Subsequent curves, where applicable, are based on this coefficient of discharge.

**PRESSURE-DROP CHARACTERISTICS**
The pressure drops through the transition duct and plenum are shown in Figs. 3 and 4. In many applications radio frequency interference (RFI) must be prevented from entering or leaving the rack enclosure. Fig. 4 shows pressure-drop curves for various configurations of protective screens. It is apparent from these curves that screens angling into the plenum almost normal to the direction of the air flow, and with a larger area exposed (Fig. 5), have the lower pressure drop.

A variety of air entrance conditions into the transition duct is possible, depending on the blower used, the size of the overhead header duct, and whether turning vanes are used in the header duct. Figs. 3 and 4 are, therefore, based upon smooth entrance conditions. If an additional pressure drop results from the particular air entrance situation, it can be added to the losses shown in these figures. If a lower pressure drop is desired across the protective screen, other commercially available shielding materials, such as honeycomb-type material, can be substituted, but usually at higher cost and space consumption.

**PLENUM AIR-FLOW PATTERNS**
In Fig. 6 the air-flow gradient along the various levels of the plenum is shown. At the higher flow rates the static pressure regain is demonstrated at the bottom of the plenum, causing higher flow through the port holes. Conversely, at the top of the plenum a decrease in static pressure is demonstrated as the air moves past the holes with a higher velocity, causing slightly less air to go through the holes. At lower to moderate overall flow rates the flow through the holes at each level is essentially constant, and slight fluctuations for practical purposes can be ignored. In light of the appreciable pressure drop at the plenum entrance, together with the flow patterns shown in Fig. 6, the pressure drop between the plenum top and bottom can be considered negligible. It should be noted that this data is not only applicable to the specific configuration shown in Fig. 1; it can also be applied to similar systems where favorable aspect ratios are maintained and abrupt air pattern changes are minimized.
METERED AIR COOLING CHARACTERISTICS

The cooling capacity in watts/hole for a 0.375-inch-diameter hole is shown in Fig. 7. It is applicable for any case where the hole coefficient of discharge is close to 0.61. For example, if a rack of equipment has heat dissipation of 1 kW and the overall temperature rise is limited to 30°F, this would correspond to a cooling air rate of 7.9 lb/min/kW. For a plenum pressurized at 1.0 inch of water above rack pressure, each hole would have a cooling capacity of 17.8 watts. Therefore, for 1 kW of heat dissipation, 1000/17.8 or 56 holes are required.

At 1.0 inch of water pressure it can be seen from the relationship

\[ \text{Velocity} = C_v \sqrt{2gh} \]

where the velocity coefficient \( C_v \) equals 0.97, that the air exit velocity from the plenum holes is 3890 ft/min. The depth of penetration of this air into a chassis of equipment depends upon the particular equipment configuration and the airflow resistance that the configuration causes. When this resistance is appreciable, the air can be expected to penetrate past the heat-critical components part way into the equipment. It then is carried into the surrounding air paths by free convection. In other cases where suitable paths are set up, the air can move straight across to the opposite side of the rack. In most applications of this type of cooling, the entire rack is maintained at a slight positive pressure, resulting in a general movement of air to an exhaust opening and overall removal of the heat.

CONCLUSION

The perforated-plenum cooling system can be applied to most cases where forced air is used for cooling electronic rack enclosures. The major advantages of this type of system are listed below:

1) Air openings can be located to direct air where it will do the most good.
2) The air is reliably metered so that a known quantity of air can be made available from specific locations for particular chassis cooling needs.
3) Flexibility is provided, since an equipment chassis can be flushed with cooling air around the outside and also penetrated.
4) Air that has not been preheated by other components is available for cooling properly located temperature-critical components.
5) The need for auxiliary blowers and heat sinks within a chassis is minimized.
6) The need for baffles for directing air flow within a rack is minimized.

Disadvantages of the perforated-plenum cooling system that should be considered are as follows:

1) Additional cost of ducting within the rack.
2) Additional blower capacity required to maintain the positive plenum pressure.
3) Possible blower noise if blowers are not carefully selected.

The advantages and disadvantages noted above are useful in comparing this system with the other two most common types of air cooling: completely free convection within the rack, and air flushed directly through the rack. These two cooling methods usually are adequate for low to medium heat dissipation by loosely packaged equipment. For high-density, high-heat-dissipating equipments, however, the advantages of the perforated-plenum technique are more apparent.
Laser Radiation Nomograph

D. J. Blattner, Electronic Components and Devices, Princeton, N. J.

Final manuscript received June 13, 1966

The phenomenal development of the laser has combined techniques from optics, spectroscopy, physics, and electronics. Small wonder, therefore, that laser radiation is variously reported in terms of wavelength, wave number, frequency, and photon energy. However, any one of these terms can be converted to the others by use of a straight-edge and the nomograph shown in Fig. 1. For example, light at a wavelength of 0.5 μm can also be specified as having the following parameters:

- wavelength = 5,000 angstroms
- frequency = $6 \times 10^{14}$ hertz or 600 terahertz
- wave number = 20,000 cm$^{-1}$
- photon energy = 2.48 electron-volts

As other examples, a glance across the chart shows that electrons with an energy of 4 volts radiate at 3,100 angstroms, and that light at 200 terahertz produce conduction in semiconductors that have bandgaps up to 0.82 volt. Keep this nomograph handy!

Laser User's Guide

D. Blattner and R. Wasserman, Electronic Components and Devices, Princeton, N. J.

Final manuscript received Sept. 14, 1966

Here is a helpful chart (Fig. 1) that shows at a glance the wavelength, frequency, color, and photon energy of radiation from various laser materials. The lasers listed on the chart are only a few of the many types reported; however, the chart itself, which illustrates the conversions from frequency to wavelength or from wavelength to energy, can be used for any laser. Detectors for each region of the spectrum are also indicated on the chart. Semiconductors are useful over the entire range shown. Intrinsic semiconductors are available for energies greater than 0.2 eV; for detection of wavelengths farther out in the infrared, the semiconductor must be doped. For short wavelengths ($\lambda < 0.7 \, \mu m$) phototubes offer the advantages of amplification by electron multipliers and higher speed. Bolometers (heat detectors) also cover the whole range, and although they have less speed and sensitivity than quantum detectors, they have the advantage of responding to power regardless of wavelength.

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**Fig. 1—Laser radiation nomograph.**

<table>
<thead>
<tr>
<th>FREQUENCY (hertz)</th>
<th>WAVELENGTH (terahertz)</th>
<th>WAVELENGTH (angstroms)</th>
<th>WAVELENGTH (microns)</th>
<th>WAVENUMBER (cm$^{-1}$)</th>
<th>PHOTON ENERGY (electron volts)</th>
</tr>
</thead>
<tbody>
<tr>
<td>$3 \times 10^{16}$</td>
<td>$3 \times 10^4$</td>
<td>100</td>
<td>0.01</td>
<td>$10^6$</td>
<td>100</td>
</tr>
<tr>
<td>$10^{16}$</td>
<td>10,000</td>
<td>500</td>
<td>0.05</td>
<td>$5 \times 10^5$</td>
<td>50</td>
</tr>
<tr>
<td>$5 \times 10^{15}$</td>
<td>5,000</td>
<td>1,000</td>
<td>0.1</td>
<td>$10^5$</td>
<td>10</td>
</tr>
<tr>
<td>$10^{15}$</td>
<td>1,000</td>
<td></td>
<td></td>
<td>$5 \times 10^4$</td>
<td>5.0</td>
</tr>
<tr>
<td>VISIBLE: $5 \times 10^{14}$</td>
<td>500</td>
<td>5,000</td>
<td>0.5</td>
<td>$10^5$</td>
<td>10,000</td>
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<td></td>
<td></td>
<td></td>
<td></td>
<td>$10^4$</td>
<td>1.0</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td></td>
<td>$5 \times 10^4$</td>
<td>5,000</td>
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<tr>
<td></td>
<td></td>
<td></td>
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<td>$10^3$</td>
<td>0.5</td>
</tr>
<tr>
<td>INFRA: $5 \times 10^{13}$</td>
<td>50</td>
<td>$5 \times 10^4$</td>
<td>5.0</td>
<td>$10^3$</td>
<td>1,000</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td></td>
<td>$5 \times 10^3$</td>
<td>500</td>
</tr>
<tr>
<td></td>
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<td></td>
<td></td>
<td>$10^{13}$</td>
<td>0.1</td>
</tr>
</tbody>
</table>

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A search for a suitable electronic packaging technique for spacecraft application resulted in the development of the Flexible-Film technique (FFIP), which comprises the mounting of integrated circuits and miniature components on a flexible film. The FFIP scheme enables compact, three-dimensional packaging without plug-type interconnections, as well as the interconnection of metal-oxide-semiconductor (MOS) transistor arrays, thin-film transistor (TFT) memory elements, conventional integrated-circuit flatpacks, and discrete miniature components, each of which may have a large range of internal packing densities. It is also possible to use FFIP to interconnect the different types of arrays not possible with most other array fabrication techniques. The FFIP scheme will thus increase in value as newer technologies evolve.

The FFIP comprises the mounting of integrated circuits and miniature components on a flexible printed-circuit dielectric film 0.002-inch thick, with one-ounce copper conductor on both sides. The width of the conductor line is approximately 0.012 inch, permitting a flexible printed-circuit assembly to be rolled or otherwise shaped and packaged in various configurations. Fig. 1 illustrates the evolution of the packaging techniques and the impact upon size, weight, and power requirements. The striking improvement in the most significant parameter, the number of logic modules per cubic inch, is shown. Data in Figure 1 indicates that, with conventional packaging, a density of 0.54 module per cubic inch was achieved; with integrated circuits on printed-circuit boards, a density of 5.9 modules per cubic inch was provided; and with the new FFIP configuration, a density of 120 modules per cubic inch was achieved.

The center board is bonded to the cover, which is in turn bonded to the one-piece enclosure. The enclosure is designed for screw mounting, but may be adapted for clip mounting, depending upon its intended use. It may be made of either metal or plastic. The advantage of anchoring the center board to the enclosure is that in the event of a malfunction, the bonded section can be separated and the board assembly removed for repairs.

The mounting of the components (Fig. 2) was done with an impulse-soldering technique developed at RCA. The technique presently used for flight equipment accomplishes electrical junctions by means of a reflow soldering process whereby presoldered component leads are joined to solder-plated, printed-circuit boards. Standard, parallel-gap welding equipment is used, with the electrodes modified for the soldering process. This process enables the production of a high yield of quality terminations without damage to the dielectric between the laminated conductors or to the components by excessive heat. The heat applied to melt the solder at the junction can be controlled (as can the dwell time, electrode pressure, applied energy, amount of solder and flux, heat-sinking, and soldering cycle) to provide a solder connection of the quality required for spacecraft application.

By the use of multilayer flatpacks, a larger number of functions can be packaged in the same volume. This packaging technique can therefore be described as a method of compact interfacing as well as a high-density packaging technique. The flexible-film technique affords large savings in cost of procurement and manufacturing, as compared with the conventional method of packaging electronic circuits. The reduction of the parts required (e.g., harness boards, interface connectors, and hardware), the reduction of container size, and the elimination of manual soldering and "hard" wiring all contribute to the cost savings. The cost of manufacturing and assembling the micropackage, integrated-circuit unit shown in Fig. 1 is approximately one-seventh that of the conventional unit and approximately one-fourth that of the integrated-circuit unit.

A comparative cost is not given for the test cycle; however, the location of malfunctioning equipment may be simplified by the addition of convenient test pads. The defective components can be replaced by removing the flexible film from the container and expanding it to expose the area to be reworked. Flatpacks and discrete components can be removed by lifting and shearing the solder connections with a sharp knife. If jumpers must be added for circuit changes, insulated nickel ribbon 0.003-inch thick by 0.010-inch wide may be used. This ribbon can be routed as required and joined by impulse-soldering.


lasers


management


Masers


medical electronics

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OPTICS


radio receivers (mass-media)


recording (digital, equipment)


solid-state devices


radio receivers (mass-media)


recording (digital, equipment)


solid-state devices


Cathode Ray Tube Fabrication—C. T. Latimer (E.C.D., Marion) U.S. Pat. 3,261,157, August 2, 1966

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Printed Circuit Assemblies of Magnetic Cores—H. P. Lemaitre, L. B. Smith (E.C.D., Needham Hall) U.S. Pat. 3,273,144, September 13, 1966

Antenna Elements & SAM-D & Array Elements & Array Space Optimizing:
—"SAM-D Array Element Space Optimizing—Fortran IV; D. Shaskan, M.S.R. 0002"

DEPOSITIONS OF CRYSTALLINE NICKELBASEN:—J. J. Haskal, J. L. Cooper (Labs, Pr) U.S. Pat. 3,268,622, August 23, 1966
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Variable Attenuators—J. F. McSparran (C.D., N.Y.) U.S. Pat. 3,273,084, September 13, 1966
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MISSILE AND SURFACE RADAR DIVISION

RCA VICTOR RECORD DIVISION
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ELECTRONIC DATA PROCESSING
Tape Transport—S. Baybrick, R. H. Jenkins (E.D.P., Cam) U.S. Pat. 3,239,330, July 5, 1966
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Timing or Clock Pulse Generator Employing Plural Counters Capable of Being Selectively Activated—M. Silverberg (E.D.P., Cam) U.S. Pat. 3,250,821, August 23, 1966

Binary Coded Decimal Counter Circuits—A. Prieto (E.D.P., Fls) U.S. Pat. 3,264,357, August 2, 1966
PROFESSIONAL MEETINGS

DATES and DEADLINES

Be sure deadlines are met—consult your Technical Publications Administrator or your Editorial Representative for the lead time necessary to obtain RCA approvals (and government approvals, if applicable). Remember, abstracts and manuscripts must be so approved before sending them to the meeting committee.


SALUTE TO DAVID SARNOFF

The electronics and communications industries have paid tribute to RCA Chairman David Sarnoff in commemoration of the 60th anniversary of the start of his career in communications. Three national organizations—Mr. Sarnoff's industries associations, the Institute of Electrical and Electronics Engineers, and the National Association of Broadcasters—co-sponsored the "Salute to David Sarnoff" at New York's Waldorf-Astoria Hotel on September 30, the exact day 60 years ago when General Sarnoff started working for a telegraph company.

Frederick R. Kappel, Chairman of the Board of the American Telephone and Telegraph Co., served as program chairman at the dinner, and Lowell Thomas, noted author, commentator, and explorer acted as toastmaster. Approximately 1,700 people, including national government leaders and eminent Americans in all walks of life, attended.

ASD TECHNICAL EXCELLENCE AWARD WINNERS

Recipients of Technical Excellence Awards at the Aerospace Systems Division, Burlington, Mass., for the second quarter of 1966 include: Angelo Muzi, Robert Piper, and John J. Cedigan. They were cited for outstanding performance in the following areas: Muzi—mechanical design of automated production test equipment; Mr. Piper—Lunar Module radar test facility; and Mr. Cudigan—DIMATE AM/FM adapter. In addition, a 19-man ASD team was honored for the design, development, test, and delivery on schedule of the Land Combat Support System.

MARS TECHNICAL EXCELLENCE AWARD WINNERS

Winners of the Technical Excellence Awards at the NASA Missile and Surface Radar Division, Moody Air Force Base, Texas, for the second quarter of 1966 and their areas of achievement are: J. D. Frattura—data handling; J. F. Herbert—configuration management; H. J. Kishi—electrical configuration of 2-pound radar; E. A. Mecler—signature analysis; R. F. Pavly—new smoothing technique based on invariant imbedding principle; C. E. Profera—monopulse antenna feed horns using multimode techniques; H. R. Witch—analysis of AN/FPS-92 Category II test results; Dr. M. Weiss—thermal design and analysis for the Lunar Module.

CSD NAMES W. KIRKPATRICK

Appointment of William B. Kirkpatrick as Division Vice President, Marketing Department, of the RCA Communications Systems Division, Camden, N.J., has been announced by Joseph C. R. H. Division Vice President and General Manager. Mr. Kirkpatrick had been Marketing Manager of CSD. Mr. Kirkpatrick, who joined RCA in 1947, served earlier with the U.S. Army Signal Corps and Air Force. With the Air Force he was a Project Officer responsible for the design, development and testing of airborne component at Wright-Patterson AFB, Ohio. Mr. Kirkpatrick received a BSEE from the University of Pennsylvania.

DR. ENGSTROM, E. BERTERO, AND V. DUKE HONORED BY SMPTE

Dr. Elmer W. Engstrom, RCA Chief Executive Officer, and two NBC engineers were honored by the Society of Motion Picture and Television Engineers at the SMPTE 100th Semiannual Technical Conference in Los Angeles. The two NBC engineers are Vernon A. Mud and Edward Bertero.

Dr. Engstrom was given the Honorary Membership Award presented to "living pioneers who have represented a substantial forward step in the recorded history of the arts and sciences with which the Society is most concerned." Mr. Duke received the Herbert T. Kalman Gold Medal Award "for outstanding contributions in the development of color films, processes, techniques or equipment useful in making motion pictures for theater or television use." Mr. Bertero was given Fellowship Membership "awarded to active members who by proficiency and contributions have attained outstanding rank among engineers or executives in the disciplines with which the Society is most concerned."

FIRST VIDEOCOMP INSTALLATION

The first installation of a new RCA electronic television type composition system has been announced by Poole Bros., Inc., of Chicago. The pioneering project, scheduled to begin operations this fall at Poole Bros. typesetting division in Glendale, California, includes the first RCA Videocomp 70/820, and an RCA Spectra 70/45 computer.

RCA COMMUNICATIONS EXPANDS SERVICES

A major expansion in the Southeast Asia telecommunications network of RCA Communications, Inc., has been announced by Howard R. Hawkins, President. The company will use circuits in the recently completed segment of the SEACOM (Southeast Asian Commonwealth) Cable System. The first segment of the new cable links Guam, Hong Kong, Singapore and Malaysia. At Guam, SEACOM connects with RCA's facilities in the Transpacific Cable System, thereby providing access to the world wide RCA Telecommunications radio and cable network. Another leg of the SEACOM Cable System, which is being constructed by the Commonwealth Cable Partners, will be added early next year, directly linking Guam and Australia. RCA will use a large number of channels in SEACOM to provide direct cable service from the United States to Hong Kong, Singapore and Malaysia. RCA initially also will use eight wideband cable circuits providing direct public telecommunication service between the Philippines and Hong Kong, Malaysia and Singapore.

RCA already has a large network of more than 60 wideband circuits in the Transpacific Cable System, which links the U.S. Mainland with Hawaii, Midway, Wake, Guam, the Philippines and Japan. Each wideband channel is capable of being used for alternate voice-date service or subdivided into 22 separate narrowband telegraph channels. The company also offers a variety of telecommunications services throughout the Pacific area over radio facilities.

DR. HAROLD B. LAW HONORED AT NEC

The 1966 Consumer Electronics Outstanding Contribution Award of the National Electronics Conference was presented to Dr. Harold B. Law on October 3, 1966. A former Fellow of the Technical Staff, RCA Laboratories, he is now director of the EG&G Television Picture Tube Division's Materials and Display Devices Laboratory at The David Sarnoff Research Center, Princeton, N.J.

In his research on single-tube color displays, Dr. Law was instrumental in adapting the shadow-mask principle for use in color television picture tubes. All shadow mask tubes depend on basic principles of phosphor-springing that he developed. His invention of the photo deposition method of color tube screening made possible the utilization of the present shadow mask tube with phosphors deposited directly on the faceplate.

Dr. Law was a co-recipient of the Television Broadcasters Association Award in 1946. The IEEE Vladimir K. Zworykin Television Prize was awarded to him in 1955, and in 1961 he was a co-recipient of the David Sarnoff Outstanding Team Award for contributions to electron optics.

RCA VICTOR, LTD., ESTABLISHES SPACE SYSTEMS ORGANIZATION

Following the successful completion of the Mill Village Communications Earth Station by RCA Victor Company, Ltd., of Montreal, J. G. Sutherland, Vice President, Technical Products, has announced the formation of a Space Systems activity to design and build earth stations and scientific satellites in the Canadian and International markets. RCA Victor, Ltd., already is prime contractor for the Alouette and Isis satellite series.

B. MacKinnon heads up Space Systems with A. Collins in charge of Marketing. Mr. Lovas is Program Manager for earth station work, and J. M. Stewart is in charge of aerospace activity.

The Mill Village units, in which significant advances in the state of the art were achieved are: a highly efficient, wideband multimode feed system and a broadband liquid helium, closed cycle parametric amplifier with a noise temperature of 13°K. The measured antenna gain of the station is 58.9 dB and 61.0 dB at 4.1 GHz and 6.2 GHz, respectively, including losses on the feed, duplexer, and radome. The overall system noise temperature is 69.0°K at 7.5° elevation angle.

The Mill Village station joins the select family of stations—Andover, Gounhill, Pleneu Badou, and Raisting—and pioneers in earth station technology that are being applied to the network of commercial stations. Mill Village is classified as experimental because it can participate in experimental work with NASA's Advanced Technological Satellite (ATS) as well as provide commercial operation with Intelsat I, II, and III satellite systems.

Mr. Lovas was the RCA Program Manager for the Mill Village project; D. Jung was the Chief Engineer, and P. Foldes was responsible for the development and supply of the Special Feed System.
THE RCA TUITION LOAN AND REFUND PLAN IMPROVED FOR GRADUATE STUDIES

The RCA Tuition Loan and Refund Plan has been improved to provide increased financial assistance for approved graduate degree programs. The change, effective August 1, 1966 provides that the yearly loan will fund the actual tuition cost plus 50% of the tuition cost above that amount up to a maximum of $500. (The previous maximum had been $325.)

The change was effected because: 1) Costs for graduate degrees in many areas of the country have increased significantly in the past few years. 2) Continuing education, especially for those in the physical sciences, engineering, mathematics, and other professional fields, has become increasingly important. No change has been made in the $225 maximum for undergraduate study.

Under the plan, RCA loans money to qualified employees to cover tuition costs for approved study courses. The loan is deducted in installments from the employee's pay, beginning upon successful completion of the course. For additional information about the Tuition Loan and Refund Program, contact the Personnel activity at your location.

NEW ENGLISH COLOR TUBE PLANT

The formation of RCA Colour Tubes Limited to manufacture RCA color r.v. picture tubes in England for the British and export markets has been announced by RCA and Radio Rentals Limited, one of Britain's leading manufacturers and distributors of television sets. The new company is owned two-thirds by RCA Great Britain Limited, the wholly owned British subsidiary of RCA, and one-third by Radio Rentals Limited. It will have production facilities at Skelmersdale, Lancashire, in a new plant to be completed for the start of operations in mid-1967.

NEW TECHNICAL EDUCATION COMMITTEE AT CSD-NY LABS

The CSD Advanced Communications Laboratory (ACL) has established a Technical Education Committee to keep ACL engineers and scientists abreast of the state of the art in the various programs at ACL. The committee has scheduled a series of lunch-hour lectures by in-house speakers. The subjects include: ACL Communications; Trends in Technology; The Marketing-Engineering Team; FM Threshold Extension; Secure Voice Communications; Advanced Filter Techniques; Superconducting Resonators, and Microwave Power Sources.

PROGRAM TO TRAIN COMPUTER PERSONNEL

The first state supported program set up exclusively to train computer programmers and systems analysts to the use of an elaborate data communications network has been announced by the Oklahoma State Board for Vocational Education. Dr. Oliver Hodge, State Director of Public Instruction, said the system, designed to alleviate the critical need for trained data processing personnel, initially will include nine RCA Spectra 70/35 and eight RCA 301 systems, and peripheral equipment.

RCA TO SUPPLY LARGEST 2-WAY MOBILE RADIO SYSTEM

RCA Broadcast & Communications Products Division, Meadow Lands, Pa., has received a $4.2 million order for a new New York City Transit Authority to provide the world's largest two-way mobile radio system for public transportation control and communications. RCA will supply 4,754 mobile radio units, 64 control units, and 21 base stations and associated equipment over an 18-month period.
PROFESSIONAL ACTIVITIES

Product Engineering Staff, Camden, Al
Pinsky (Editor of RCA Trend) is serving as a member of the Executive Committee of the IEEE Philadelphia Section, and as Publicity Chairman, with responsibility for the section publication, IEEE Almanac.

Missile Test Project, Cape Kennedy, Fla.: R. P. Murkhe has been named both National President and Chairman of the Board of Governors at SPIE’s 11th Technical Symposium in St. Louis in August. During the past year he was Executive Vice President. During the conference, Mr. Murkhe also served as chairman of the Range Instrumentation technical papers session. Assisting him as co-chairman of the session was E. M. Bonsall.

Frank W. Hopkins, Jr., has been elected president of the Canaveral Chapter of the American Institute of Industrial Engineers. He previously has served the organization as Director and as a member of its local conference committee.

Two members of the RCA Missile Test Project have been elected President and Vice President of the Cape Kennedy Quality Control and Reliability Club, Paul E. Badar and will fill the presidency for the coming year, and Kingsley E. Forry will serve as Vice President.

Robert A. Menella is serving as Assistant Planning Director and Consultant for a Science Center to be established near Cape Kennedy by the Brevard County, Florida, Board of Public Instruction. Mr. Menella will lend particular assistance in the area of instrument requirements and design. The Science center will include a planetarium, observatory, laboratory, optics workshop and other related facilities.

Some 41 members of the Missile Test Project’s Data Processing and Systems Analysis organizations made presentations during the recent Seventh Range Users Data Conference held by the Air Force Eastern Test Range at Orlando AFB, Florida. The conference is an annual event sponsored by the Directorate, in coordination with RCA MTP to acquaint Range Users with the capabilities available from the AFTR.

W. M. Sheahan, Manager of Range Photography for the Missile Test Project, has been elected a Governor of the Southeastern Region of the Society of Motion Picture and Television Engineers. Active in SMPTE for many years, Mr. Sheahan is a Fellow of the Society. —T. L. Elliott, Jr.

Record Division, Indpls. Robert C. Moyer was chairman of the symposium on Automotive Tape Cartridge Systems Oct. II at the Audio Engineering Soc. meeting in New York.

DEP Central Engineering, Camden, M. S. Gokhale participated in a Conference on Standardization organized by the Metropolitan New York Section of the Standards Engineers Society, at Barbie, New Jersey on June 19, 1966. Presentation by Mr. Gokhale consisted of data on various aspects of “Budgeting for a Standards Department”, based on an objective analysis of the problem without reference to any one industry. Data on “Cost Avoidance through Standardization” was also presented by him as a basis for discussion on this subject. At the invitation of the U.S. Department of State, American International Development (USAID) and the Rensselaer Polytechnic Institute (RPI) School of Management, Mr. Gokhale also made a presentation on the importance of Standardization to a group of visitors from various industries in the developing Countries, meeting in Troy, New York, during June.

ECD, Somerville, N.J.: Dr. H. S. Veloric is serving as Membership Chairman, N.Y. Area IEEE Electron Device Group. —P. Farina

MSR, Moorestown, N.J.: Ulrich Frank has been appointed Chairman, Program Committee, IEEE professional group for Parts, Materials, and Packaging for the Philadelphia Chapter. —L. W. Lazarick

ECD, Harrison, N.J.: Robert McMurray was made chairman of the New York Section of the Electron Devices group of the IEEE. This includes No. N.J., N.Y.C., I.I. and Westchester. —H. Wolfskein

ECD, Lancaster, Pa.: L. D. Miller, Dep't. 980, attended the 14th National Iris Symposium held at Ft. Monmouth, New Jersey, on June 1-2. A. G. Nekut and H. R. Krall, Dep't. of Physics, attended the Conference of American Societies for Experimental Metabolism meeting in Atlantic City, New Jersey, on April 17. —R. L. Kaufman

Jules M. Forman, P.E., a past president of Lincoln Chapter, was recently appointed by the New President of Lincoln Chapter, PSPE, as the 1966-1967 Chairman of a Long Range Planning Committee. This special committee will be composed of only past presidents of Lincoln Chapter and the Chapter Director. The committee will attempt to formulate improved plans and directions to strengthen the Chapter and enhance the concepts of professionalism. Mr. Forman was recently appointed by the State Society President-Elect, Mr. R. L. Reiling, P.E., to serve as a member of the State Examination Committee for New Jersey and Pennsylvania Section, of Professional Engineers. Committee efforts will be applied to the strengthening of the examination phase of professionalism while aiding the State Registration Board.

—G. Thomas

CSD, Camden, N.J.: David Shore CSD Chief Engineer will be Chairman of the 1968 International Conference to be held in Philadelphia in June of 1968. —D. G. Hymas

Dr. Richard Guenther was Program Vice Chairman of the IEEE International Communications Conference held in Philadelphia on June 15-17, 1966.

Wes Fields is serving as Chairman, Philadelphia Chapter of IEEE-GEWS, Editor of the GEWS national Newsletter, and as a member of the GEWS Administrative Committee. In addition, he is Editor of Standards Engineering magazine, the journal of the Standards Engineering Society.

CSD, New York: Seymour Krevsky, CSD Advanced Communications Lab., N.Y., was elected Chairman of the New Jersey Coast Chapter, Communication Technology Group, IEEE.


RCA Labs., Princeton, N.J.: In the Princeton Section of IEEE, from RCA Labs, the new officers (July 1966-June 1967) are: Chairman, B. J. Lechner; Vice Chairman, G. B. Hertzog; Secretary-Treasurer, H. L. Cooke; and Editor of PS, Section Newsletter, S. F. Dieter. —C. W. Sall

ASD, Burlington, Mass.: David B. Dobson was Chairman of the Conference Record Committee of the 1966 Aerospace and Electronic Systems Convention held at the Sheraton Park Hotel, Washington, D.C. on October 3, 4, 5, 1966. Mr. Dobson is Executive Editor of the IEEE Transactions on Aerospace and Electronic Systems and former Editor of IEEE Transactions on Military Electronics which was devoted to Automatic Testing Techniques.
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